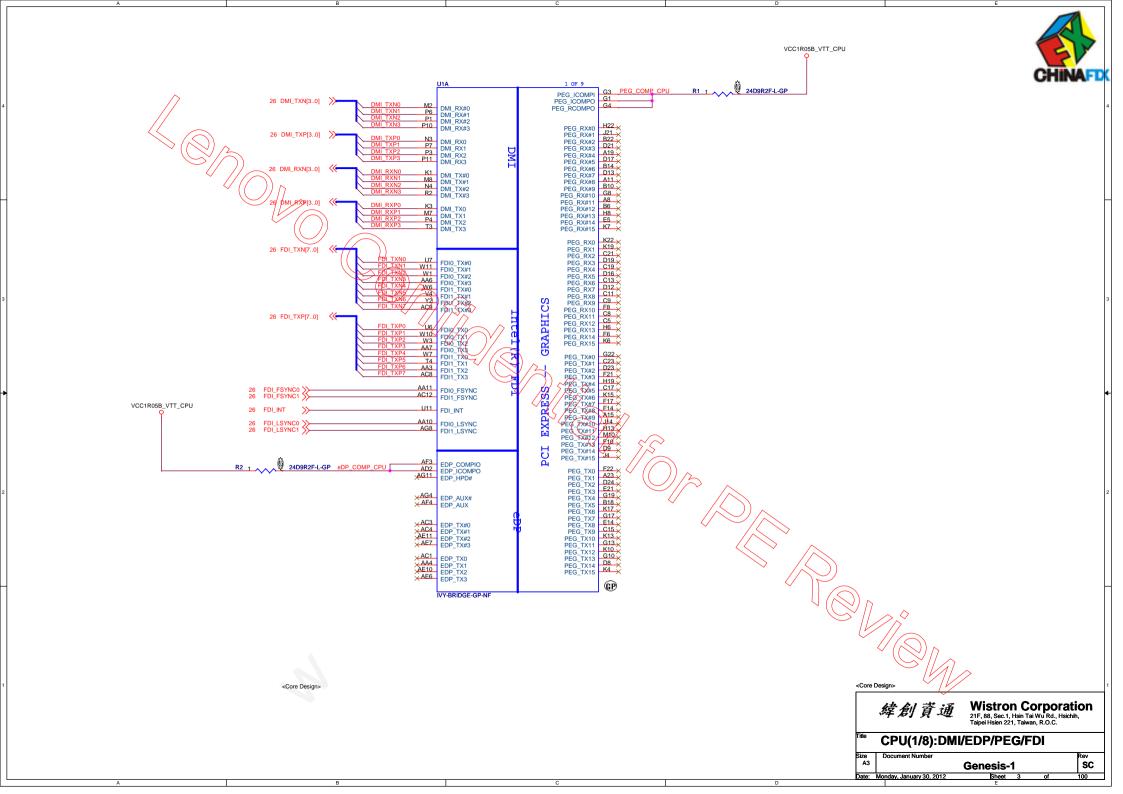
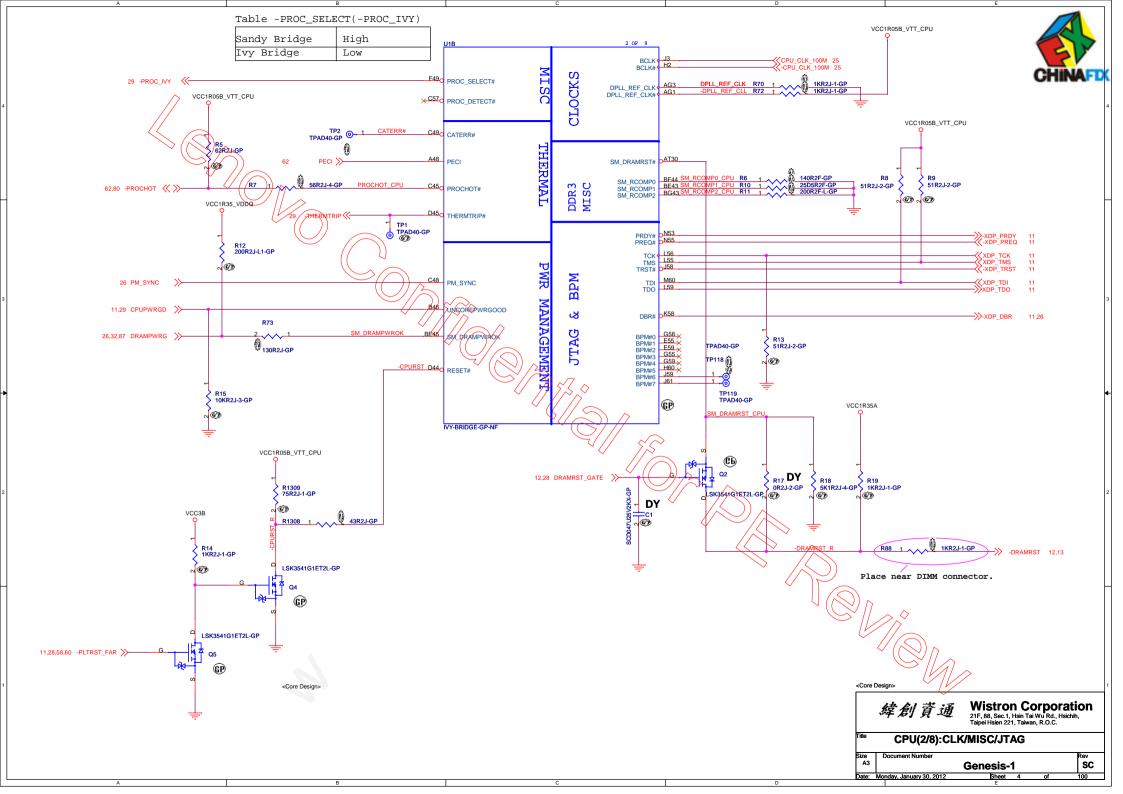
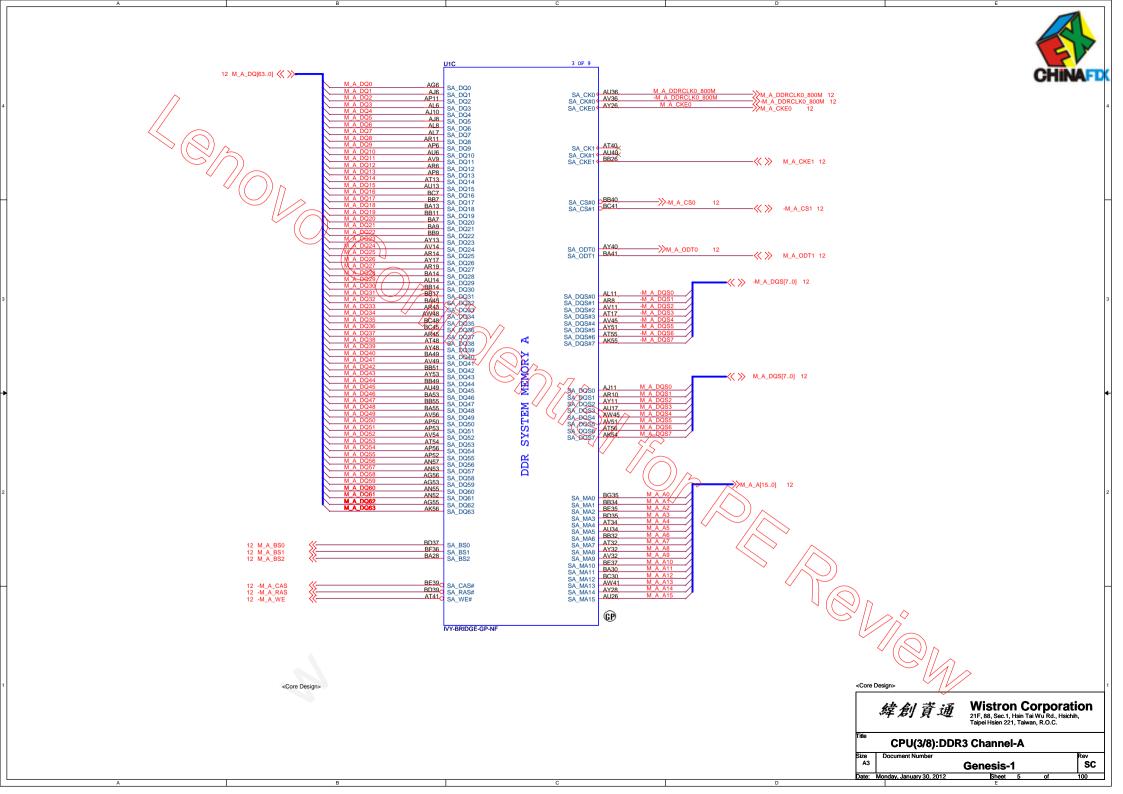
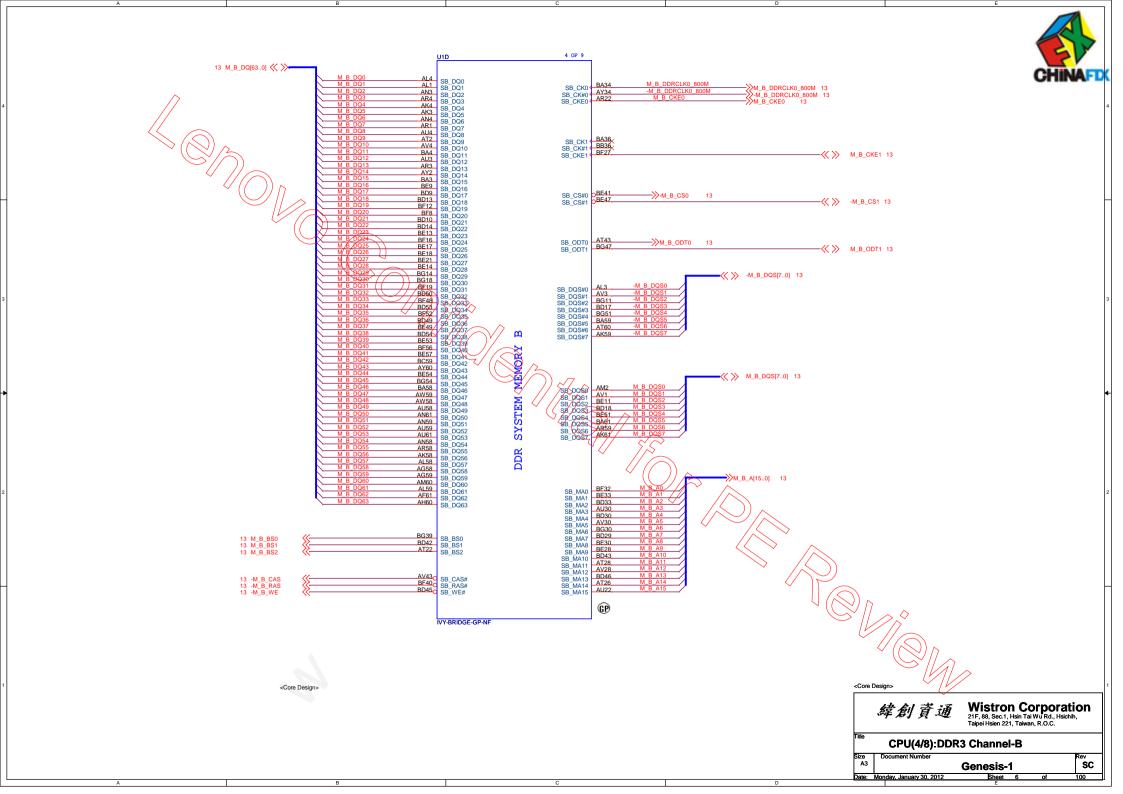


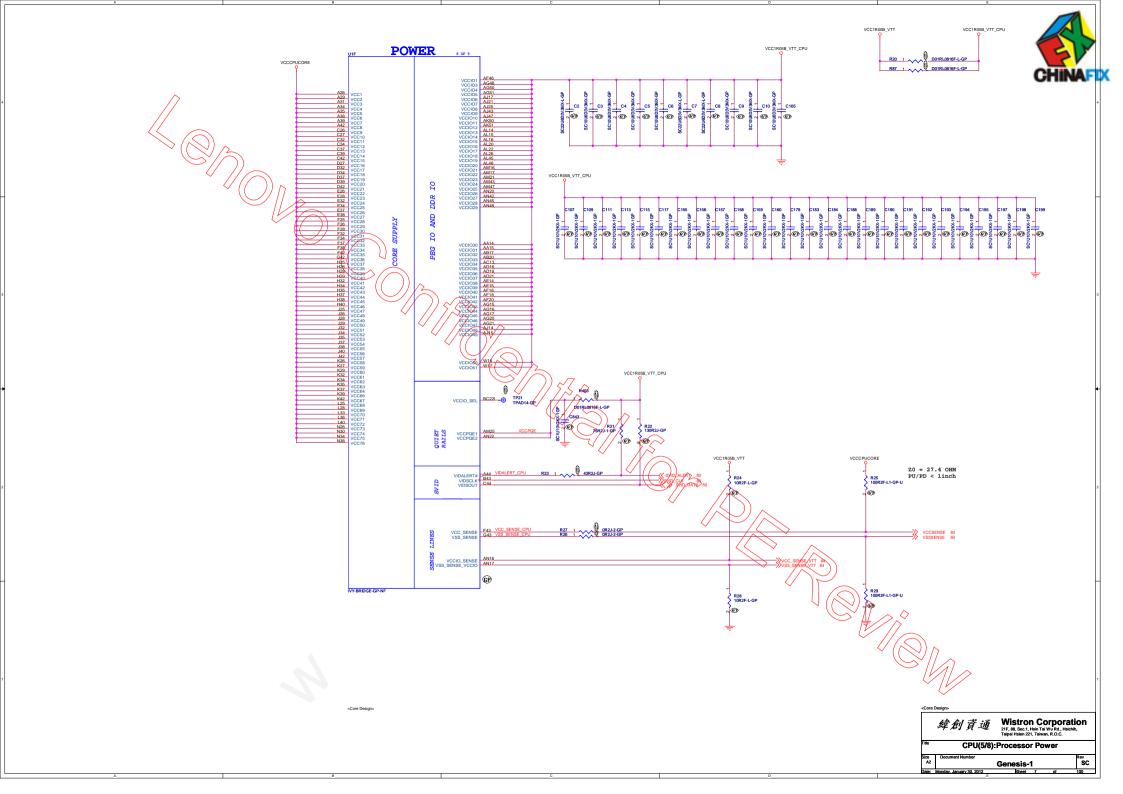
RESISTOR															
	Symbol name Value Tolerance Rating Size								EC F	IISTC	RY				
	(J: 5%, F: 1%,			(J: 5%, F: 1	1%, D: 0.5%, B: 0.1 %)	0402=> 1/16W, 25V 0603 => 1/16W, 75V 0805 => 1/10W, 100V	2=>0402, 3=>0603, 5=>0805, 6=>1206, 0=>1210	 	Stage	Date	EC No.	Page	Note		CHINA
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F	The naming rule	naming rule is value + R + size + tolerance the value, it can be read by the number before R R means resistor)													
	For the tolerand	or the size, R2=>0402, R3=>0603, R5=>0805,													
	For the size, R2=>0402, R3=>0603, R5=>0805,														
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(CAPACITOR	۲						i 							
3	Symbol name	Val			Tolerance	Rating	Size	550							3
				(IVI: +/-20, r	K: +/-10, Z: +80/-20)		2=>0402, 3=>0603, 5=>0805, 6=>1206, 0=>1210								
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	The naming rule is Capacitor type + value + rating + size + tolerance + material SCD1U10V2MX-1 SC=> SMT Ceremic, TC=> POS cap or SP cap D1U => 0.1UF 10V => the voltage rating is 10V 2=> 0402, 3=>0603, 5=>0805									4 (//		\wedge			
	X=> X7R/X5R	l⇒stolerance M, K, Z ⇒ XTR/X5R, Y=> Y5V ⇒ symbol version, nonsense to EE characteristic													
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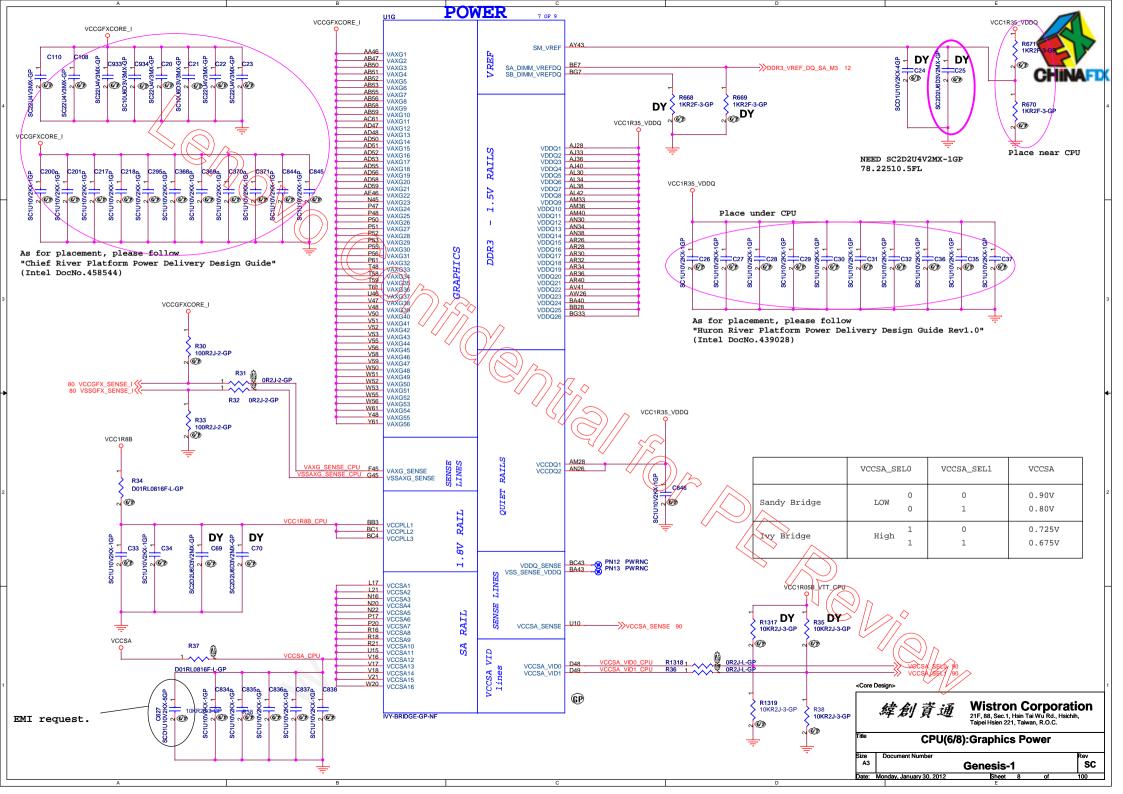


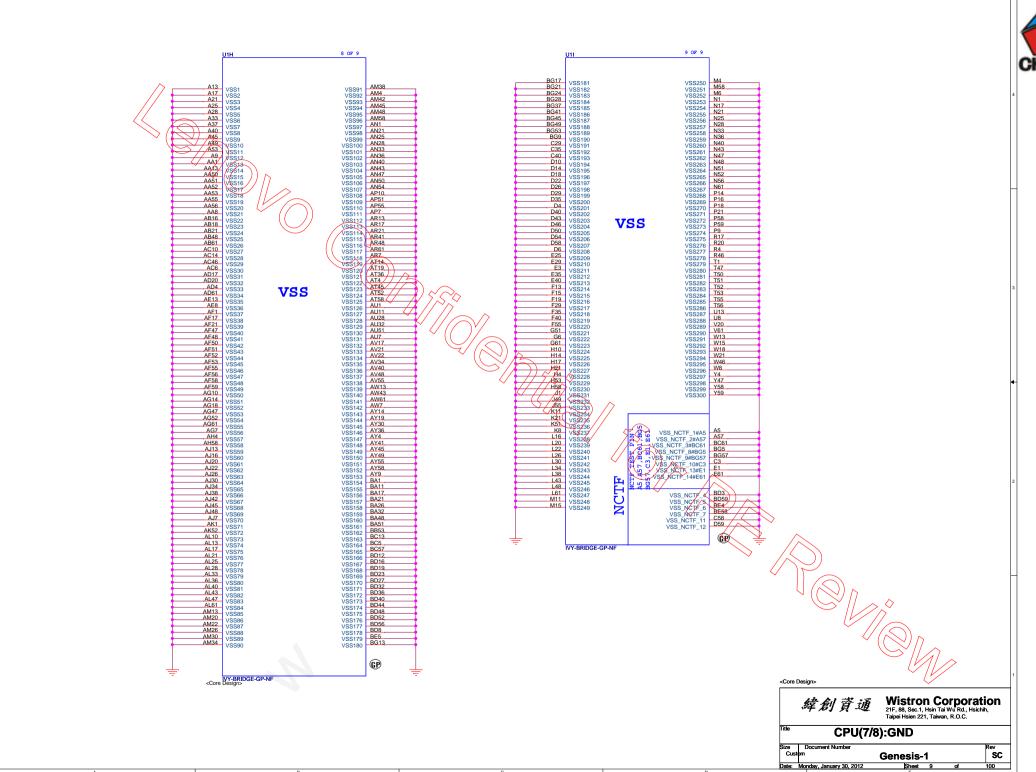




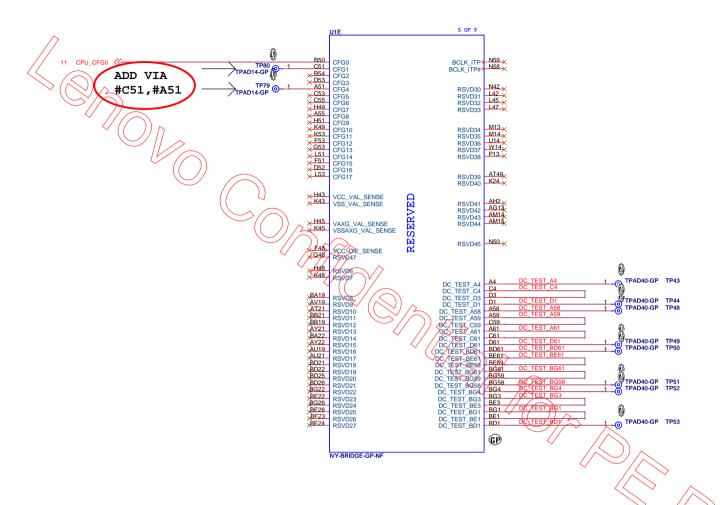








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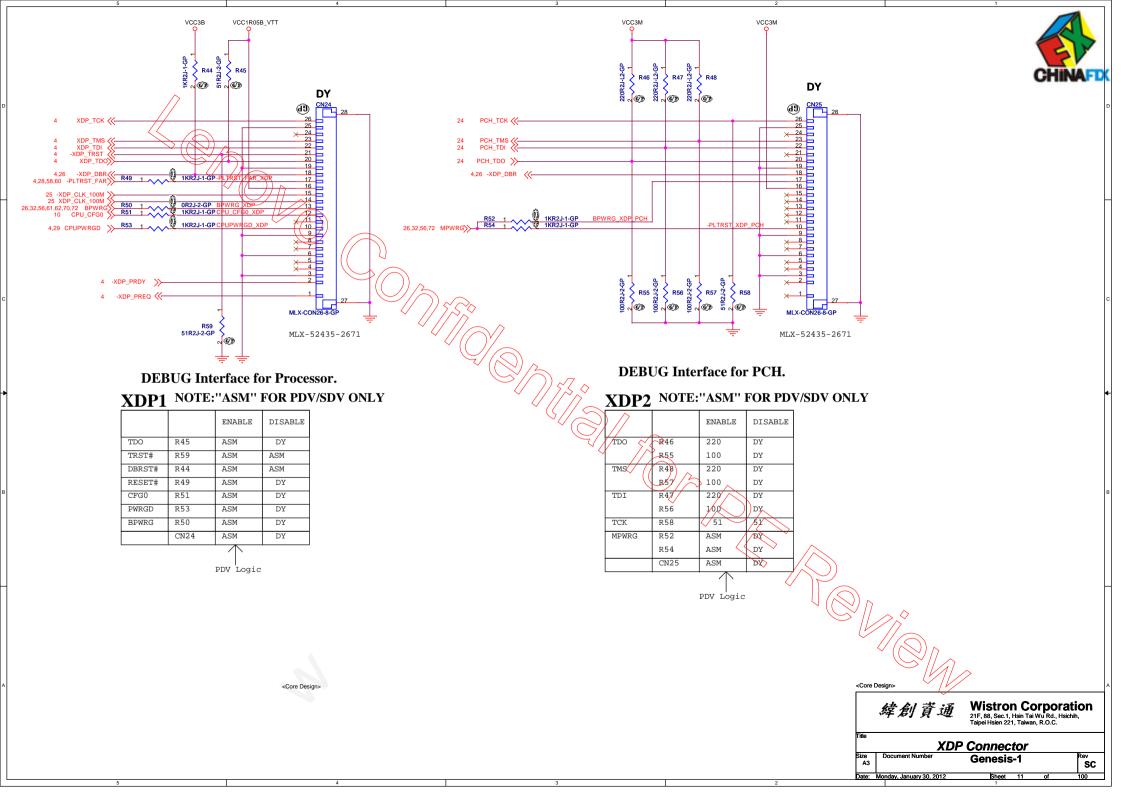
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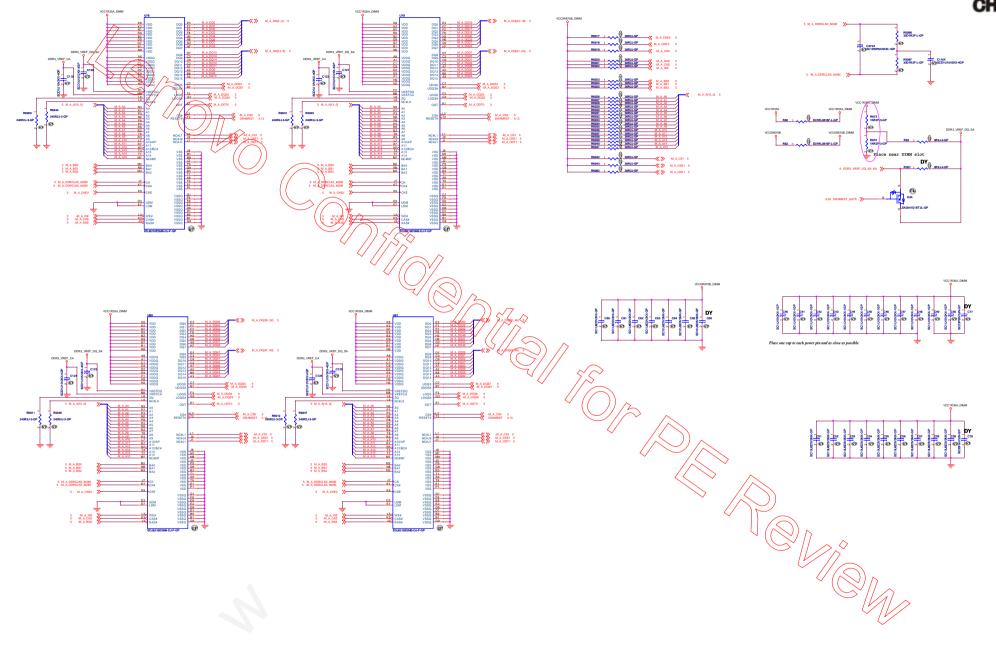
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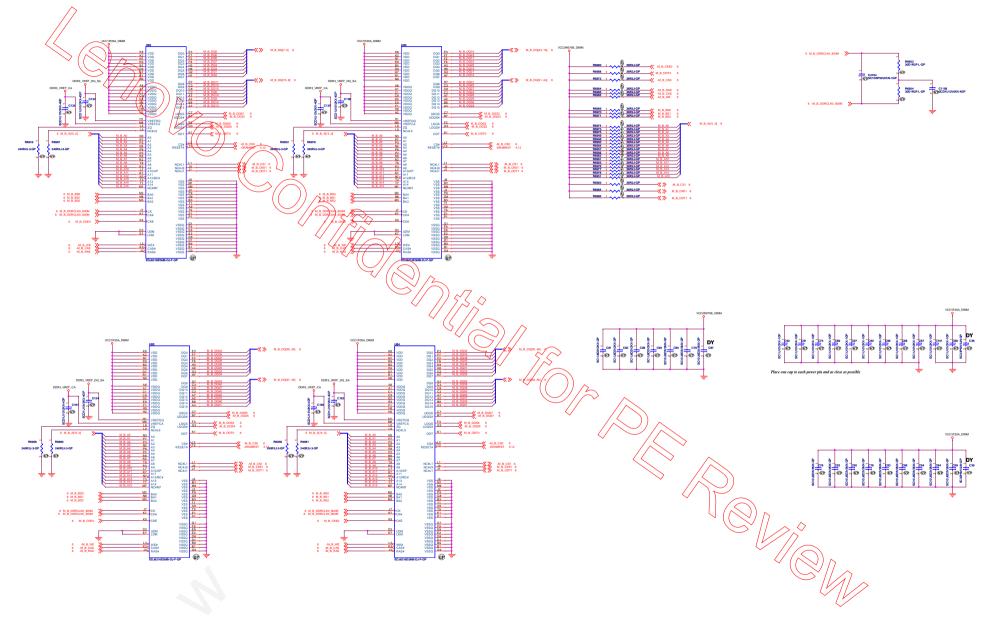
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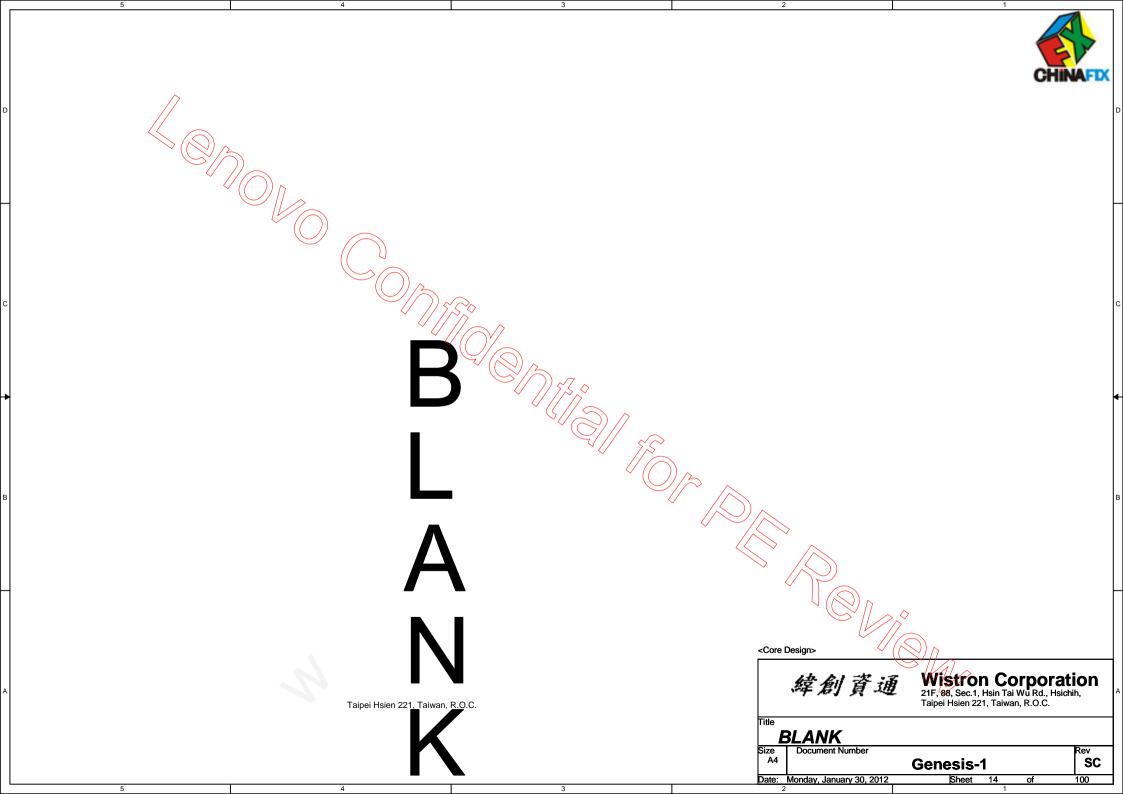
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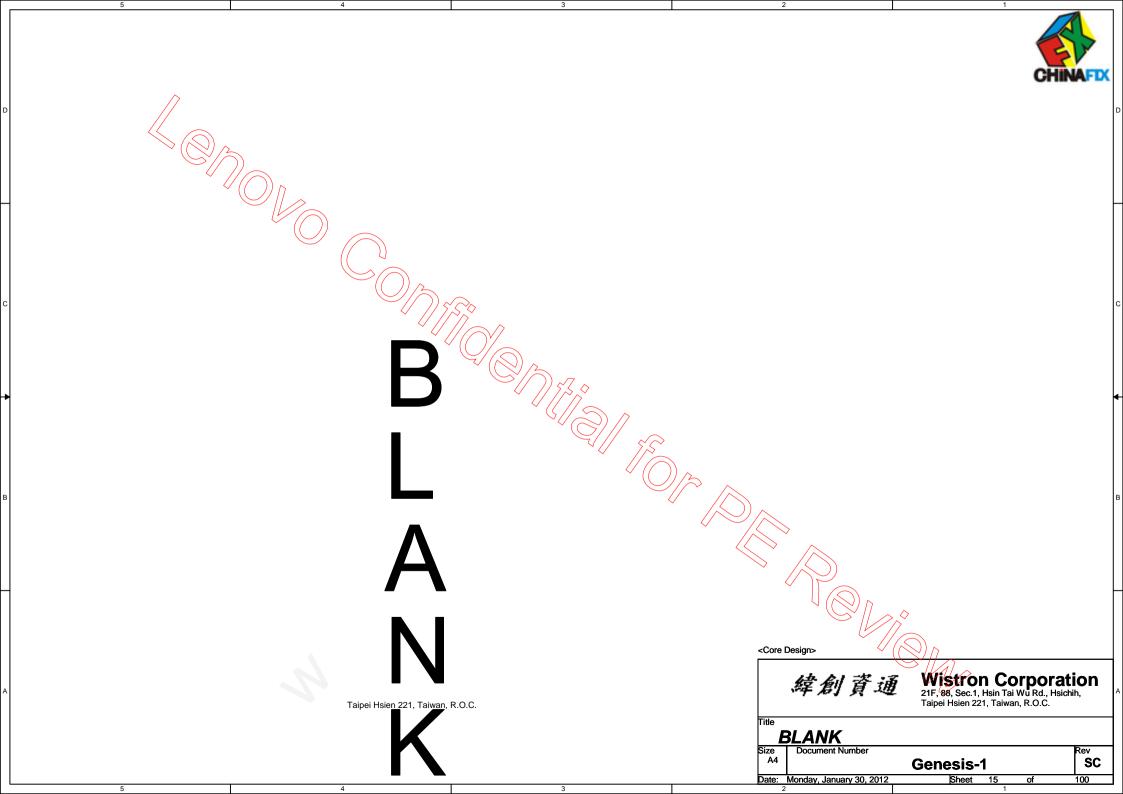
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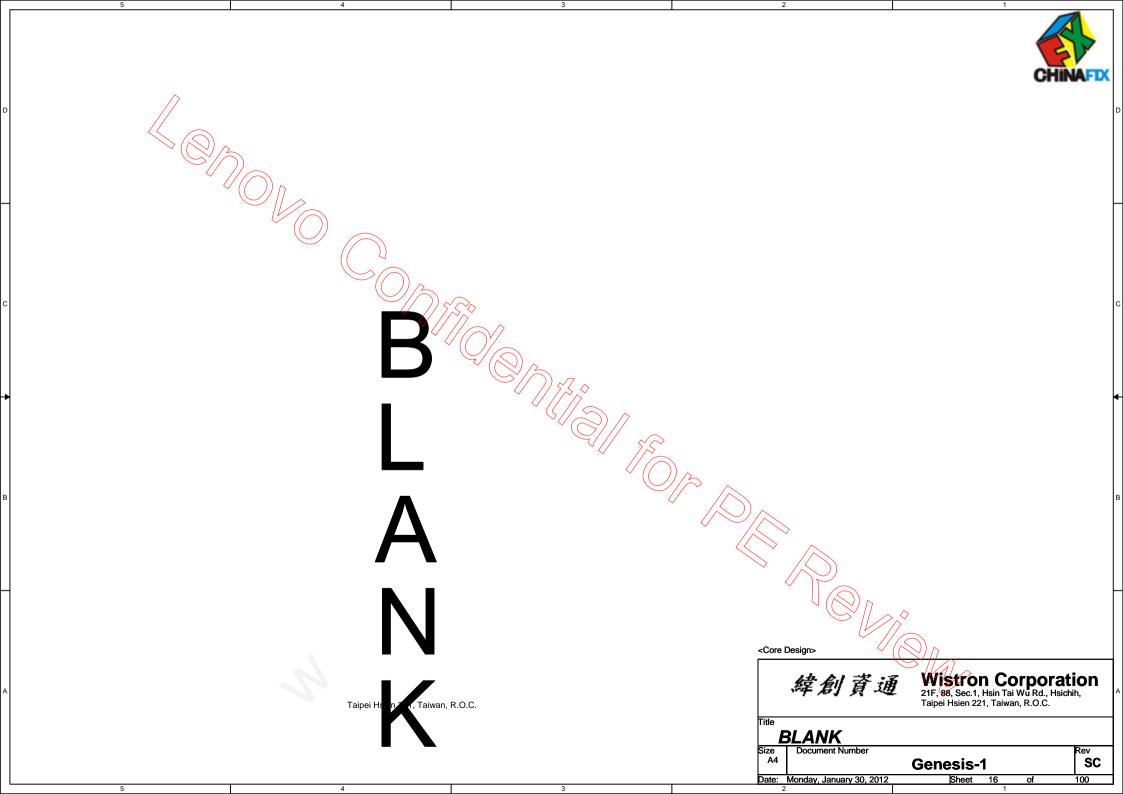
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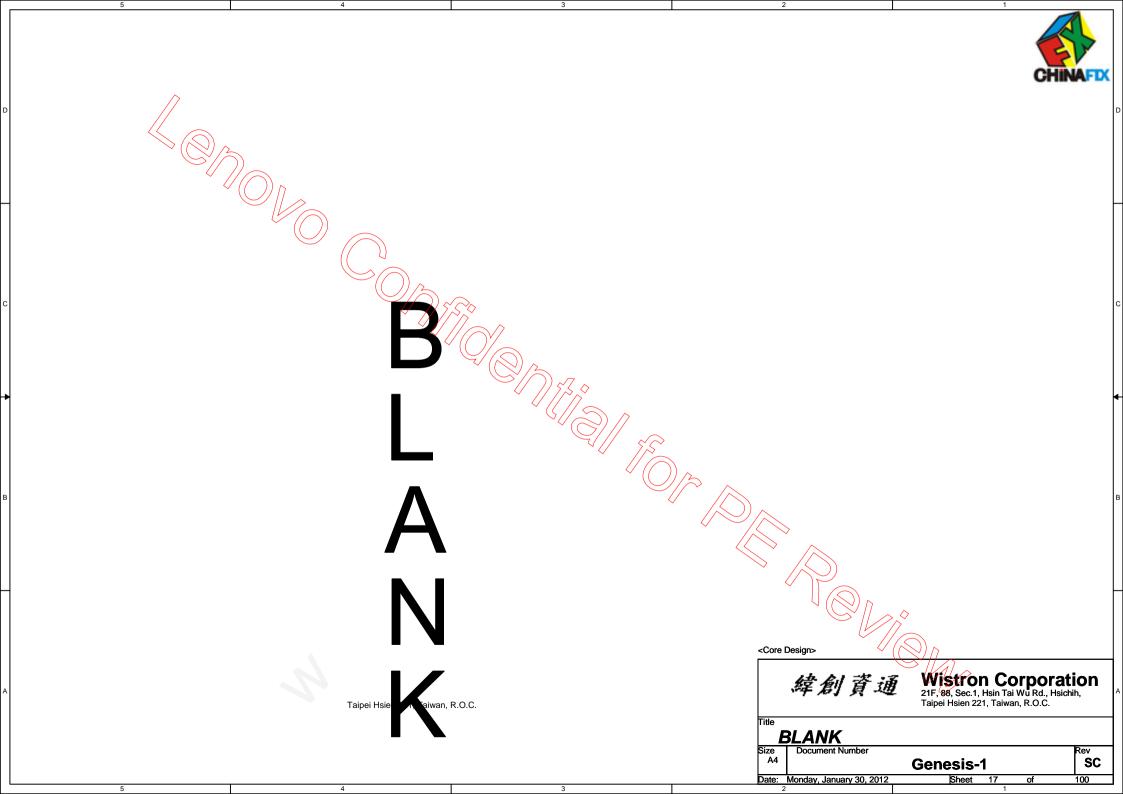
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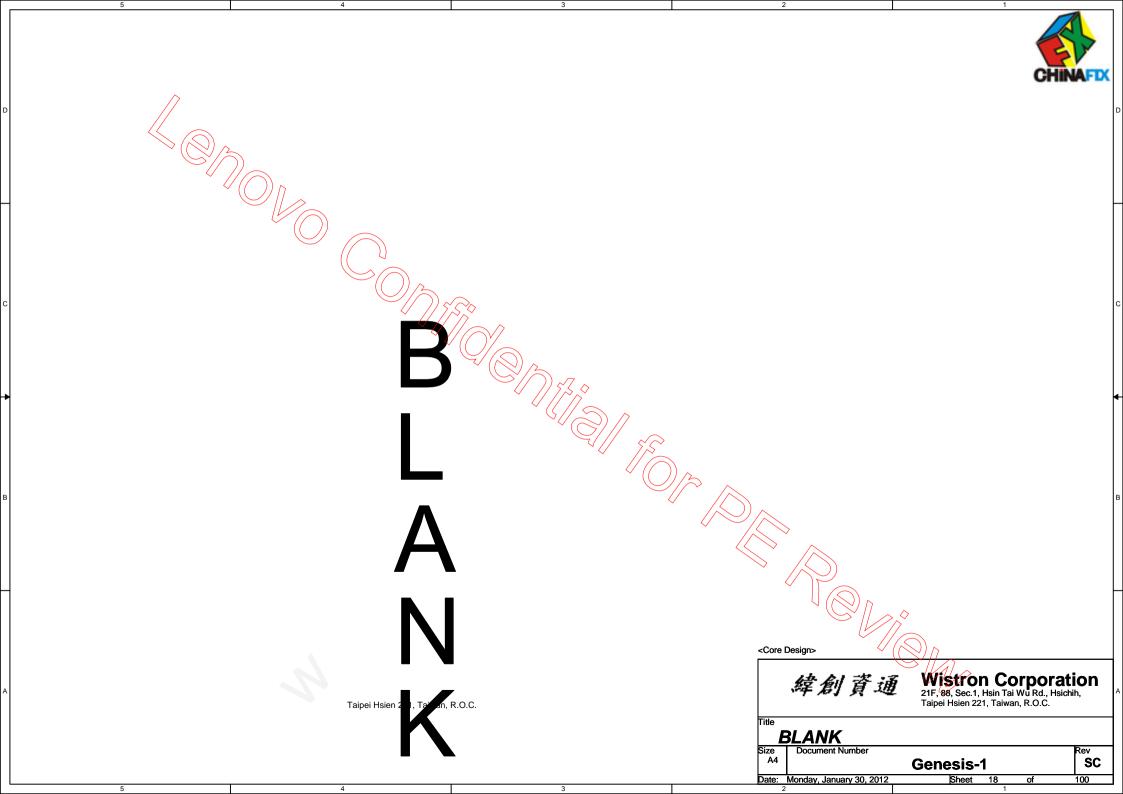
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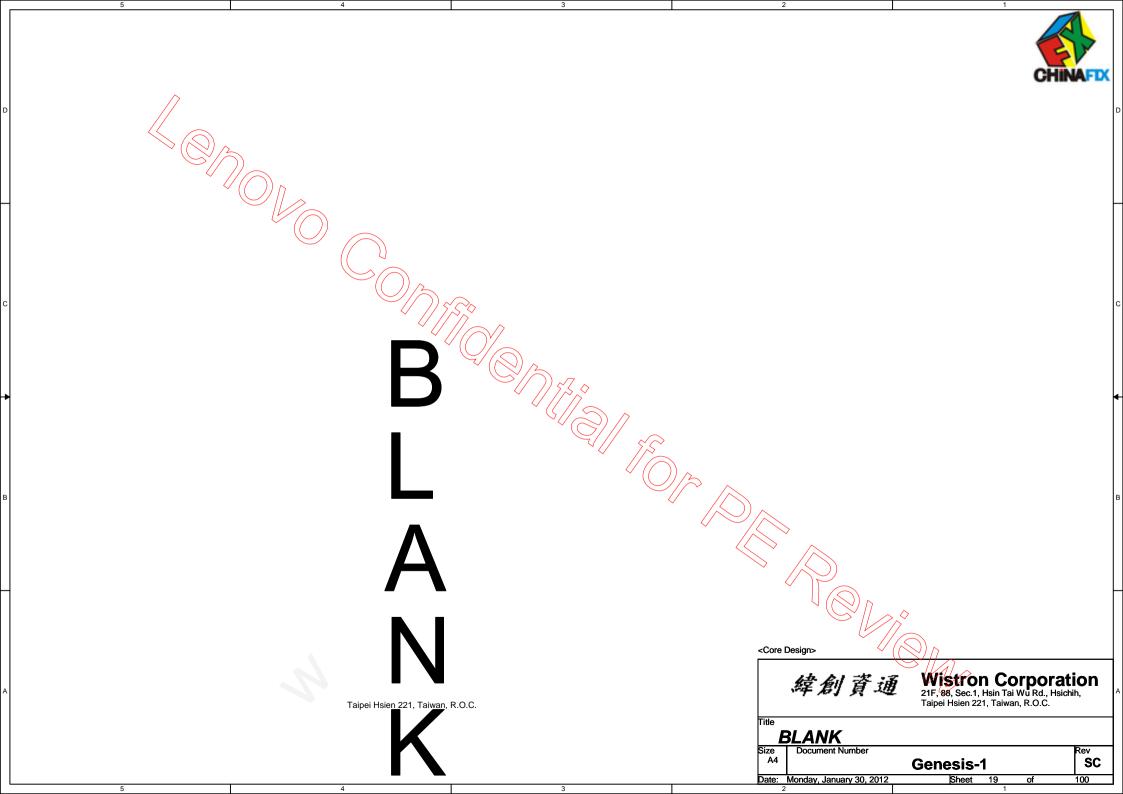


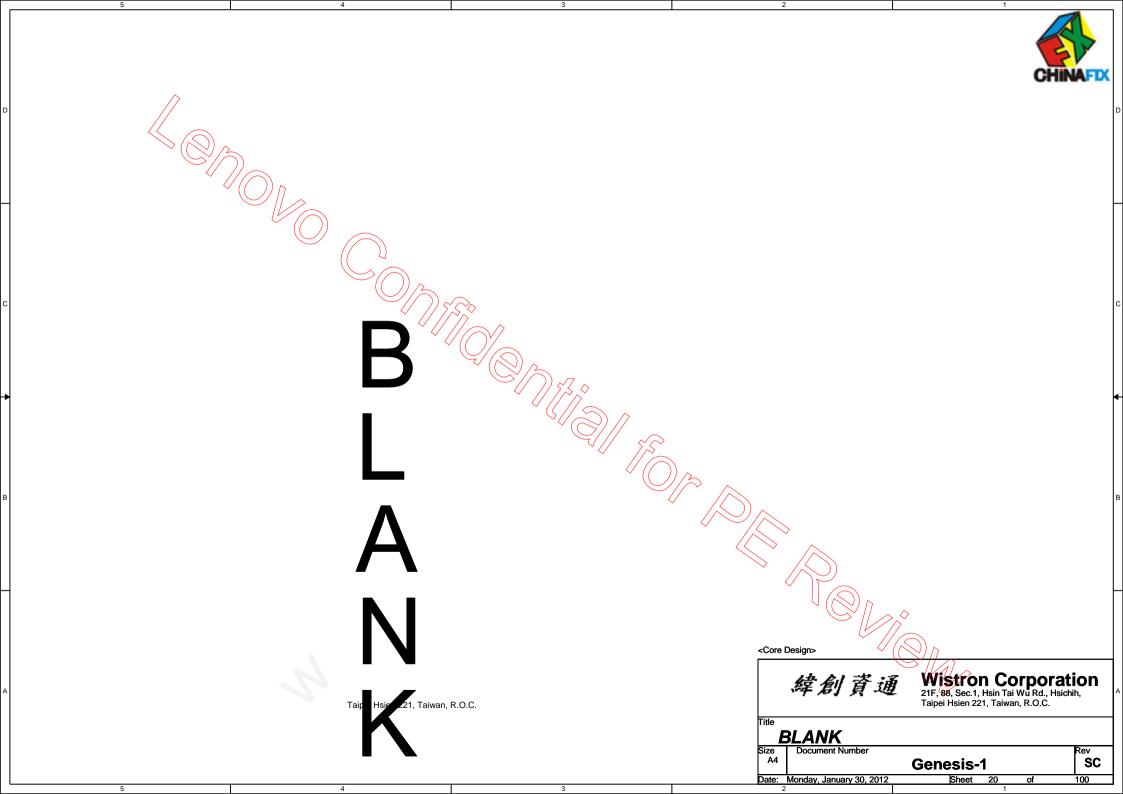


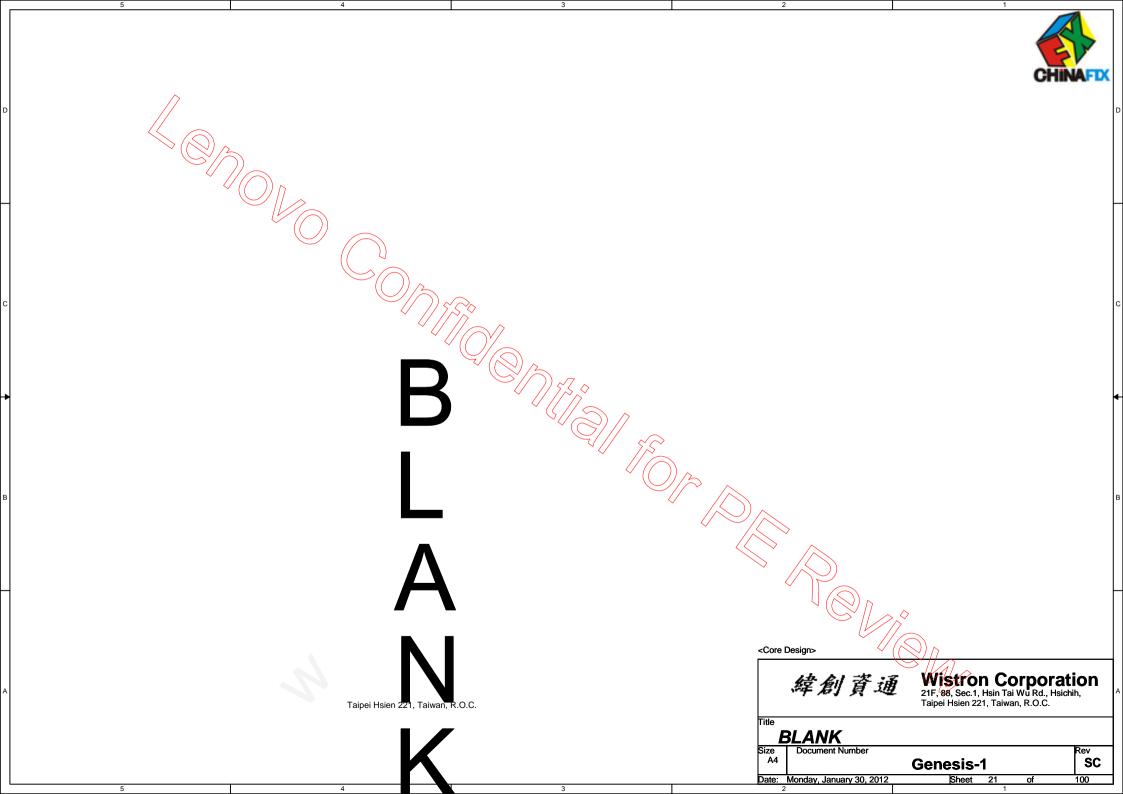


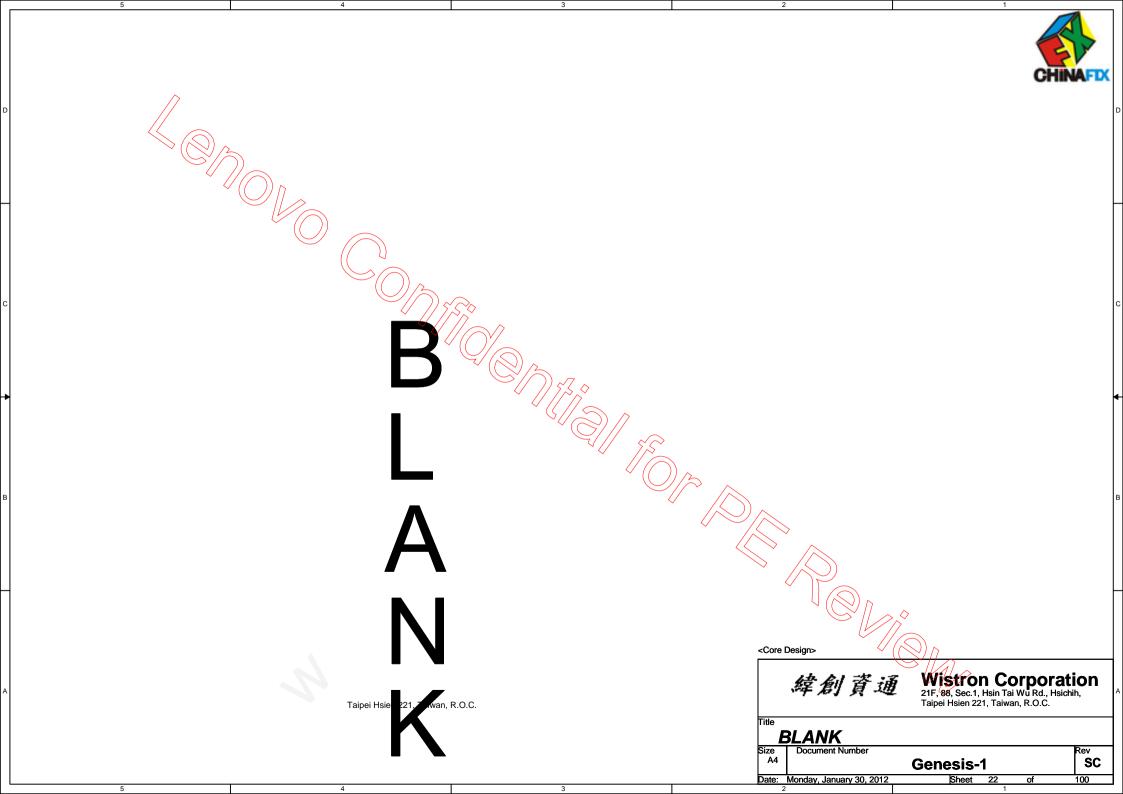


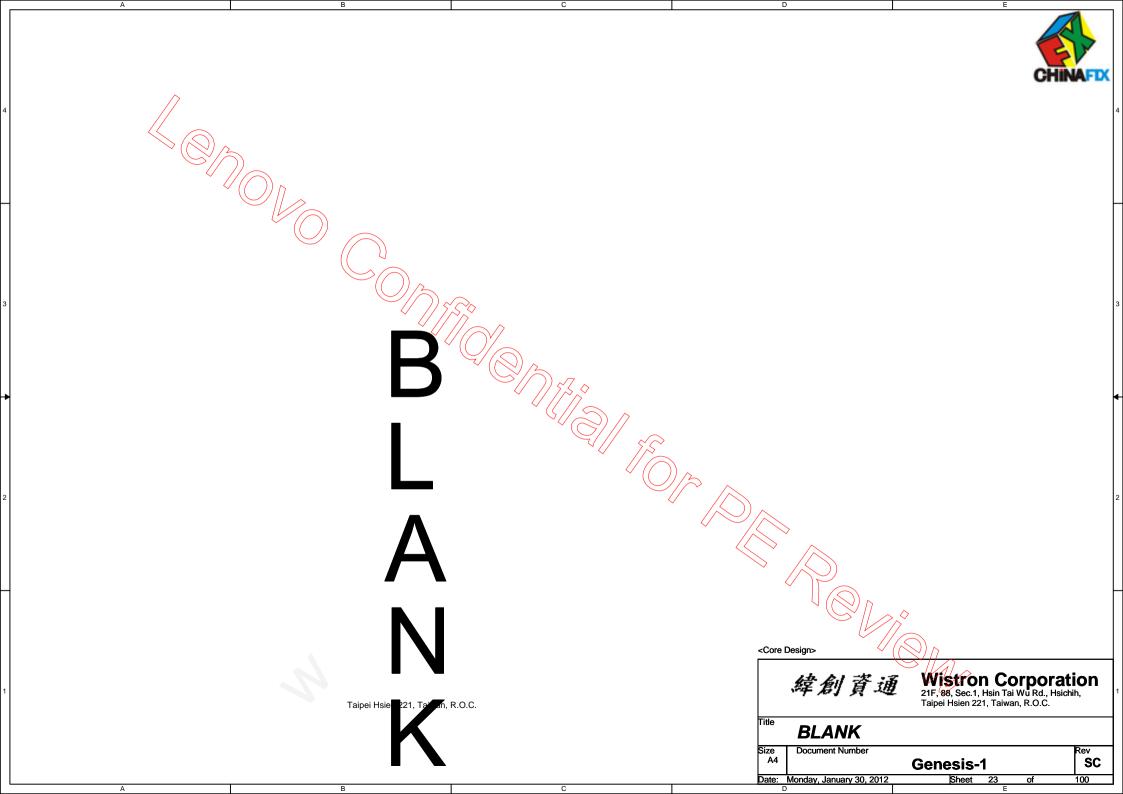


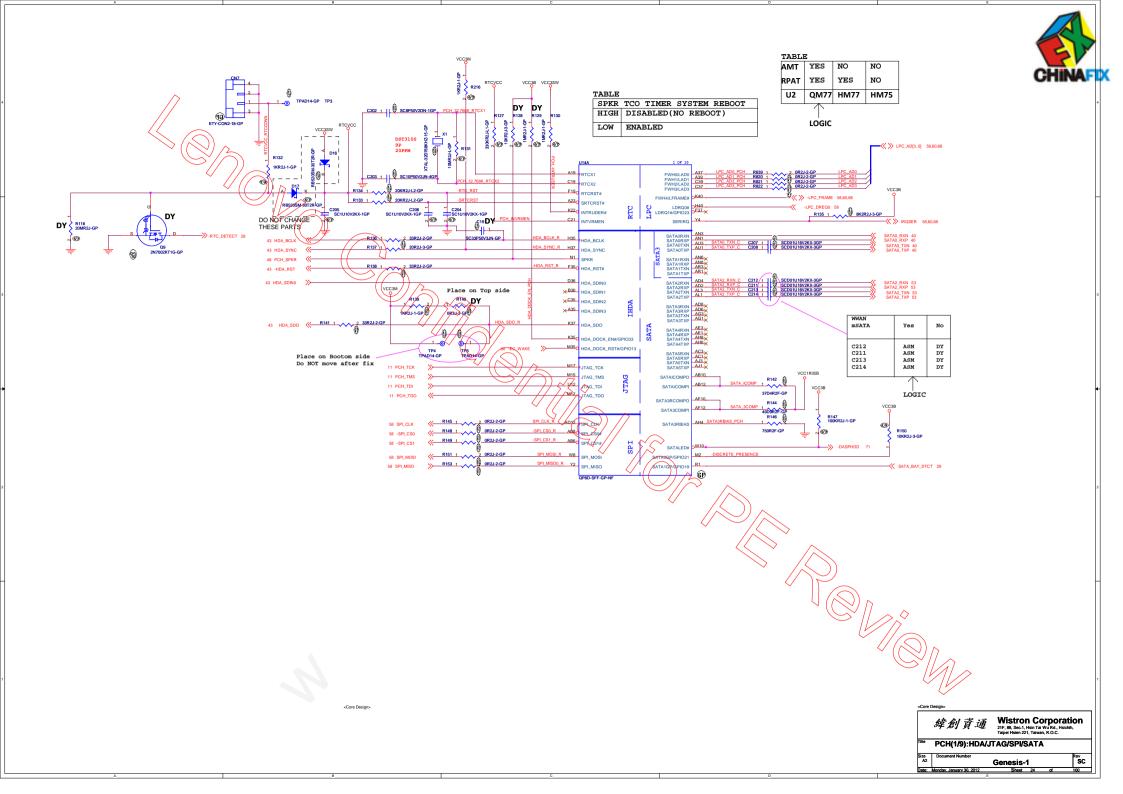


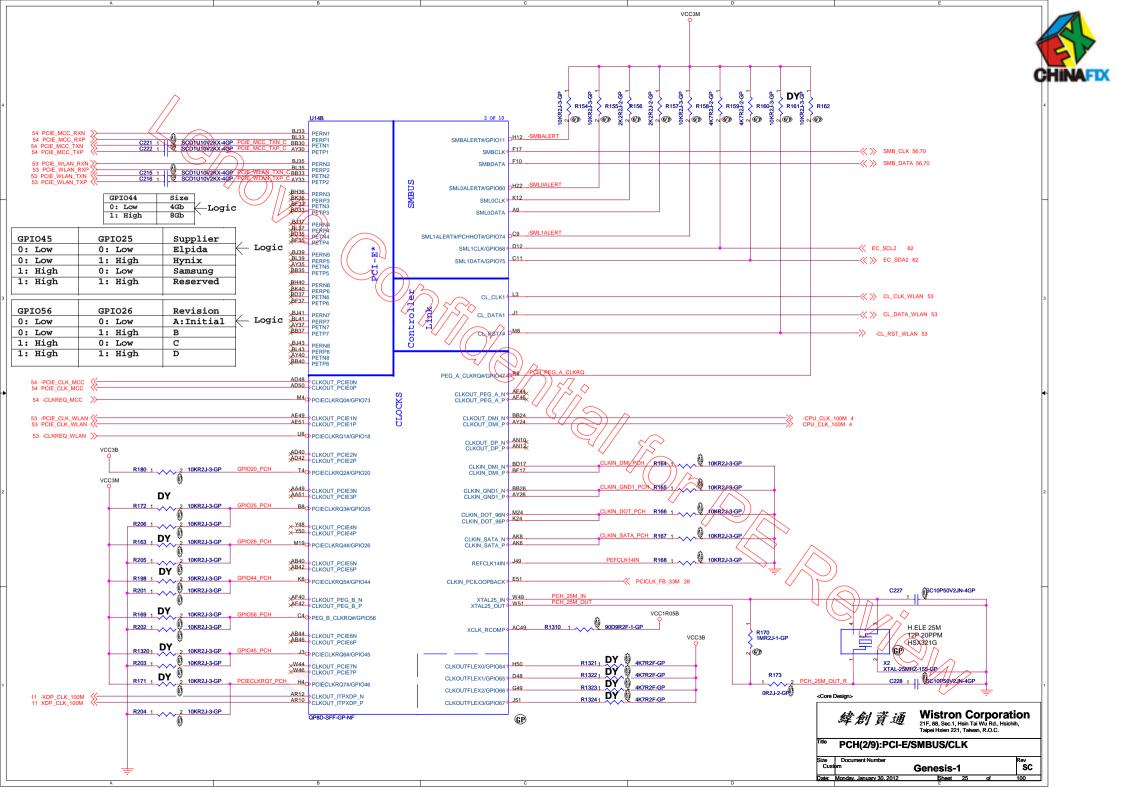


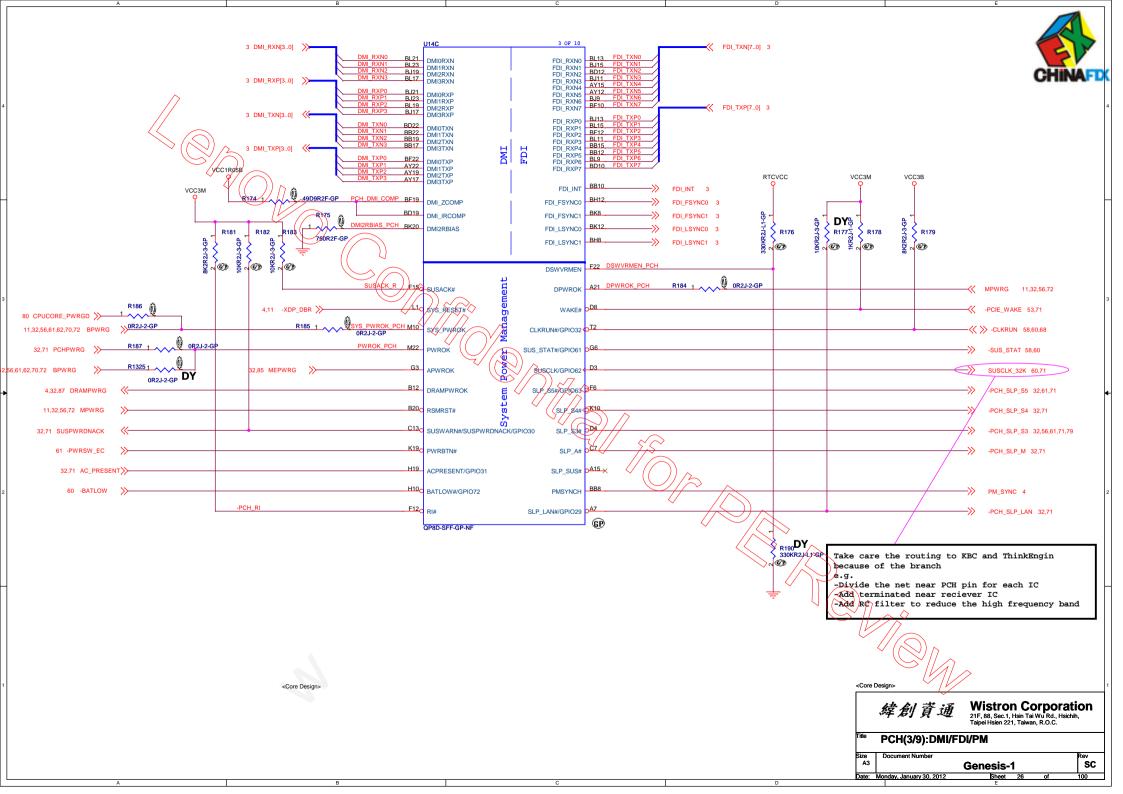


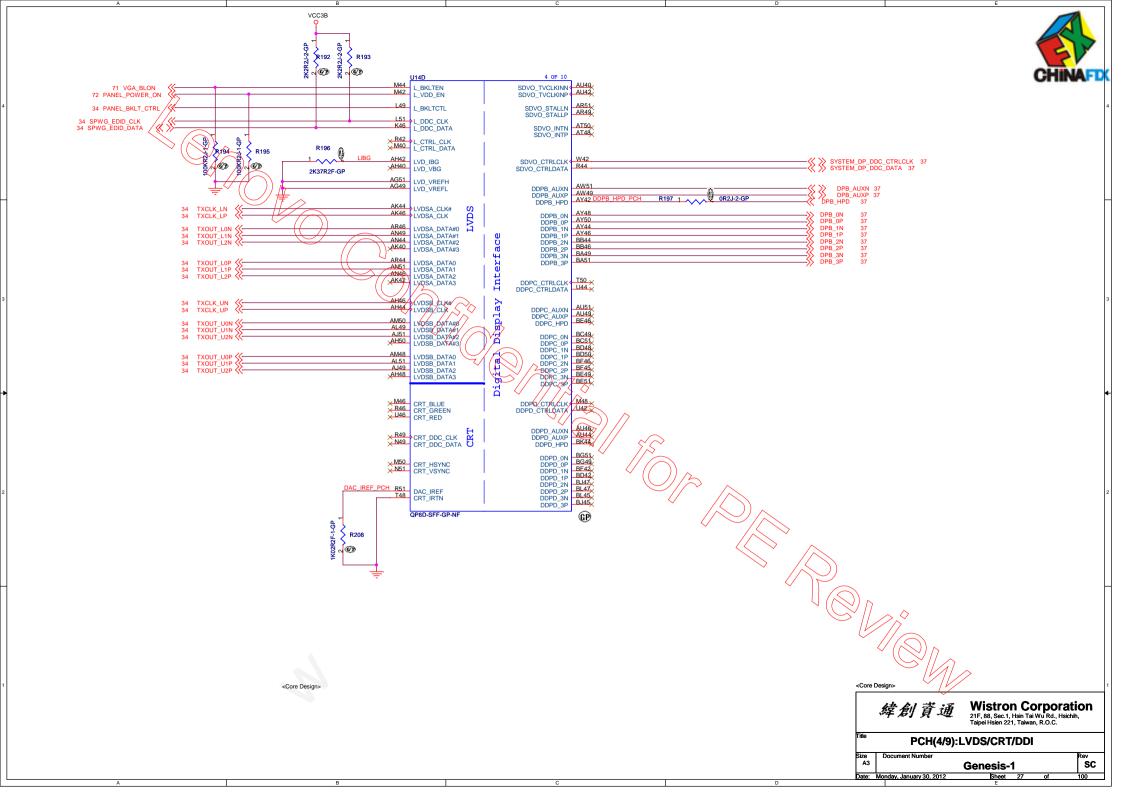


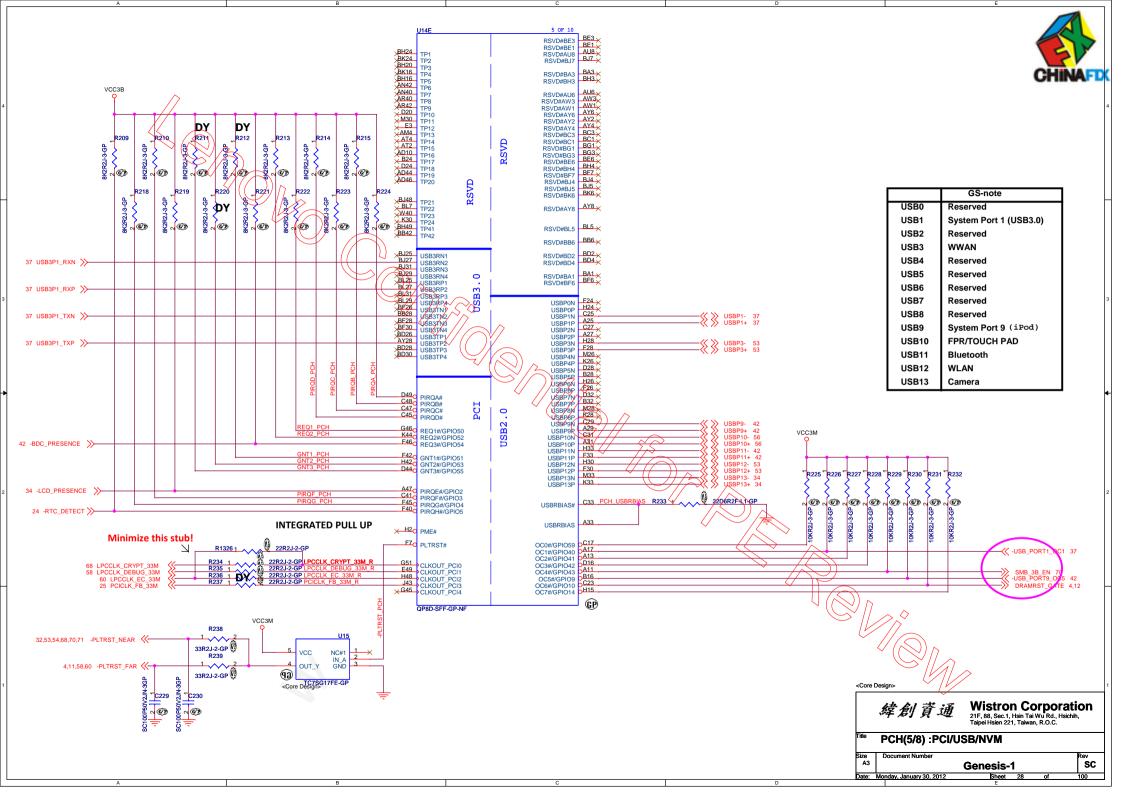


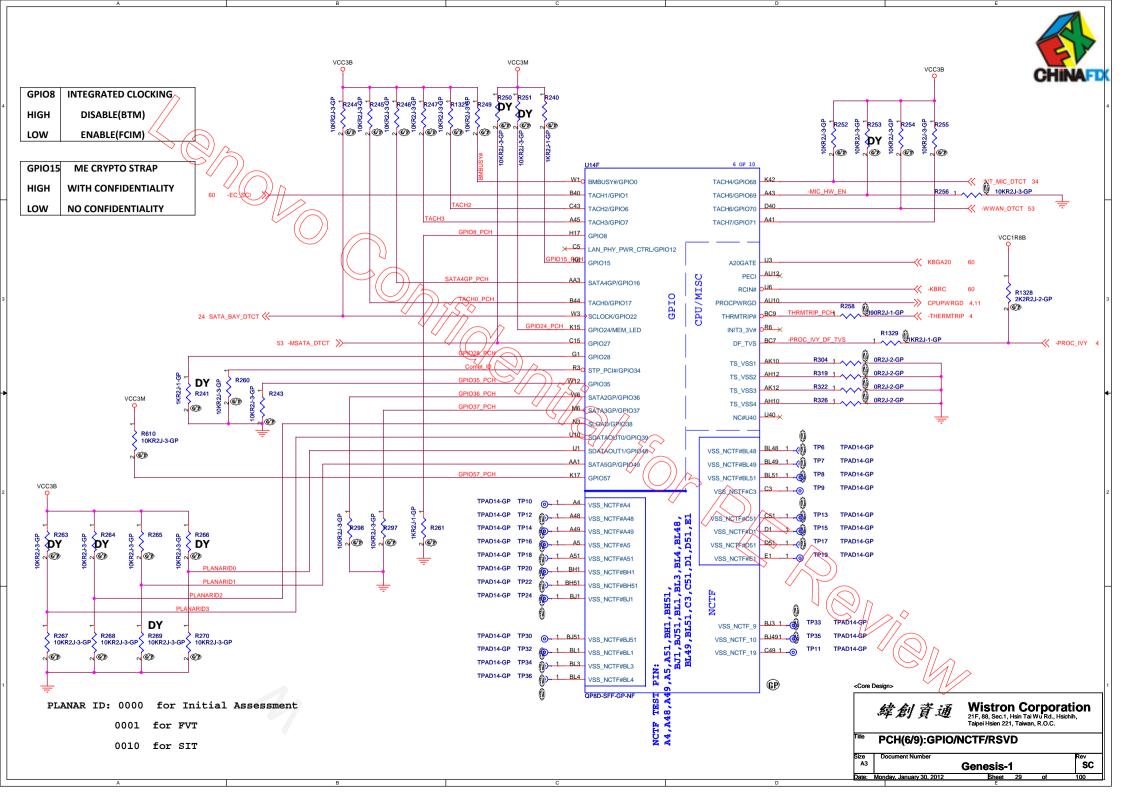


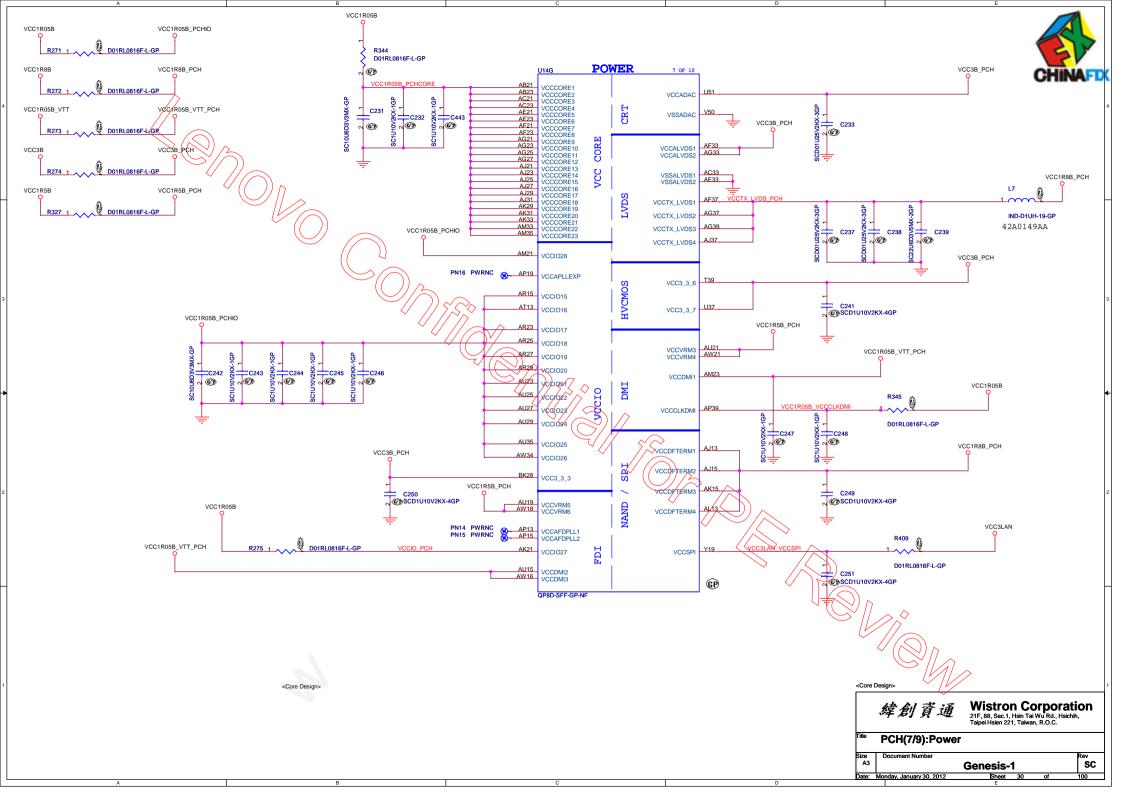


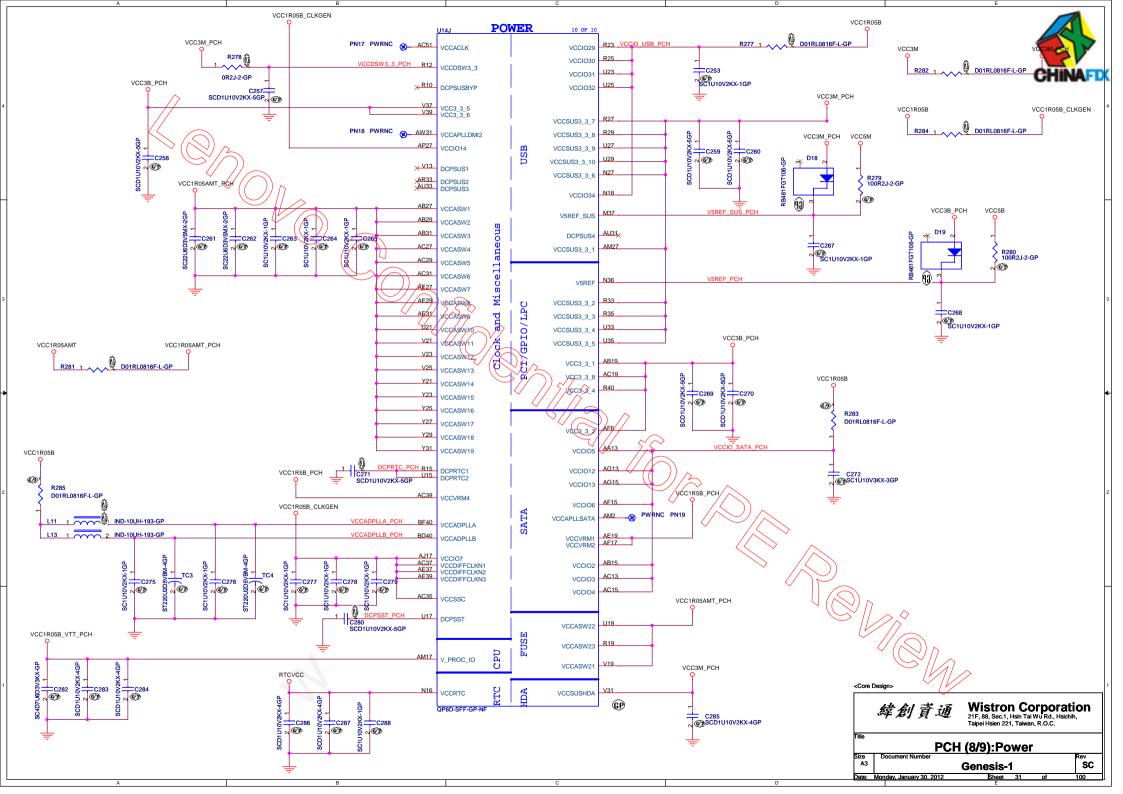


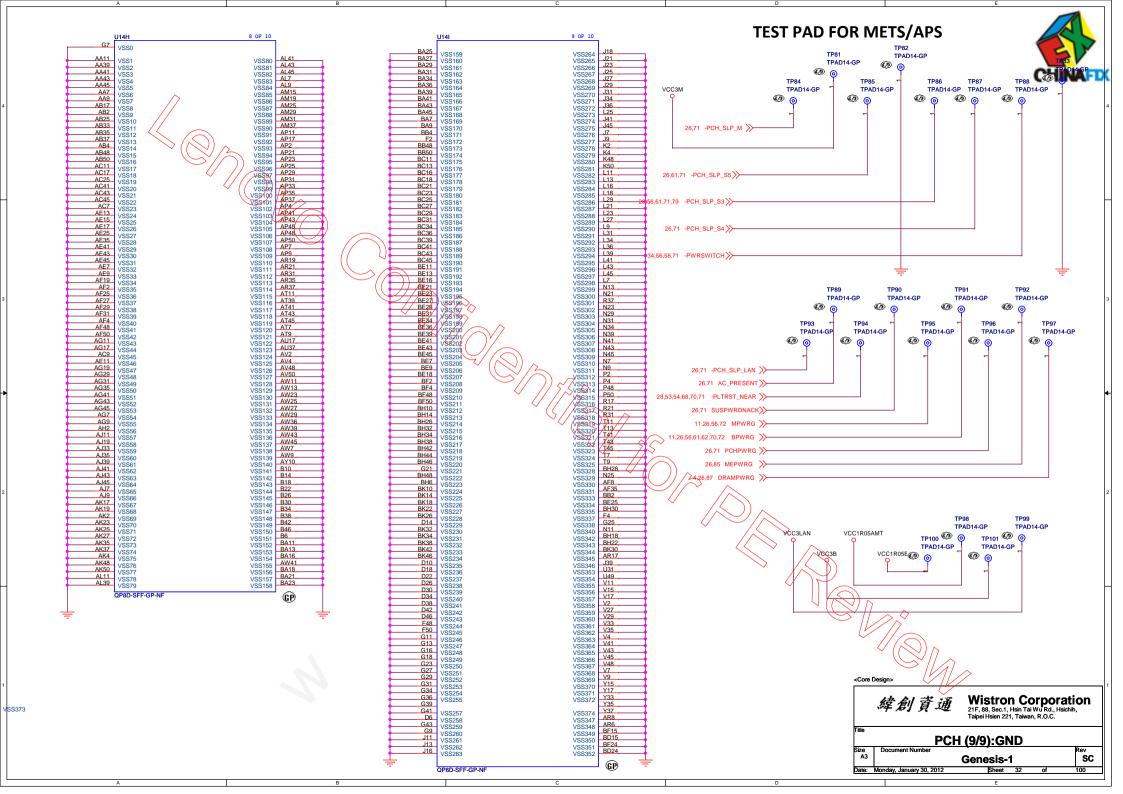


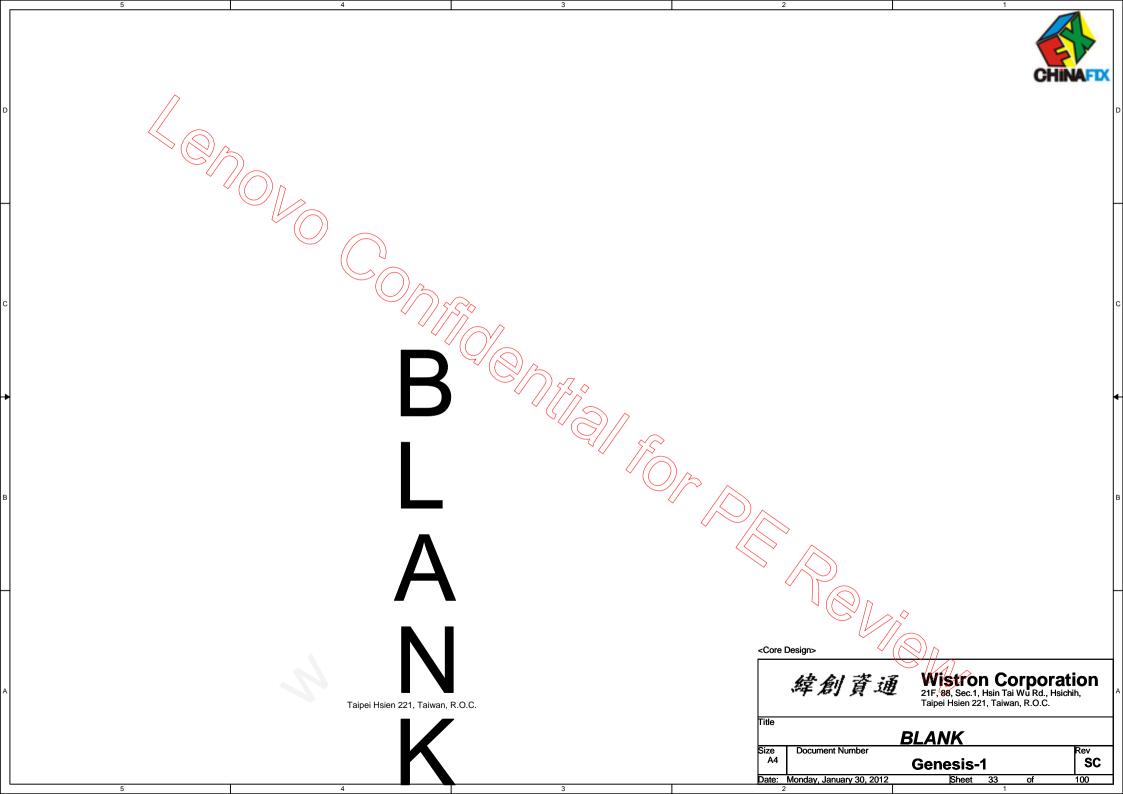


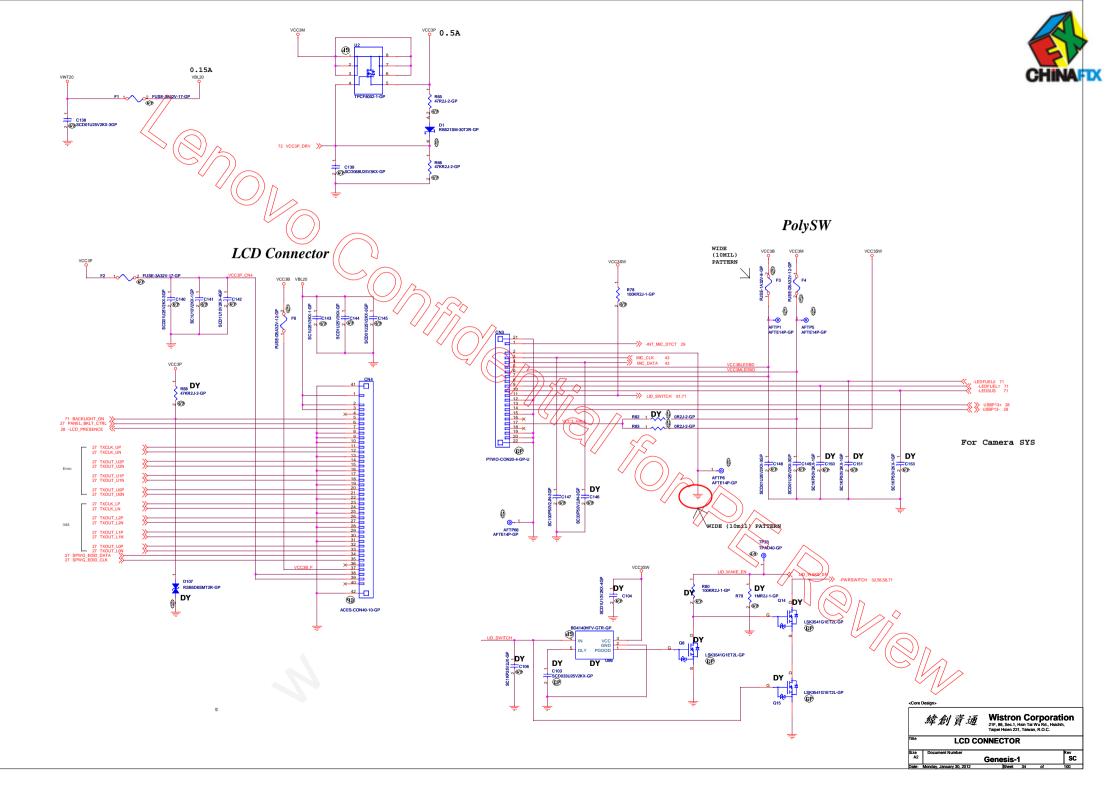




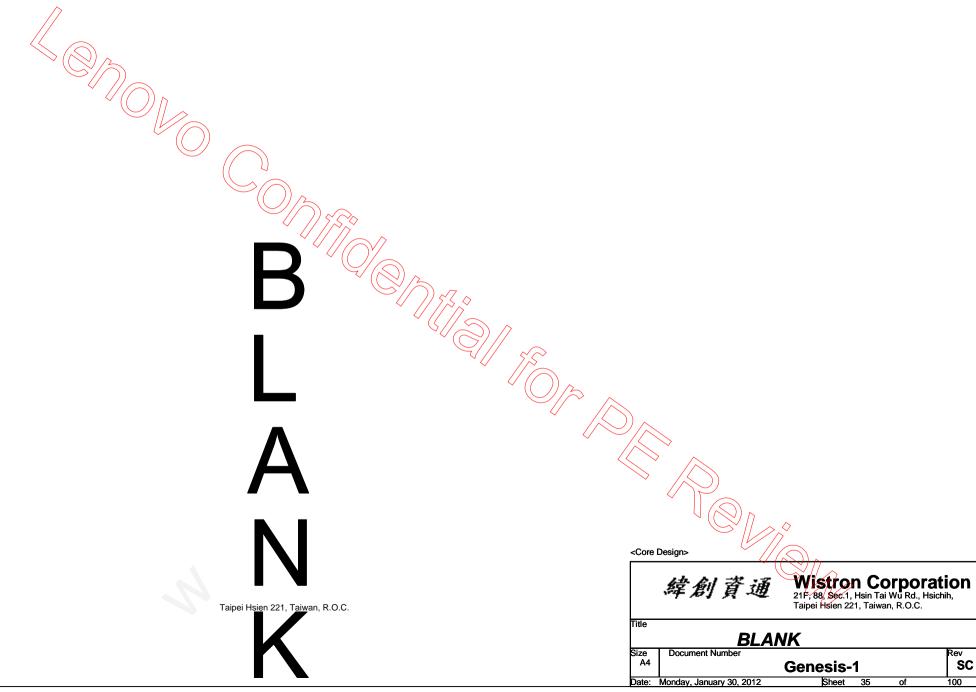




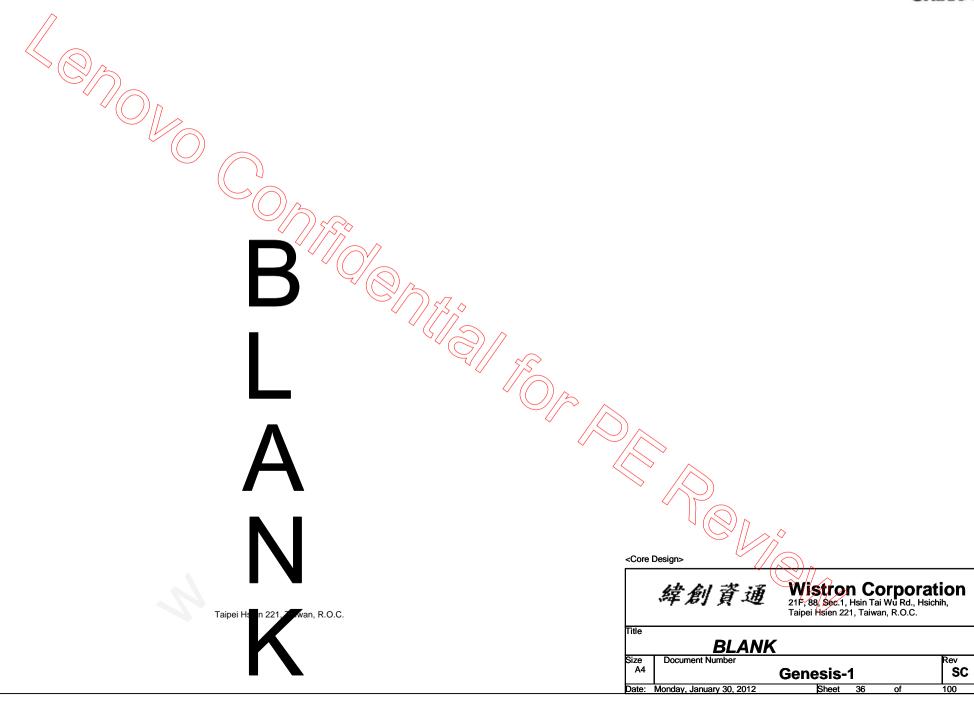




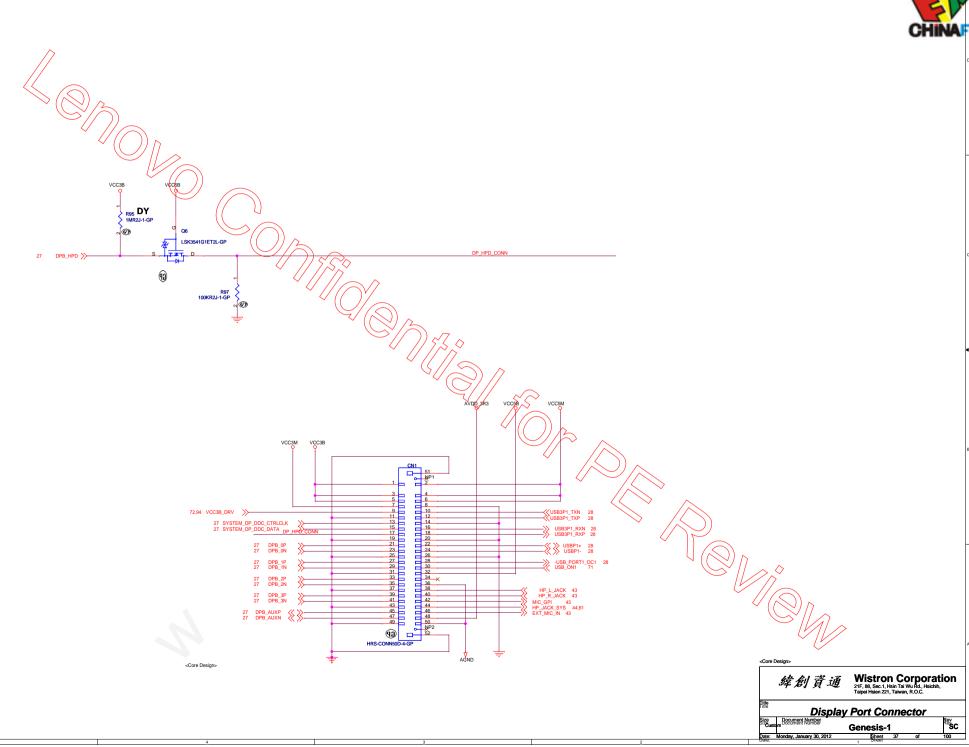


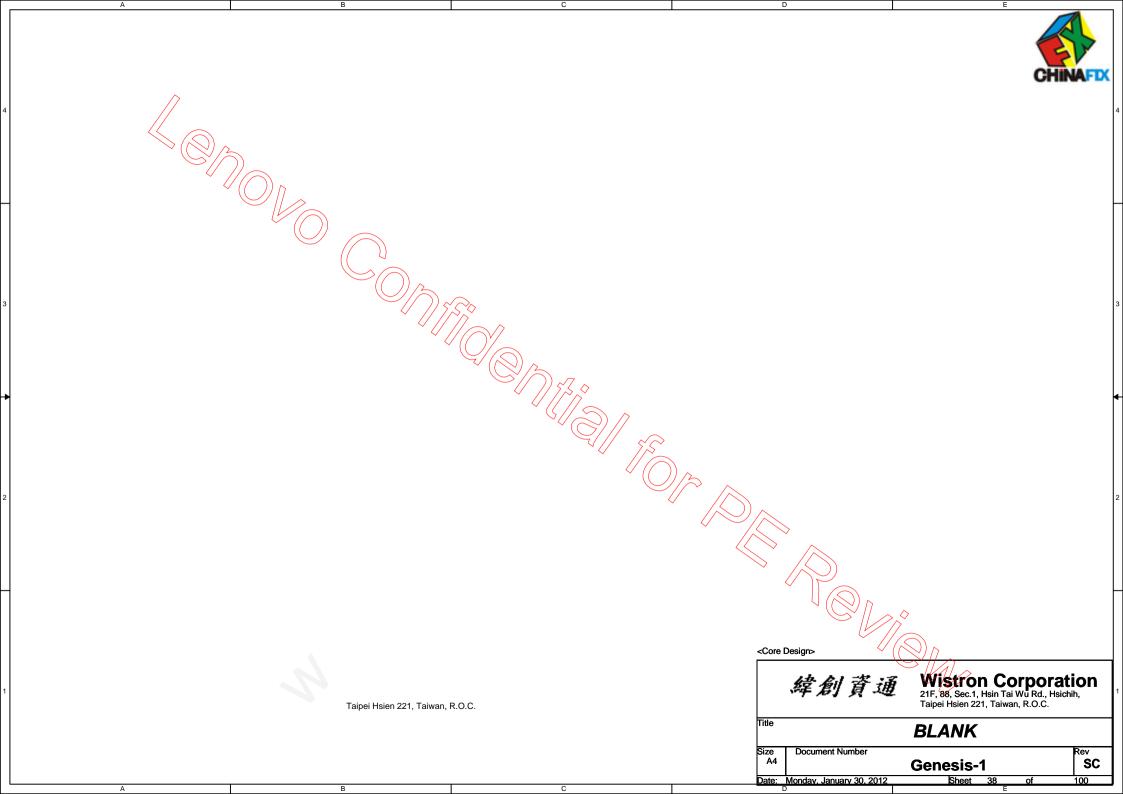


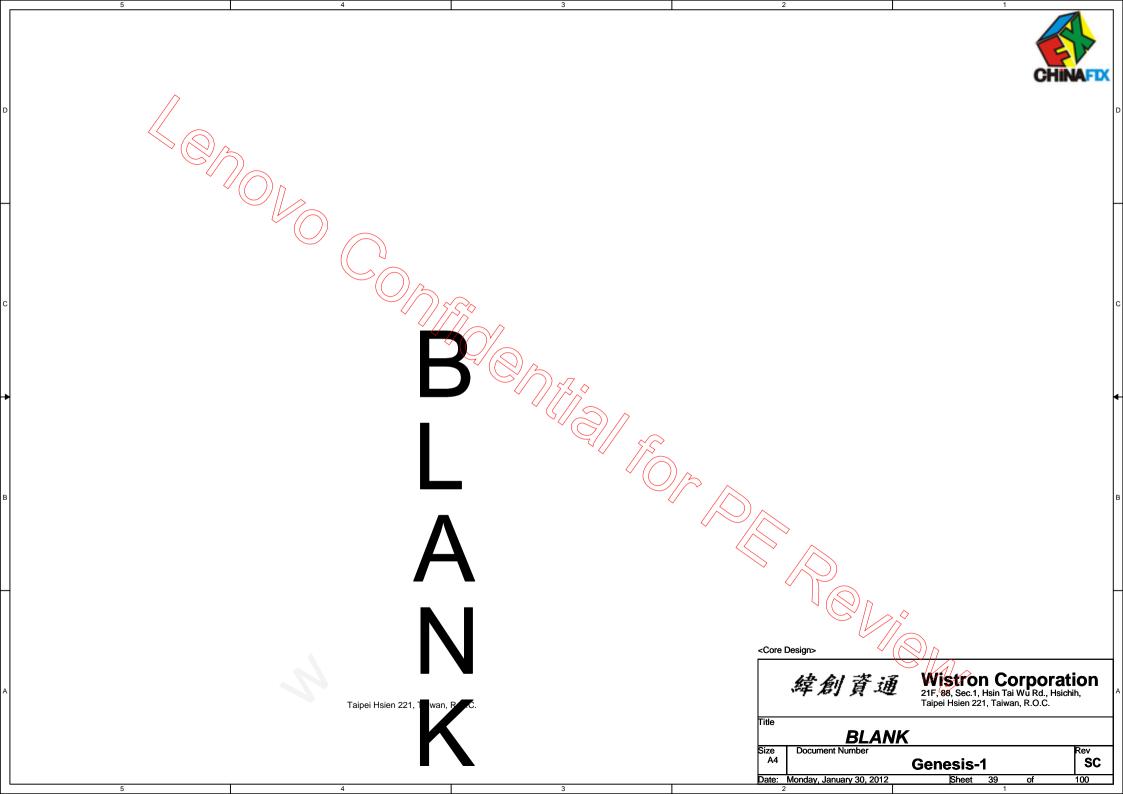


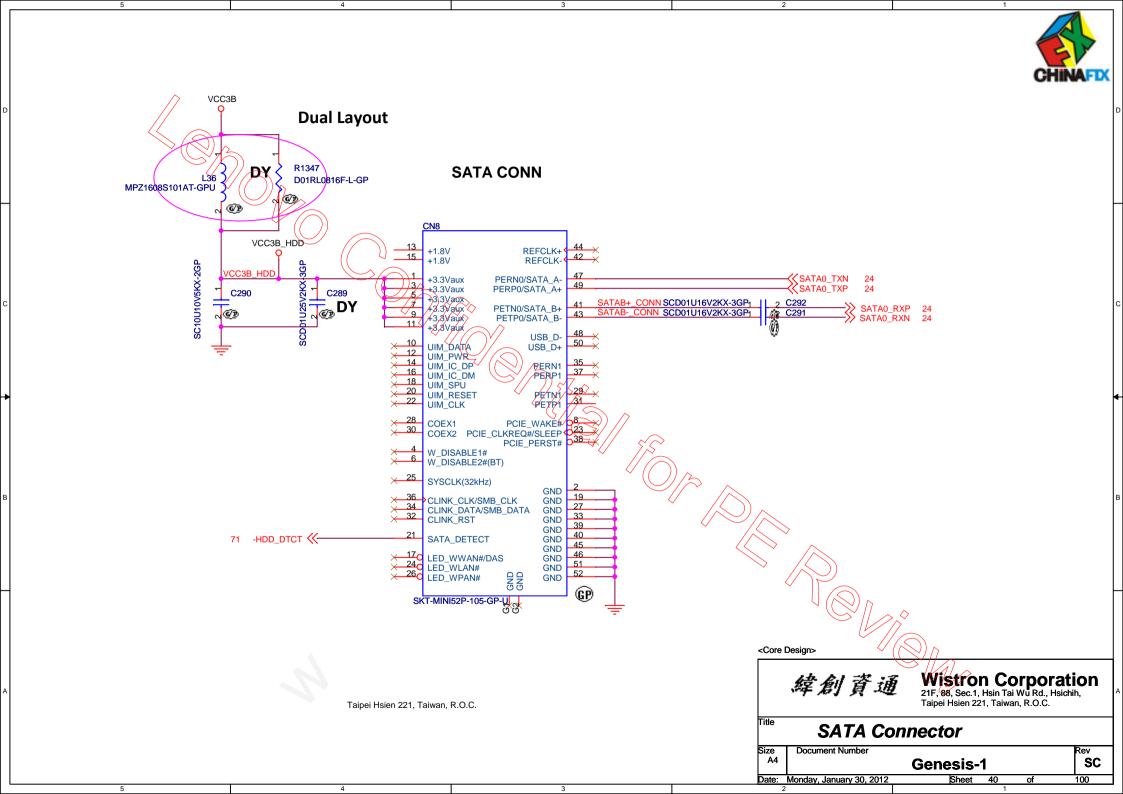


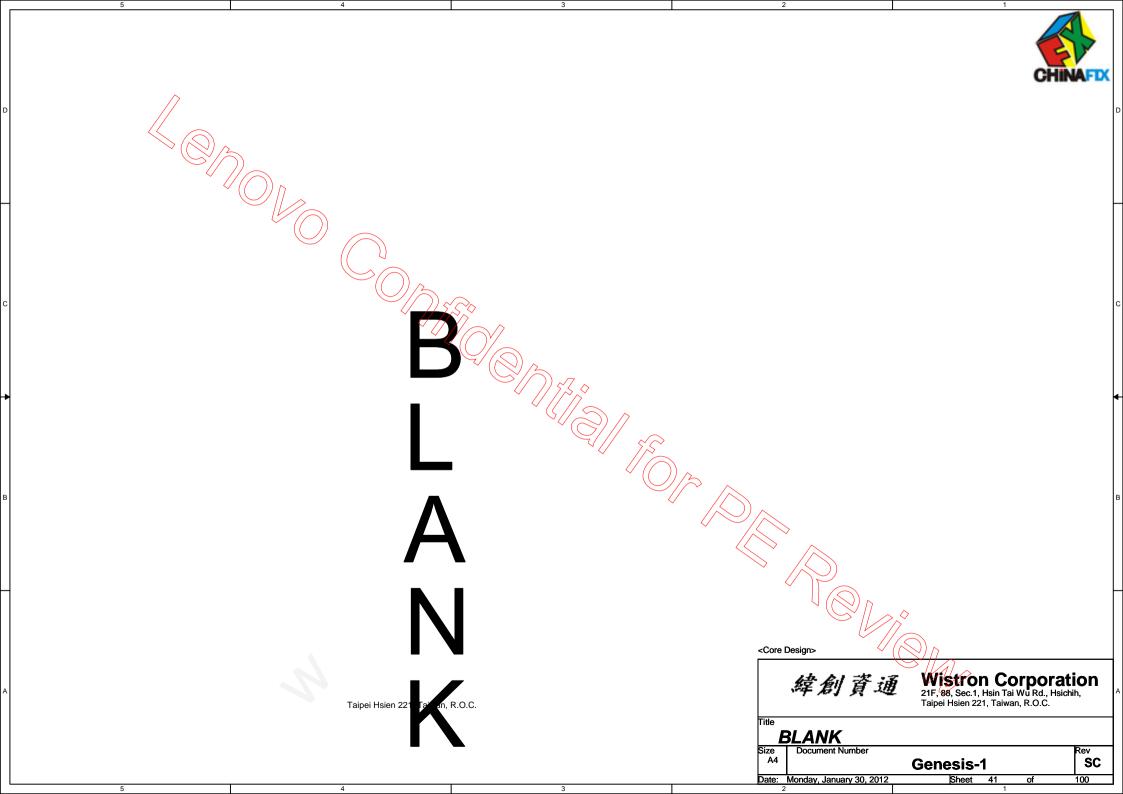


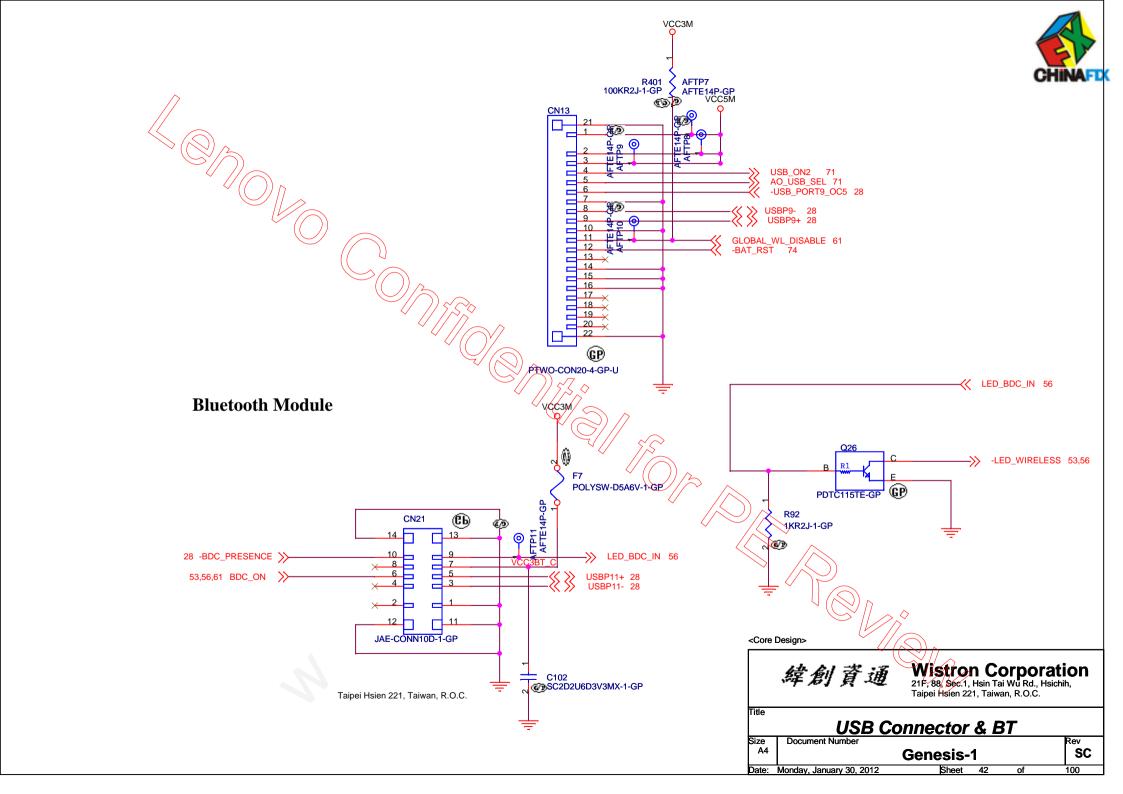


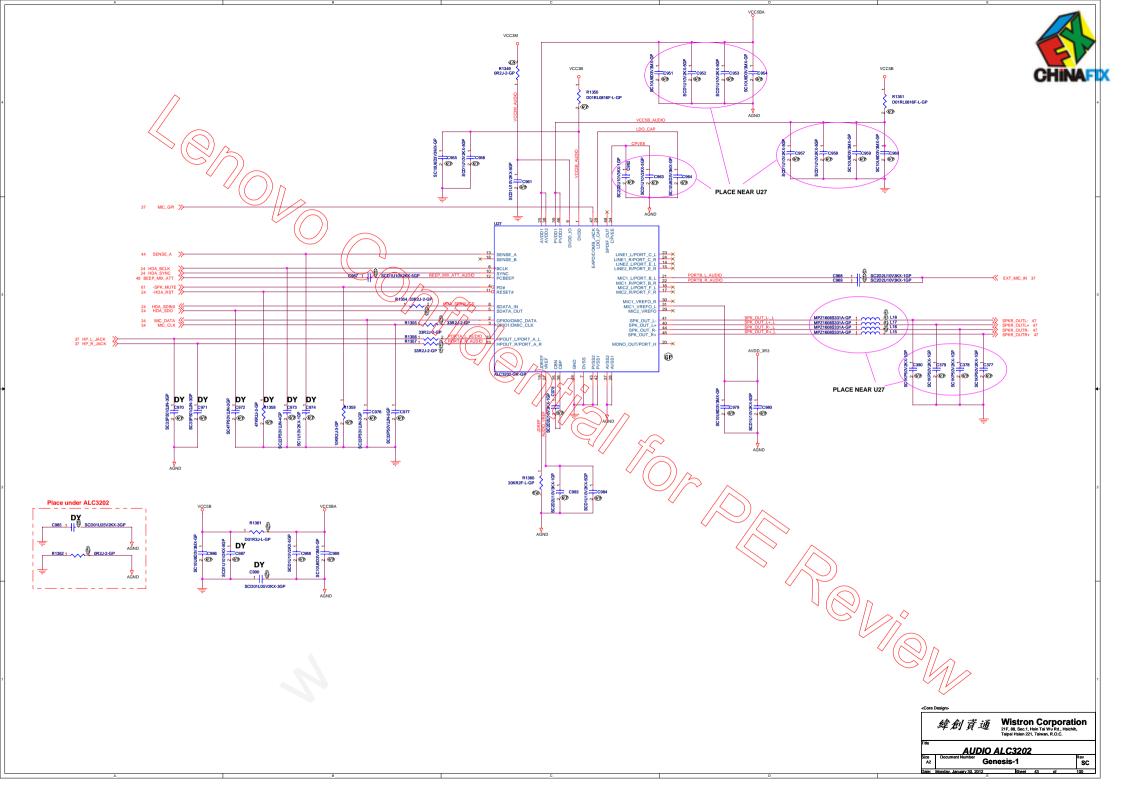


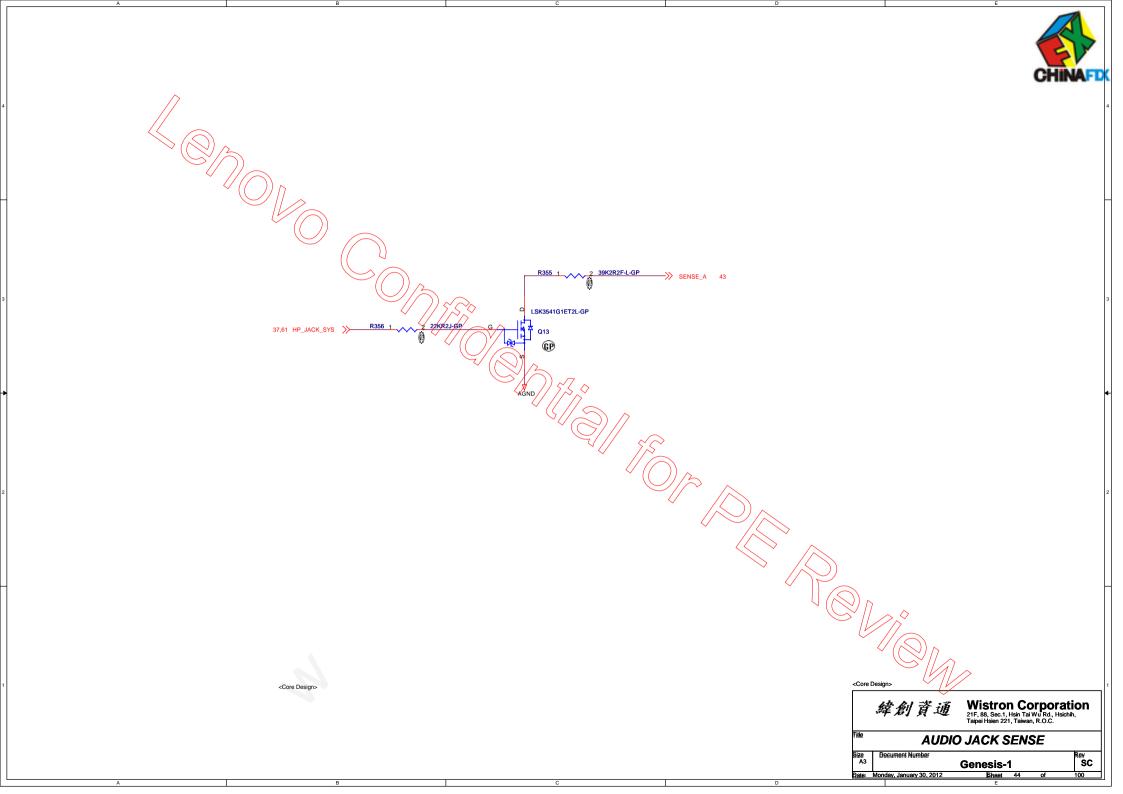


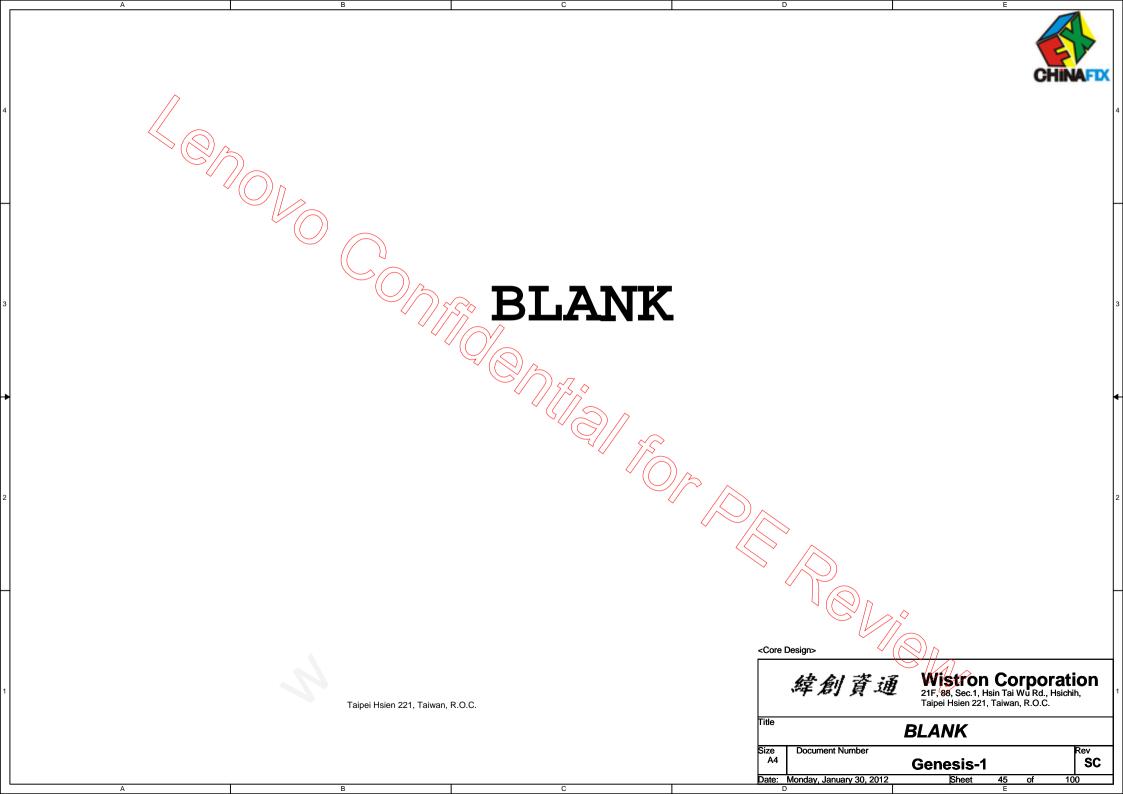




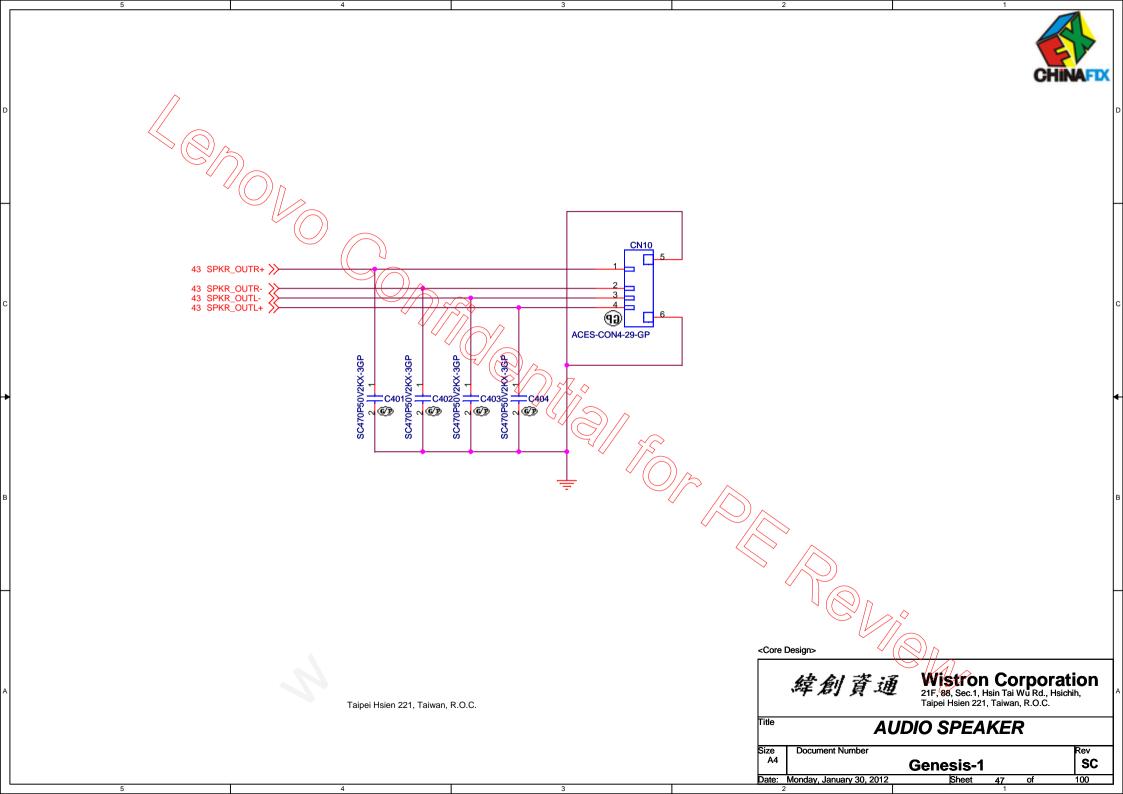


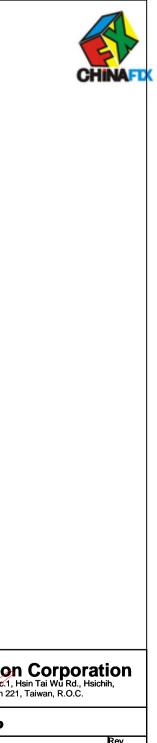


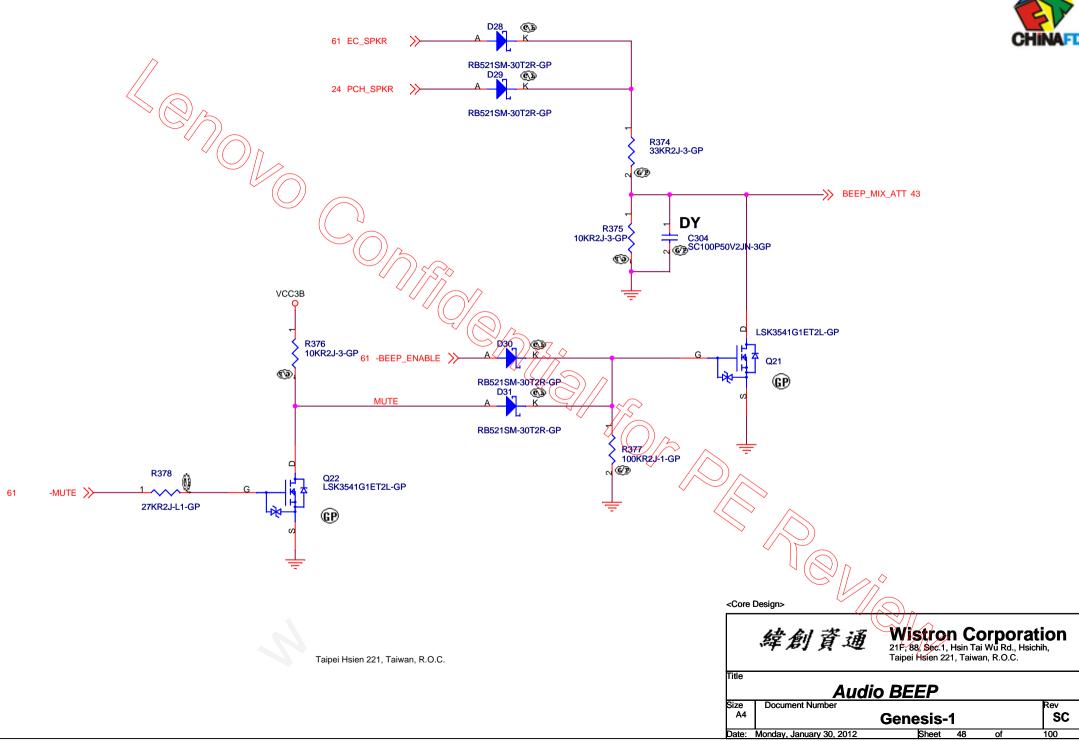


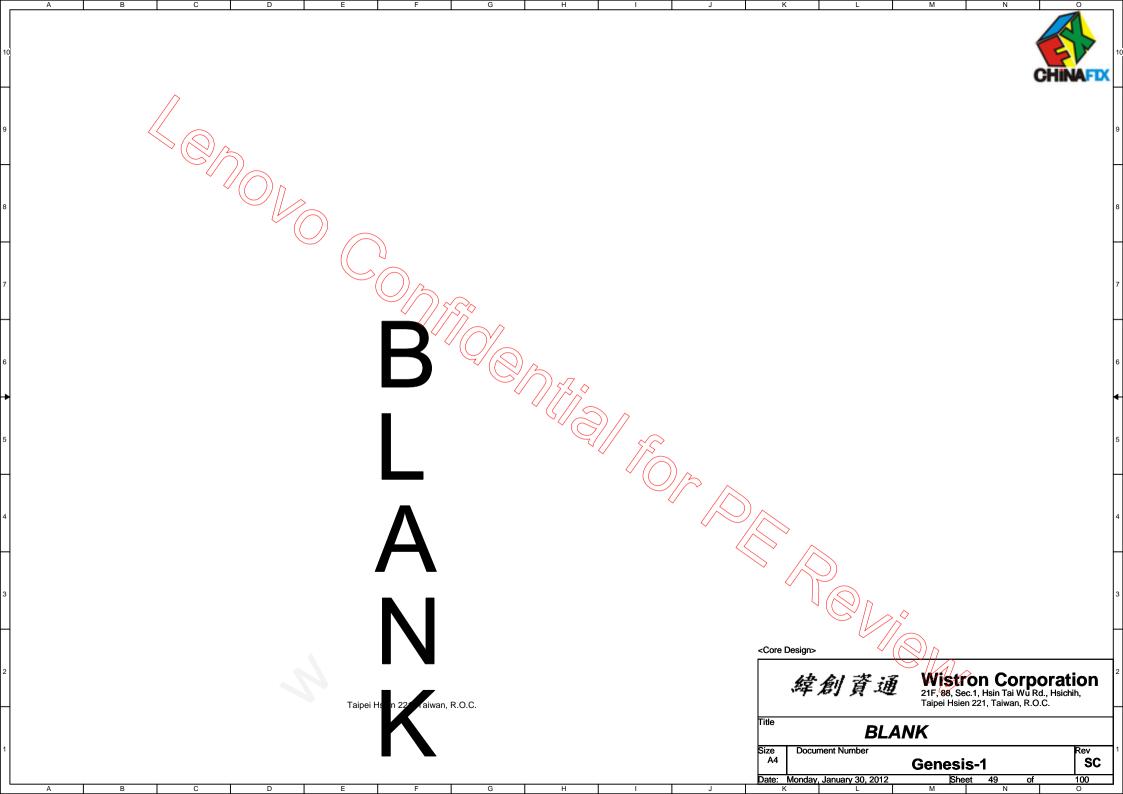


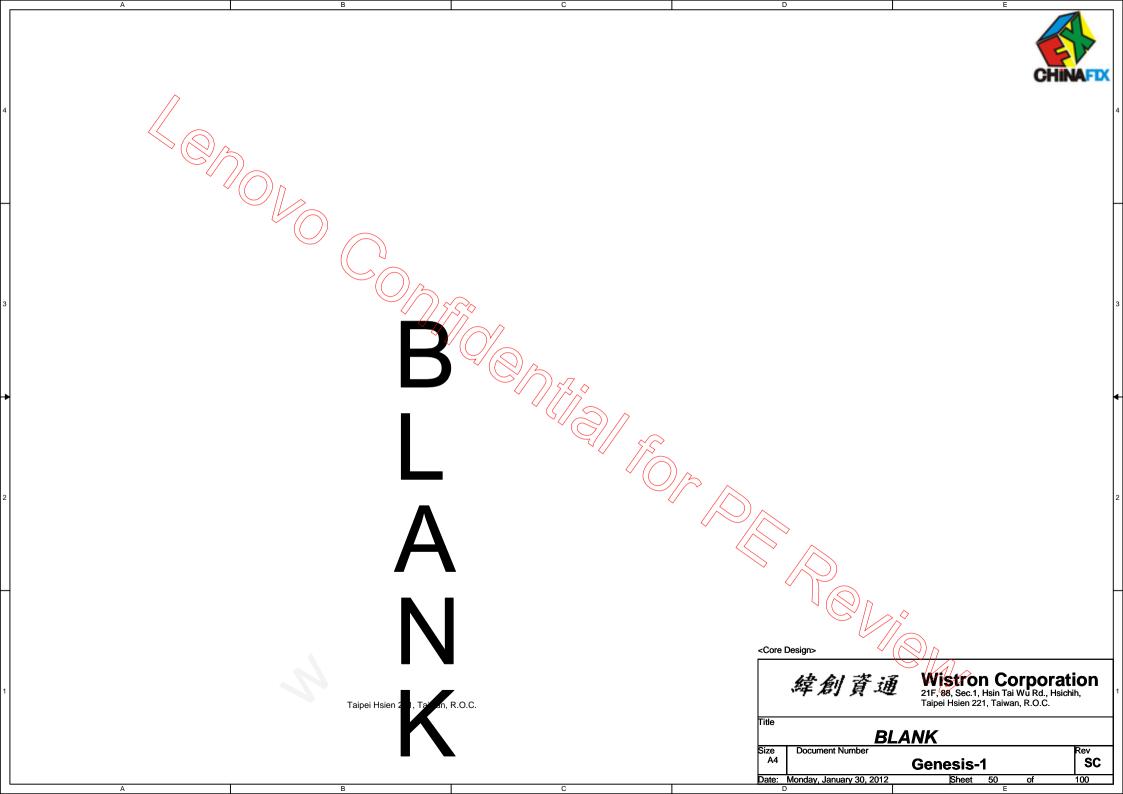


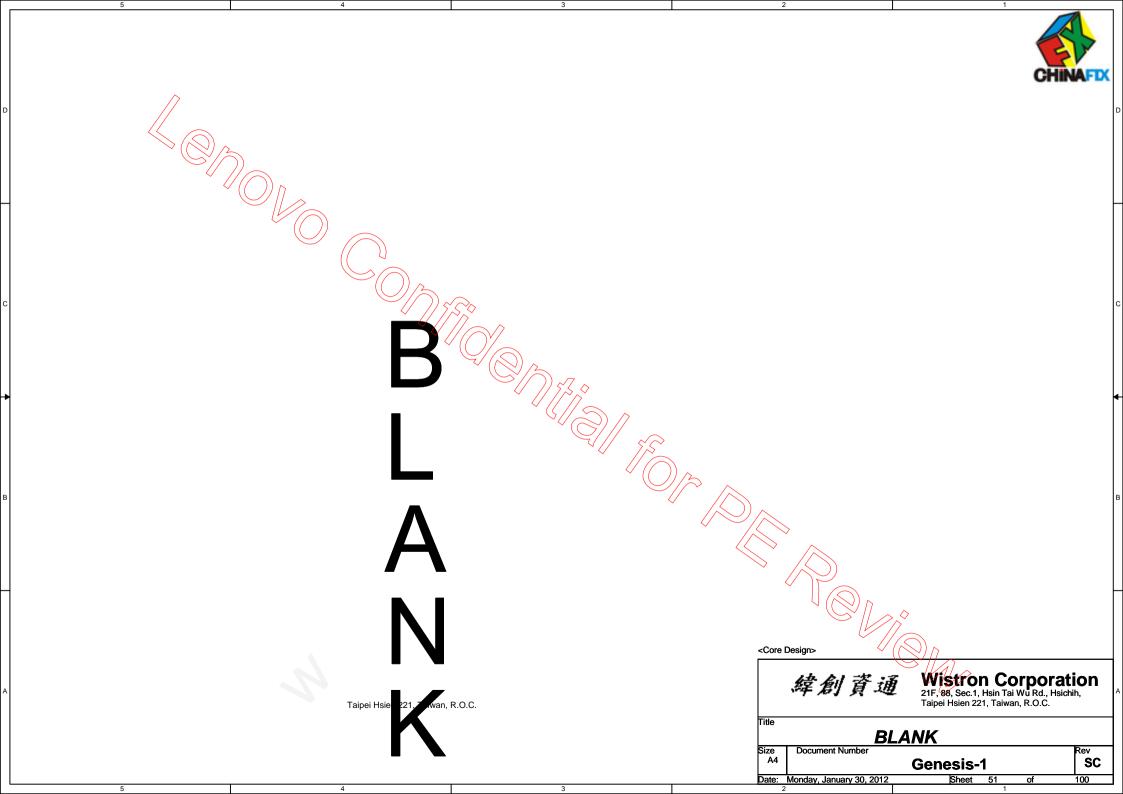














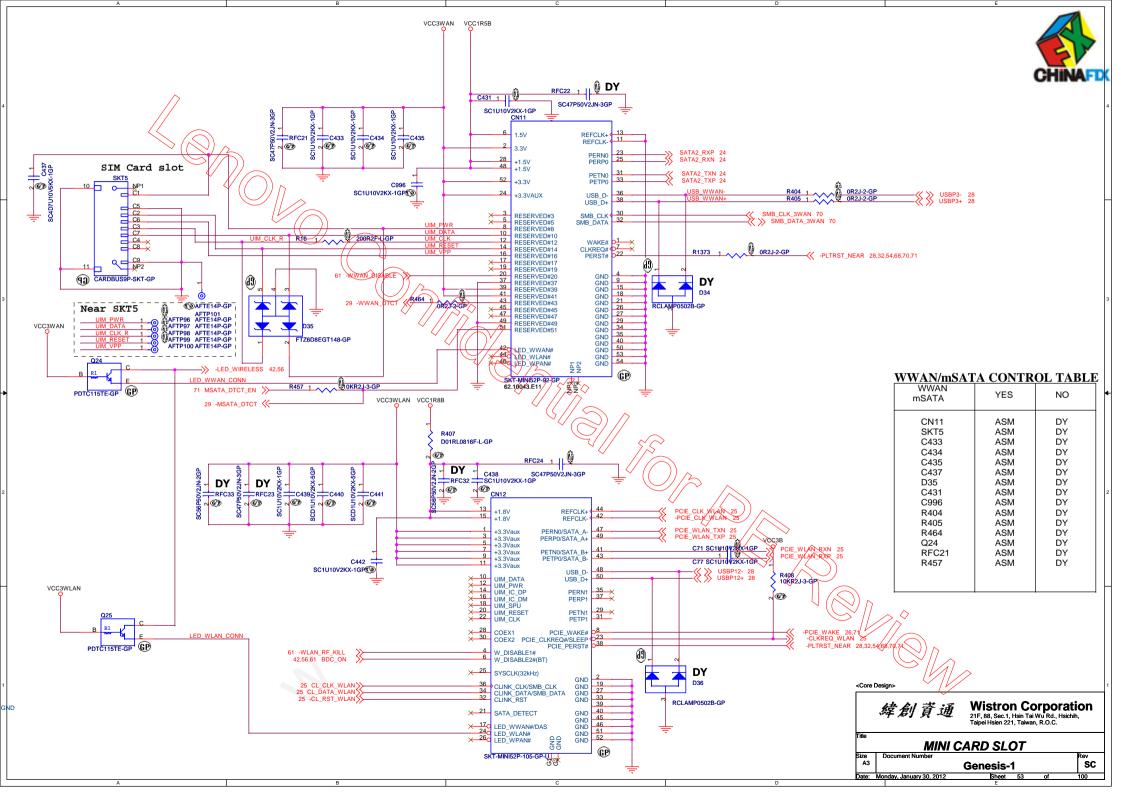


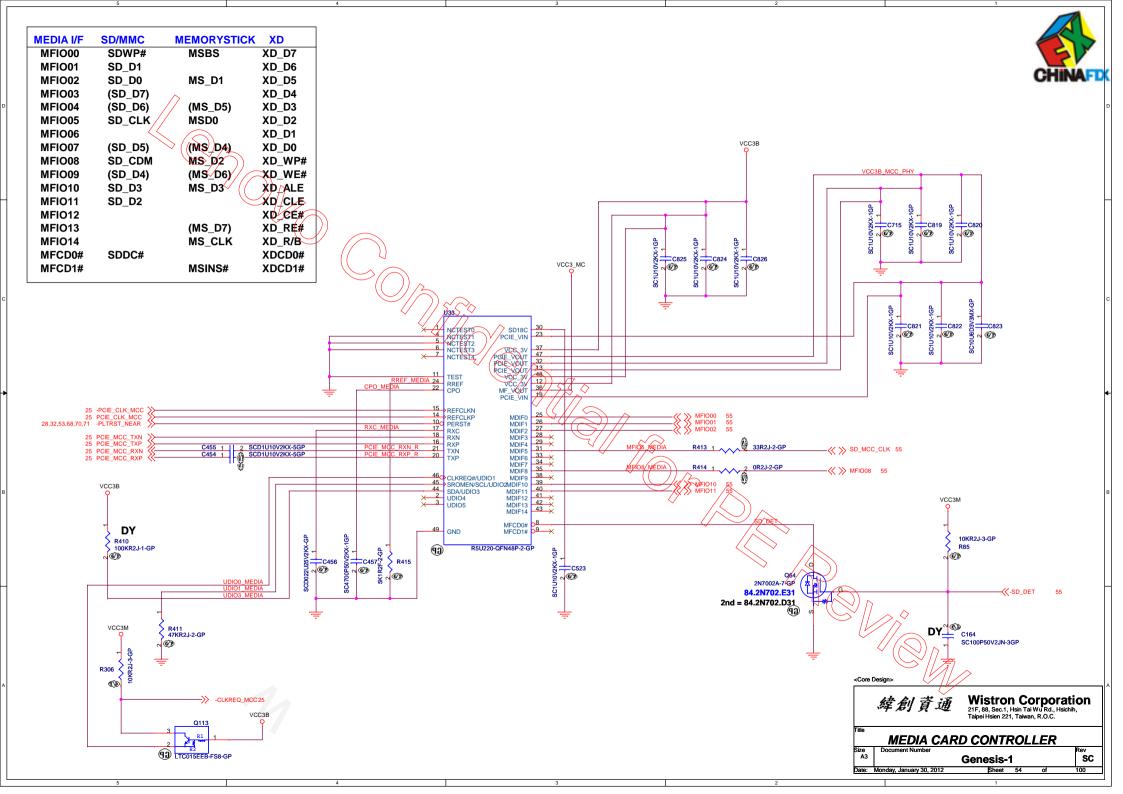
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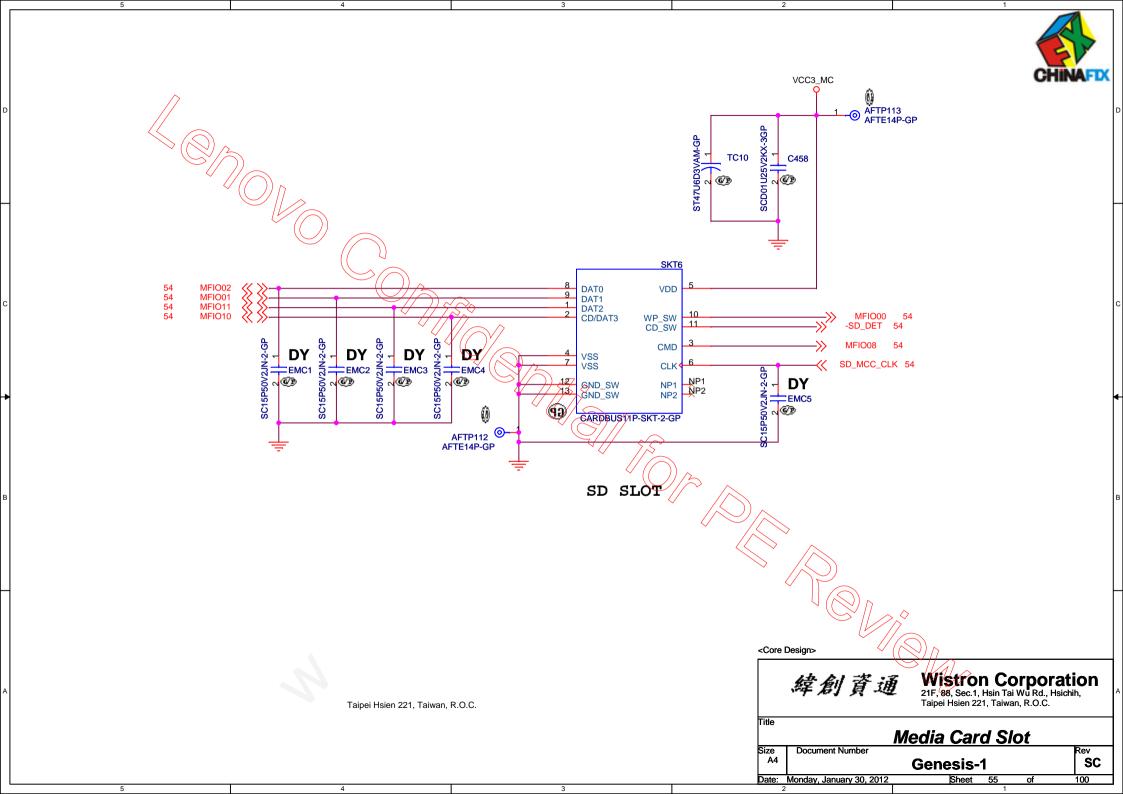
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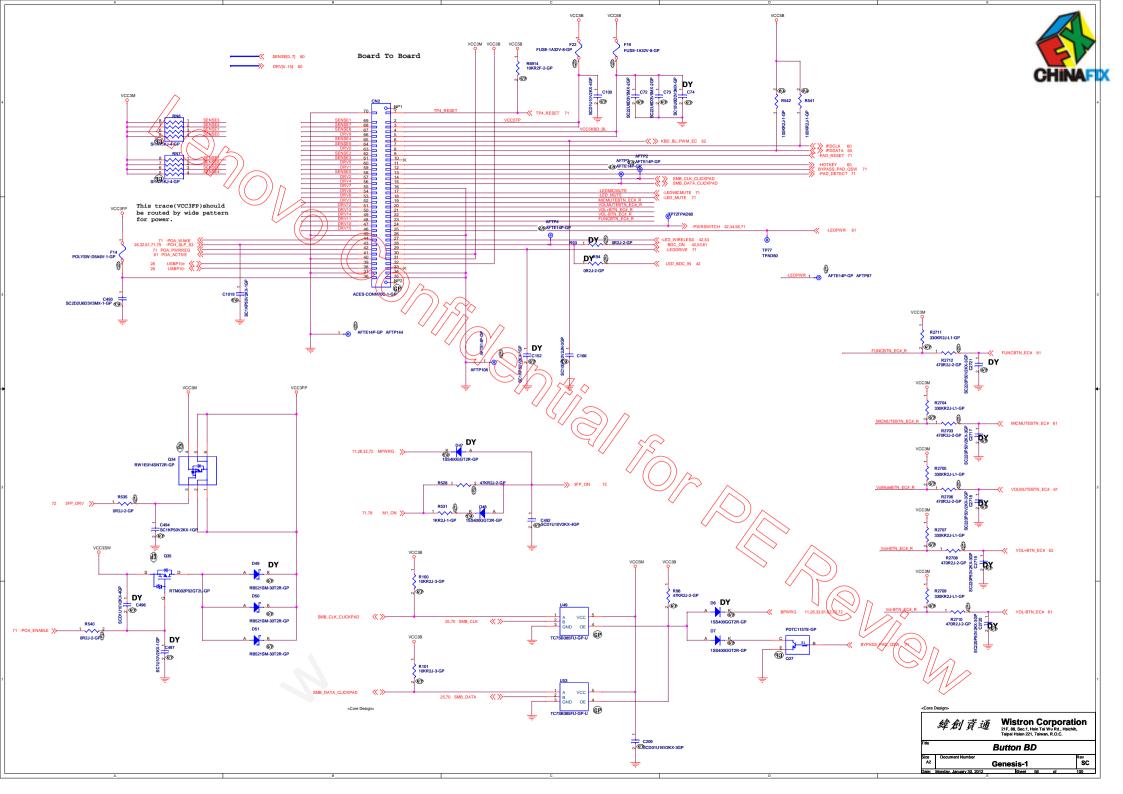
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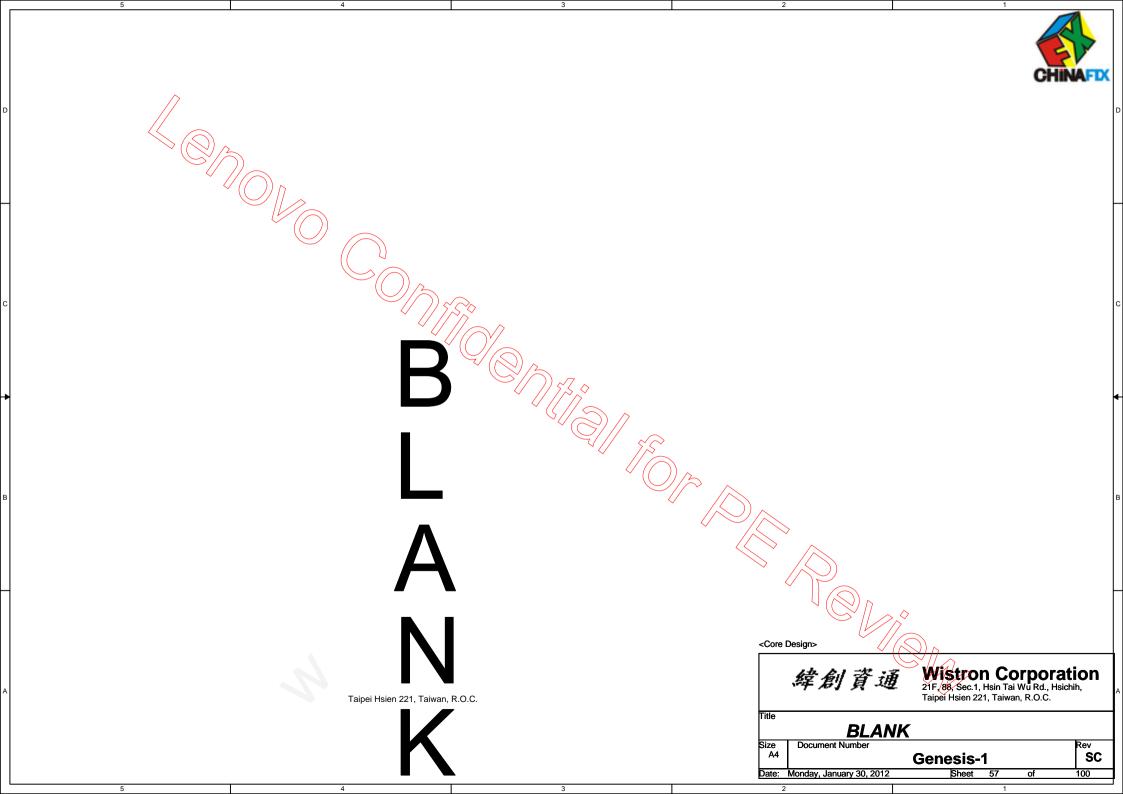
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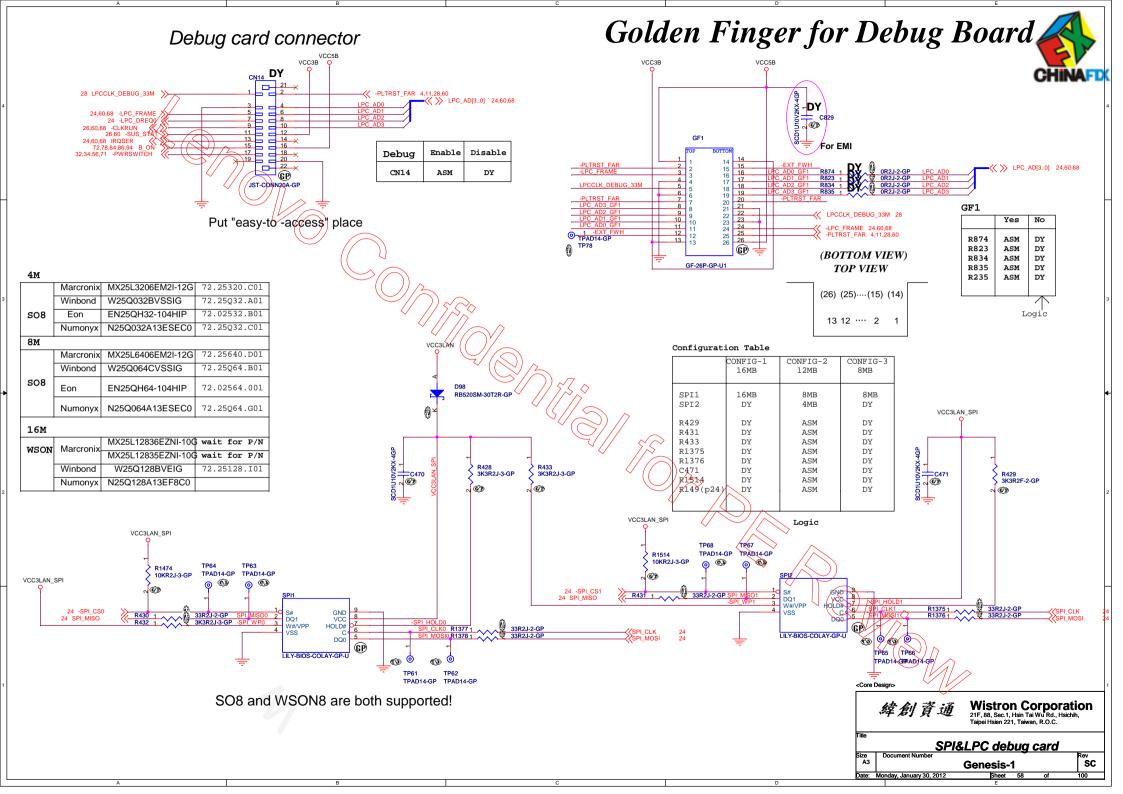


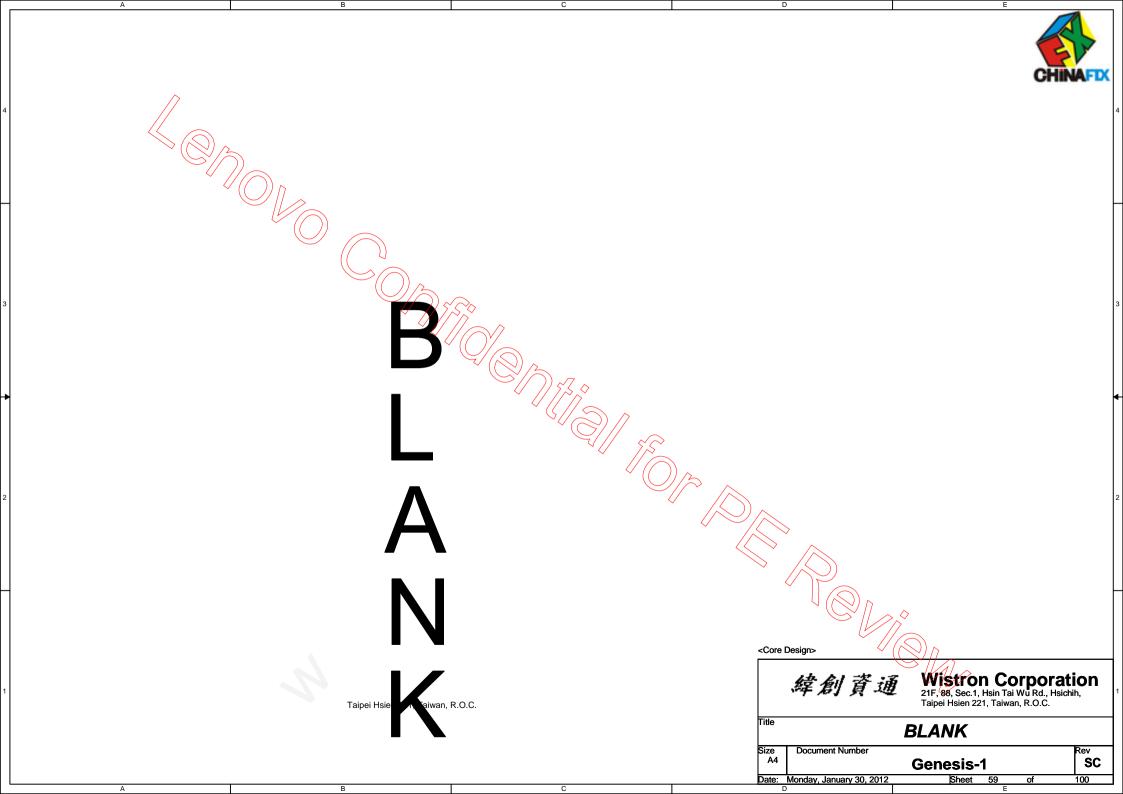


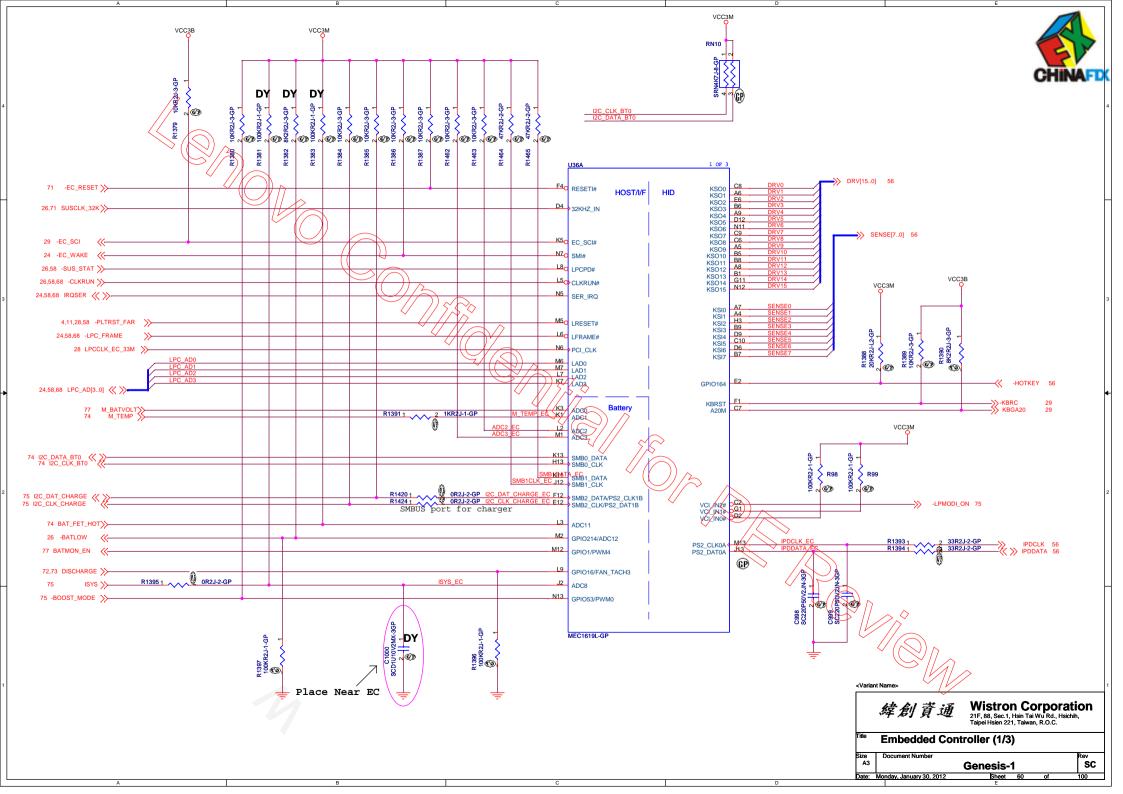


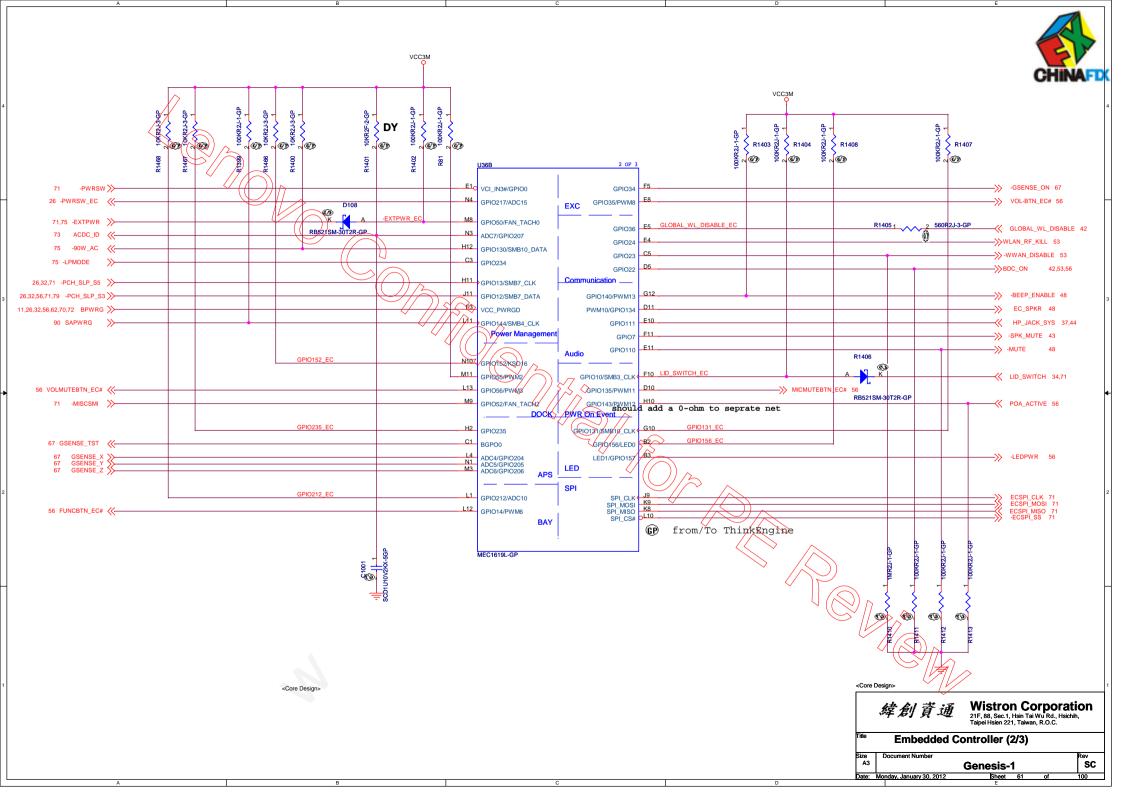


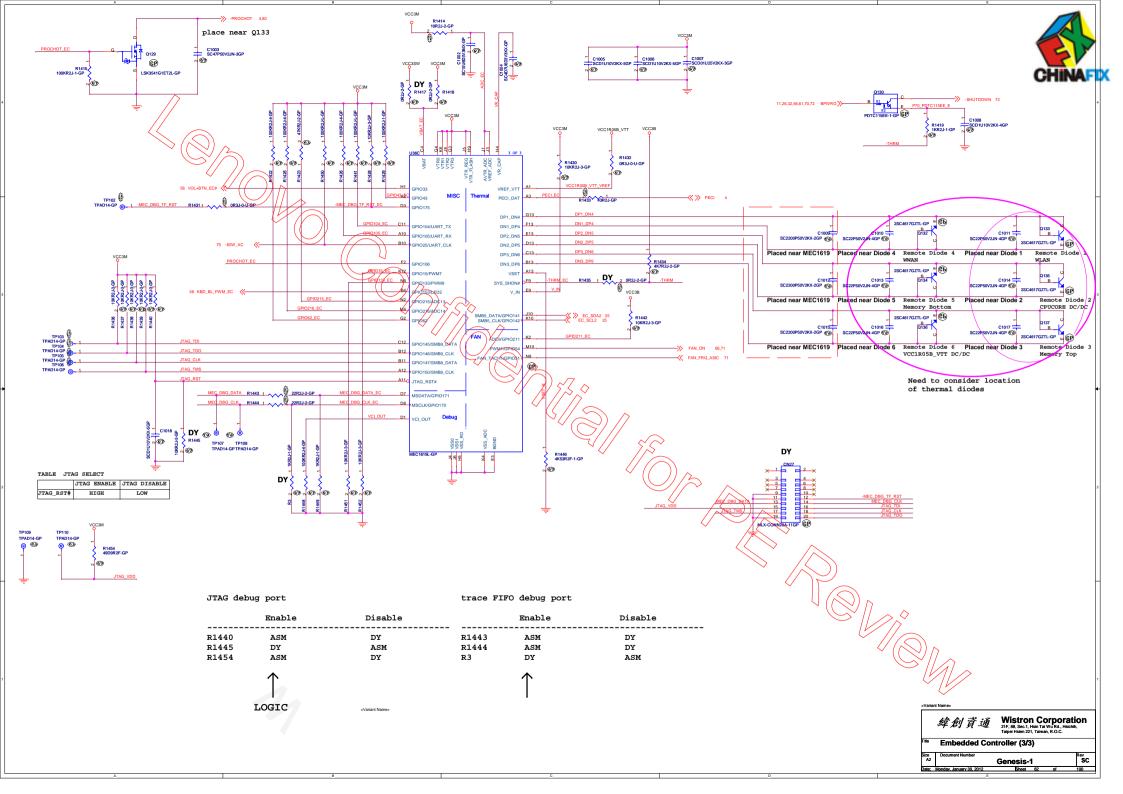






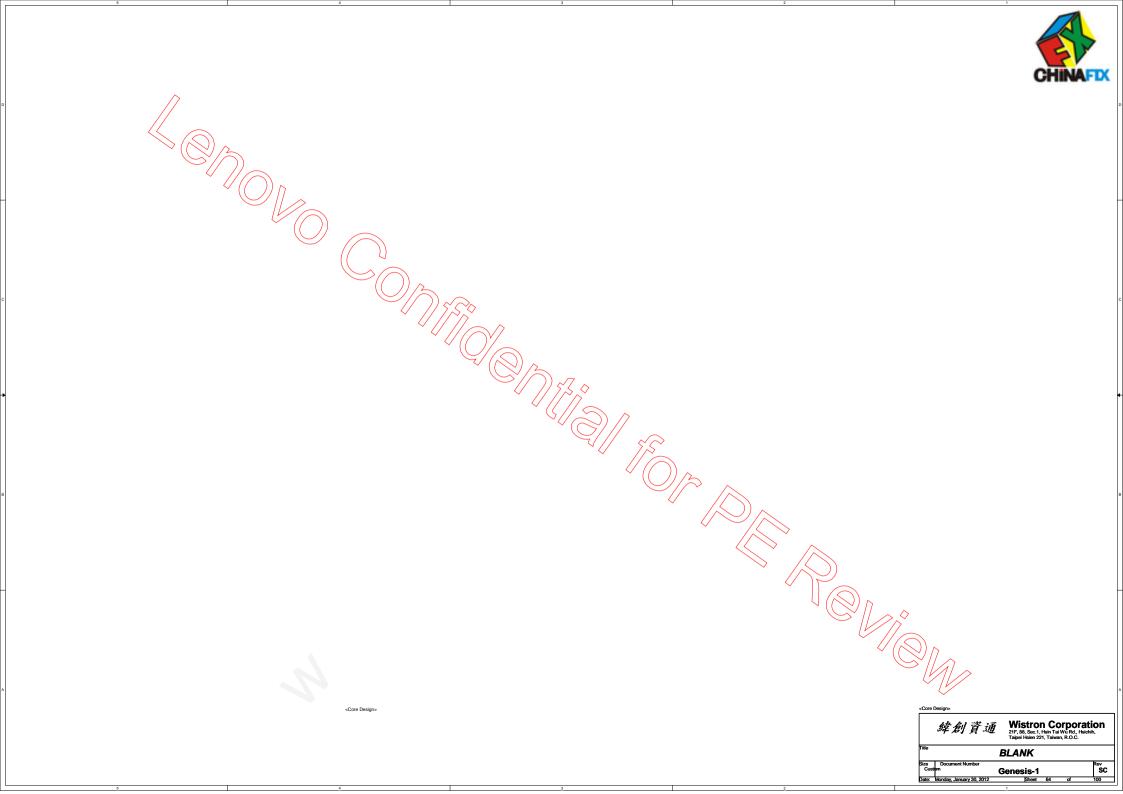


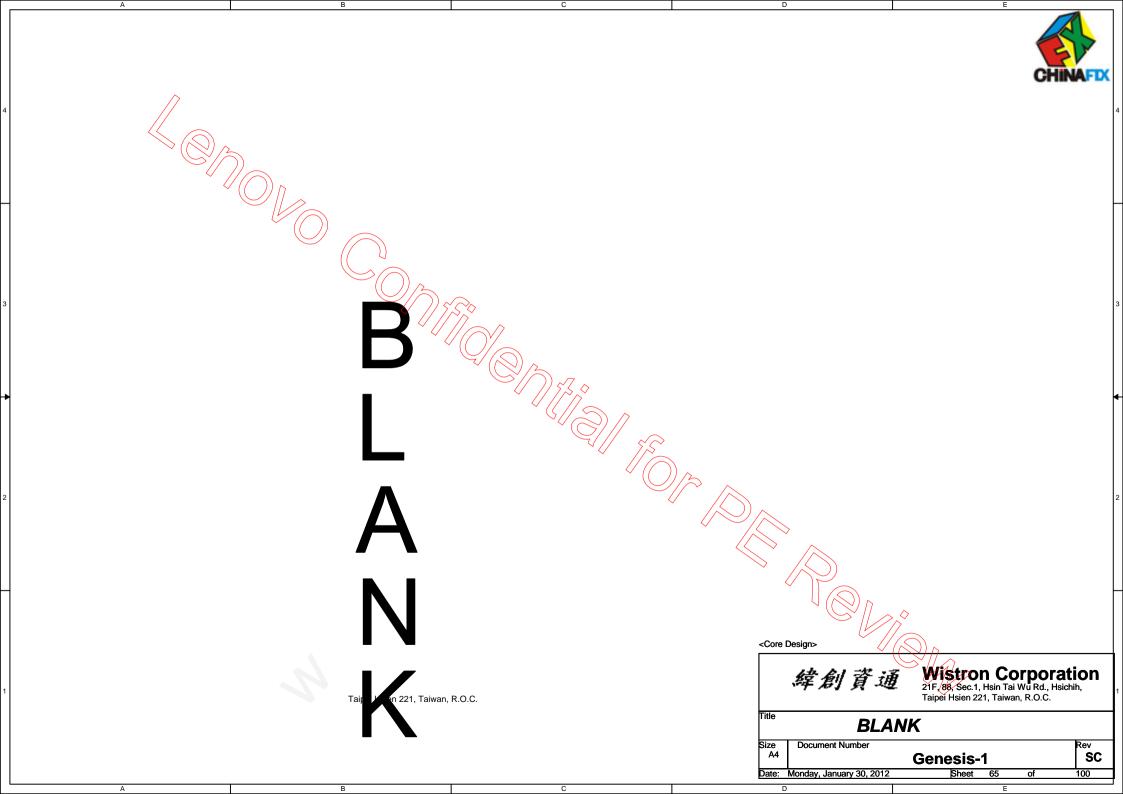


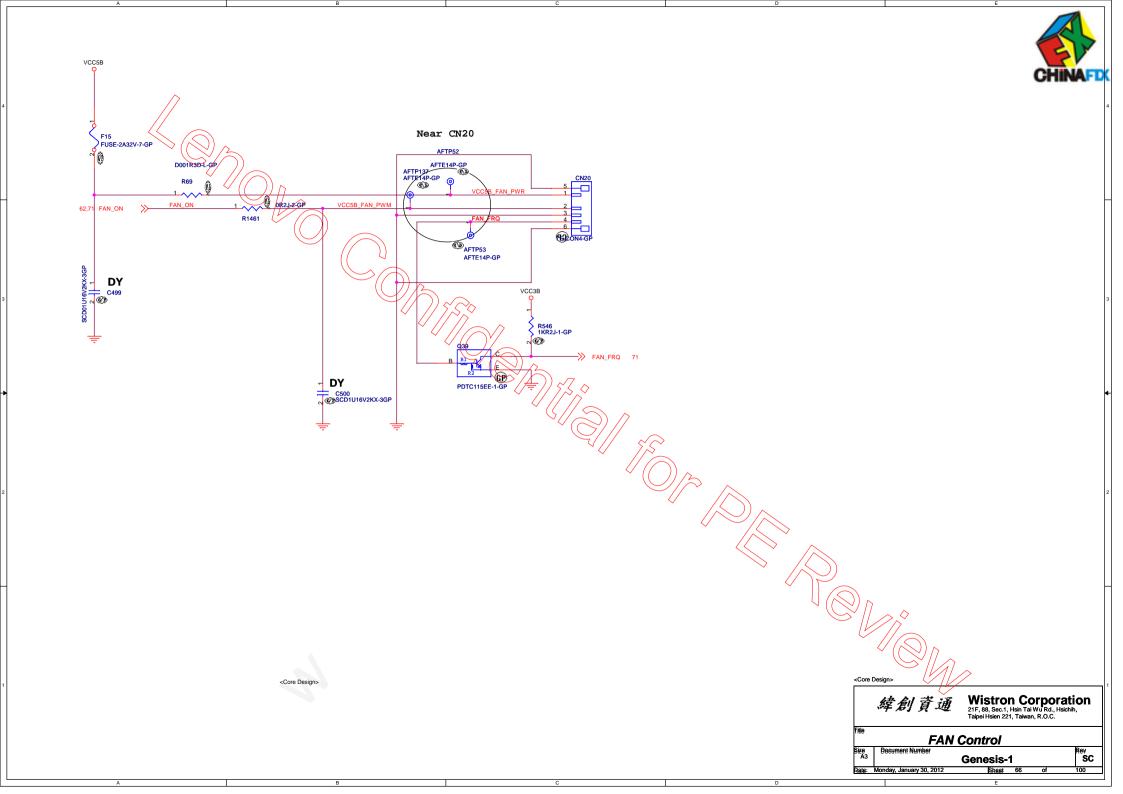


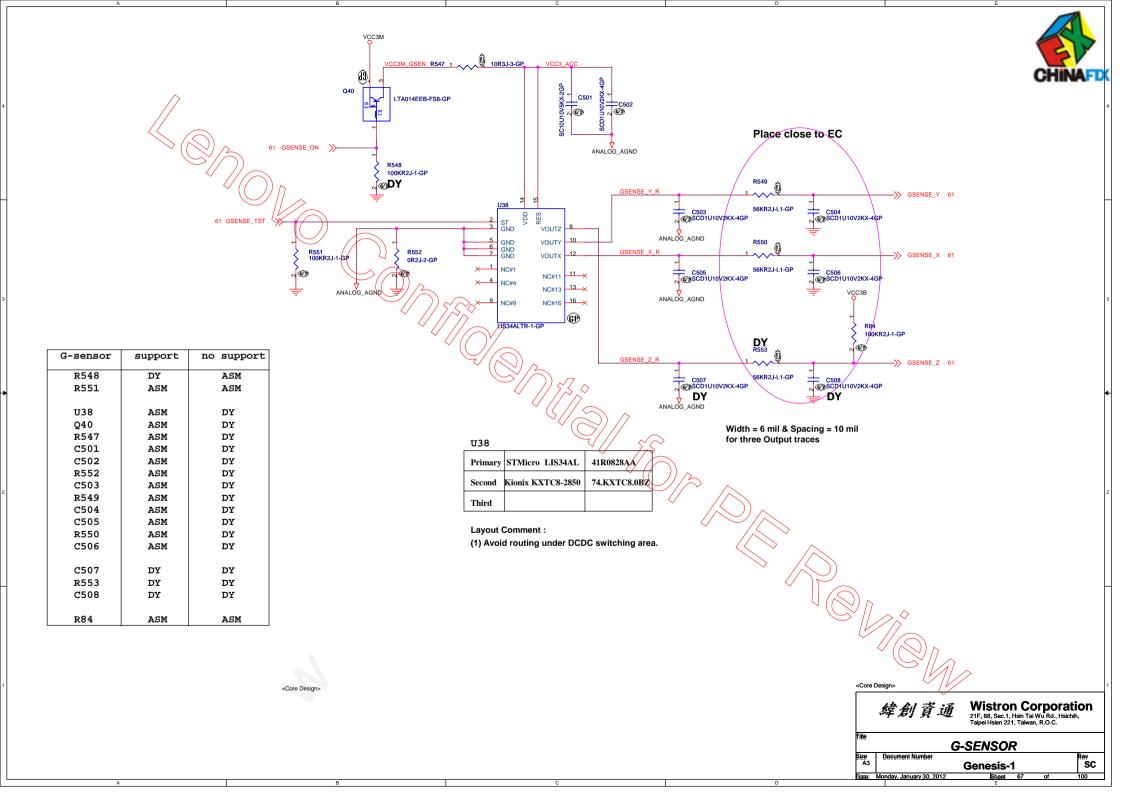


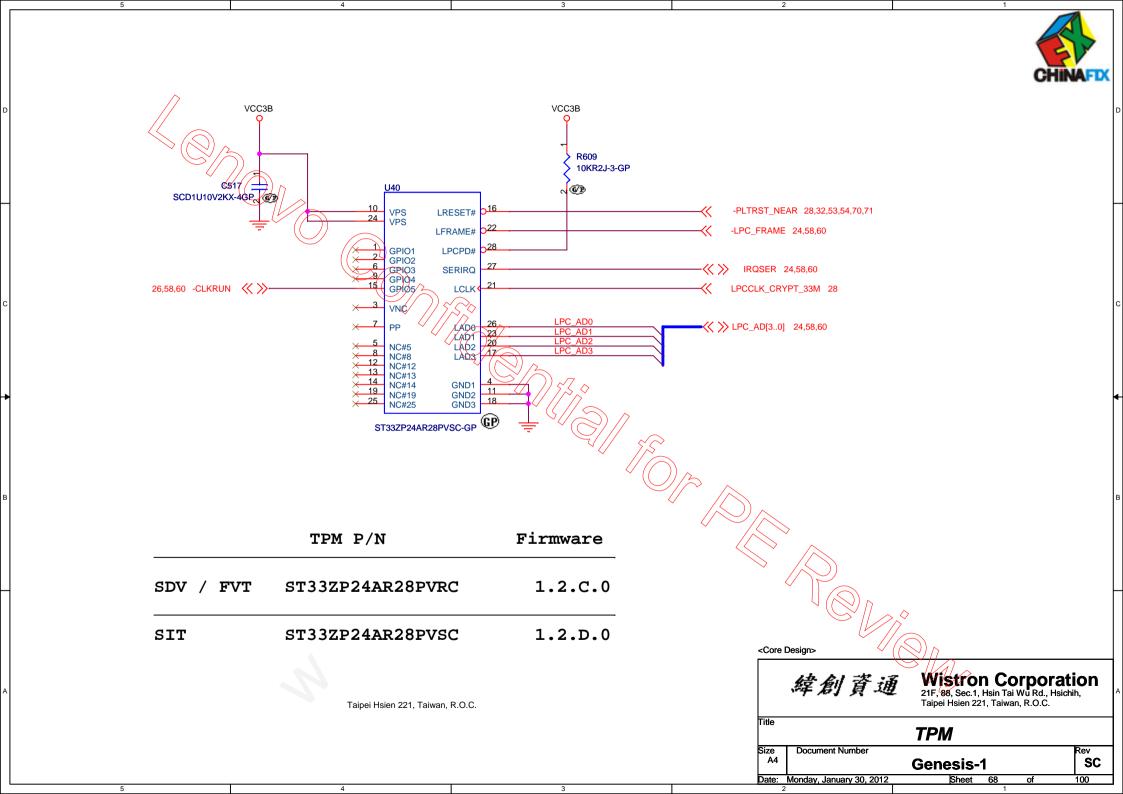


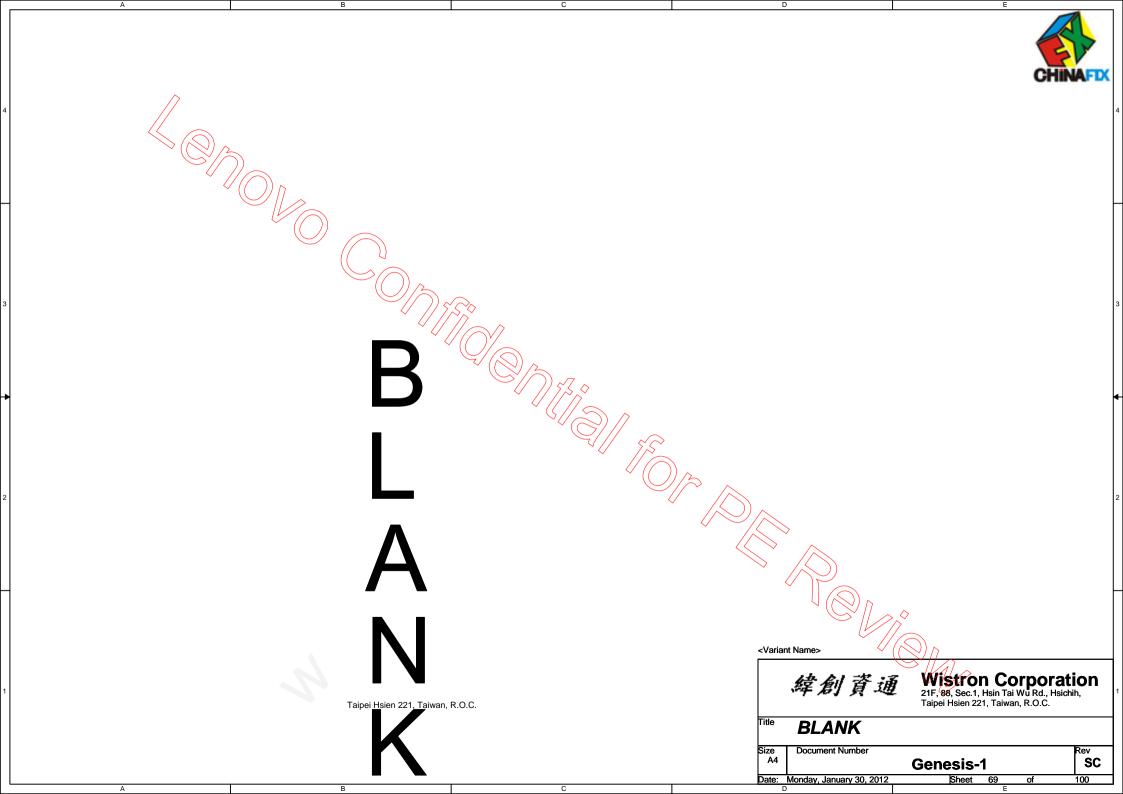


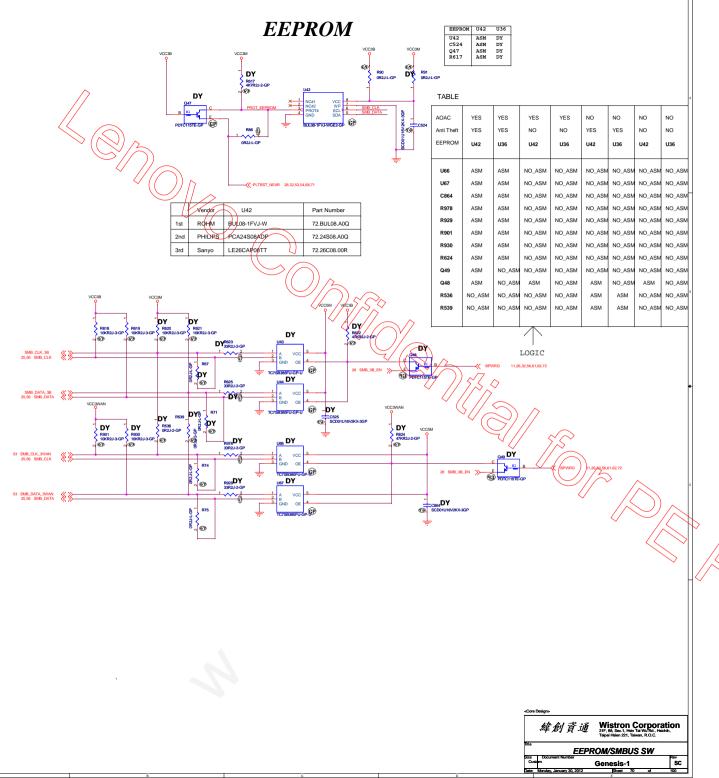






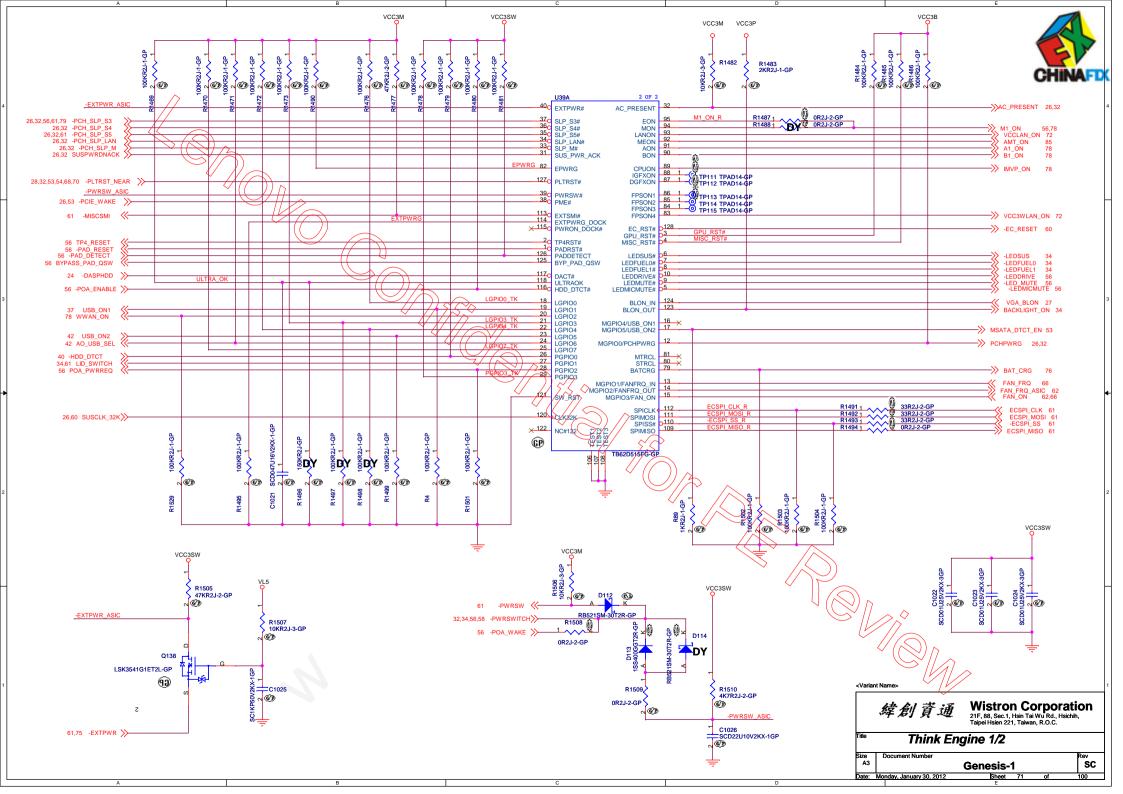


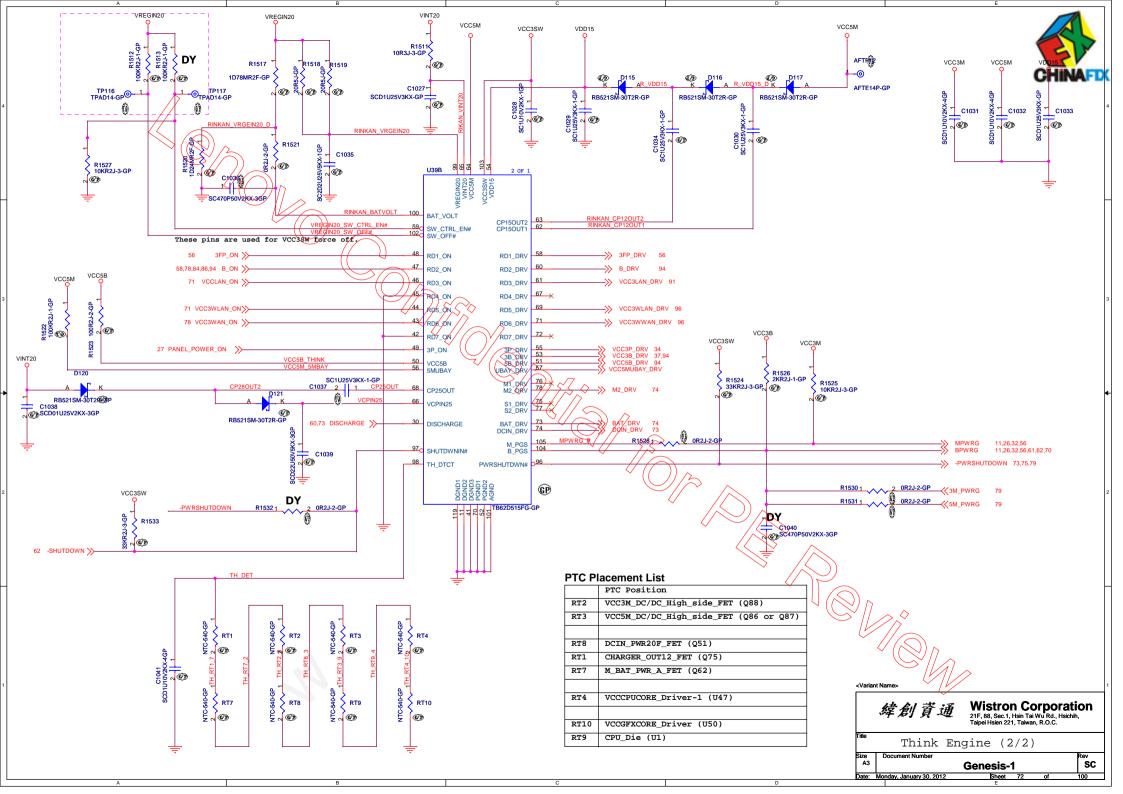


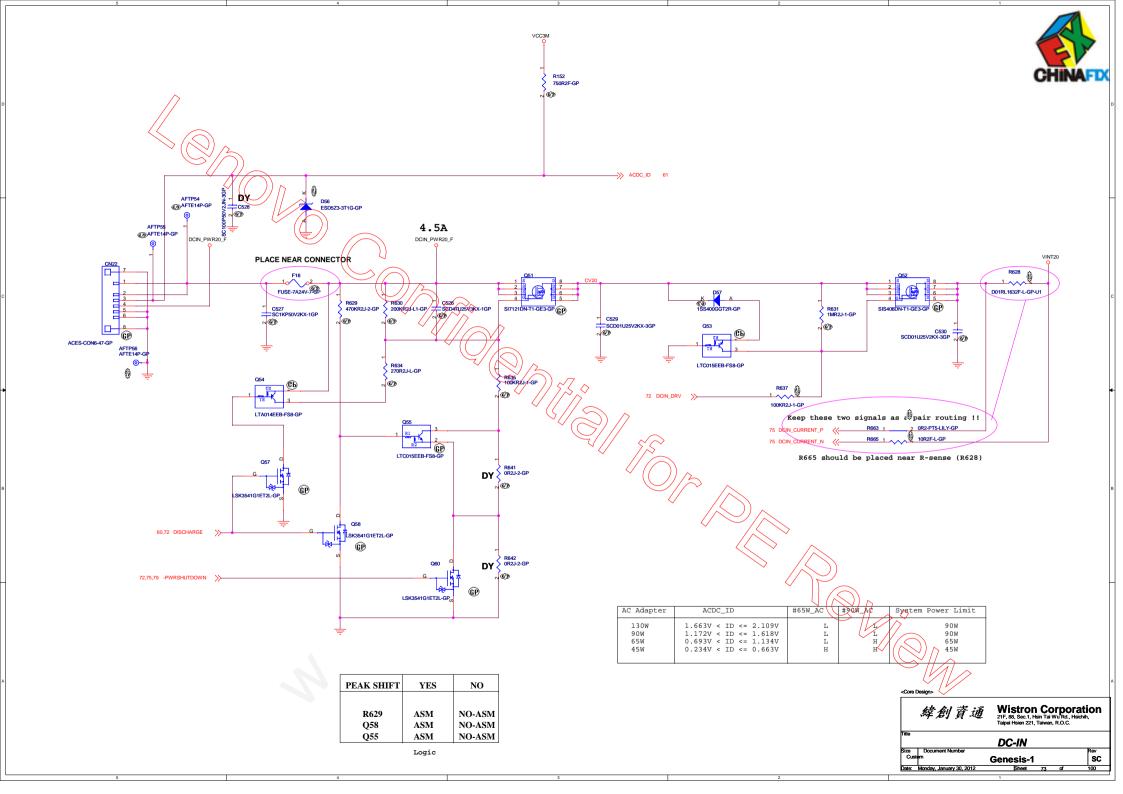


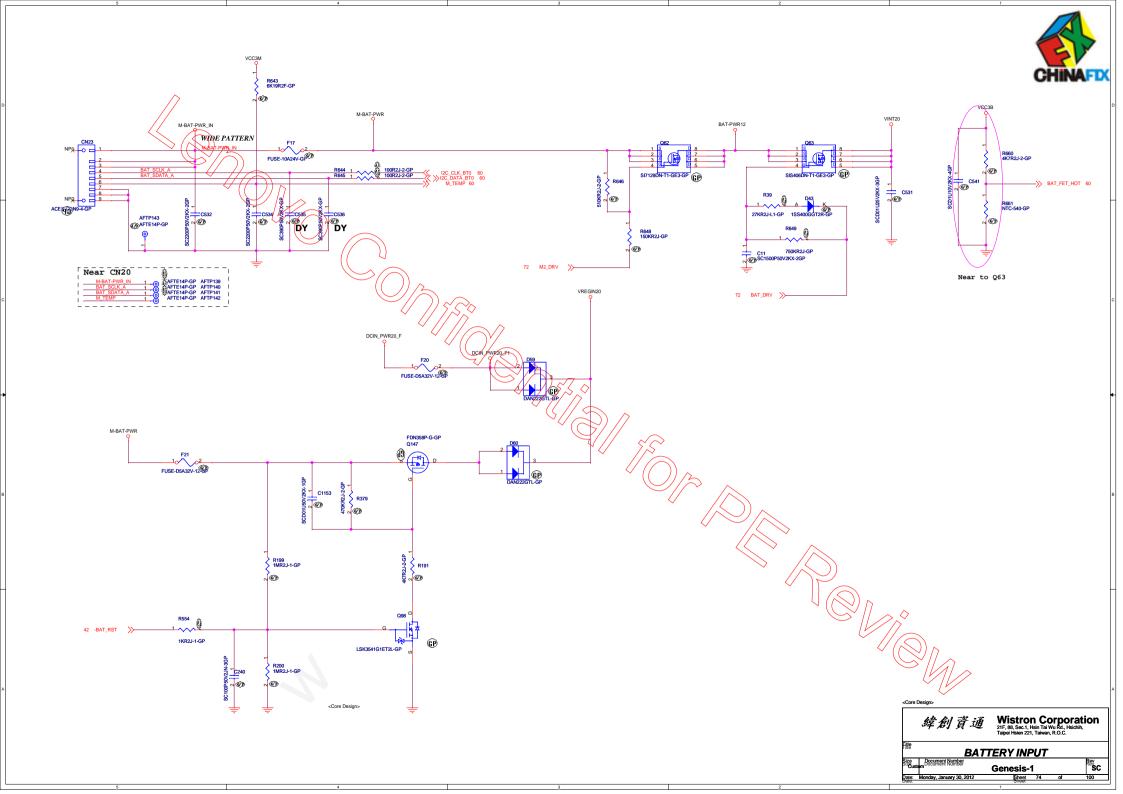


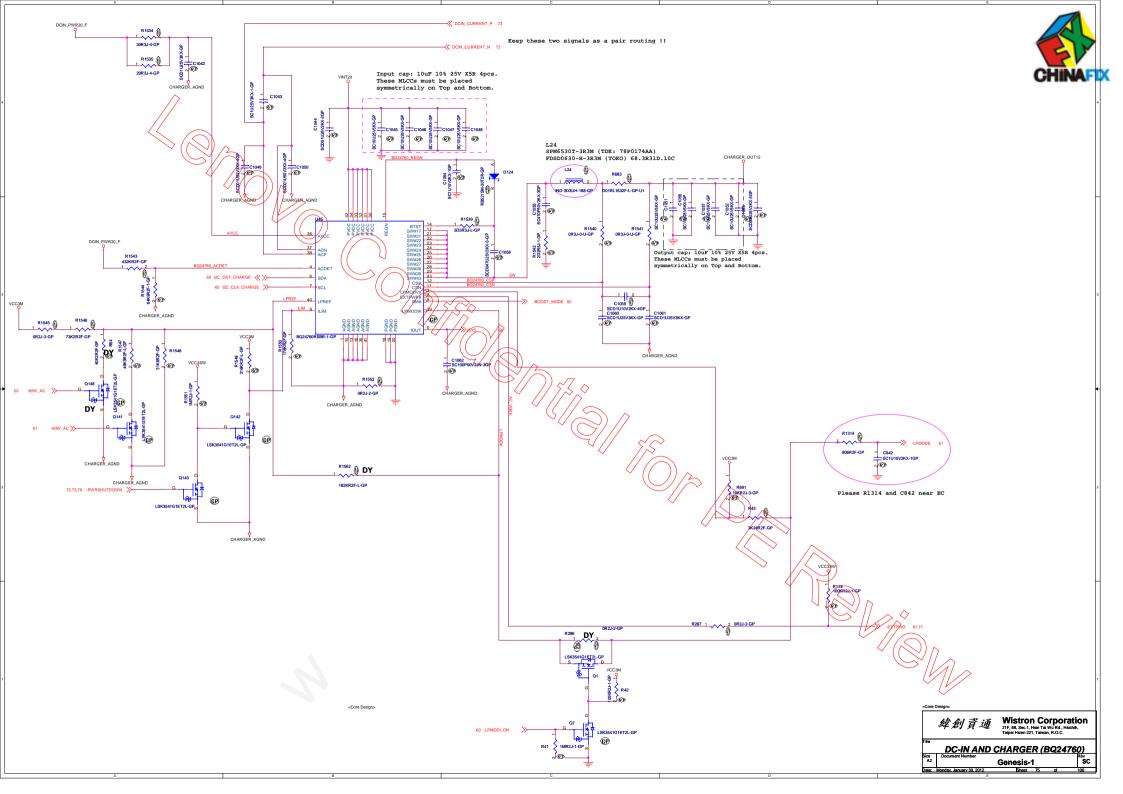
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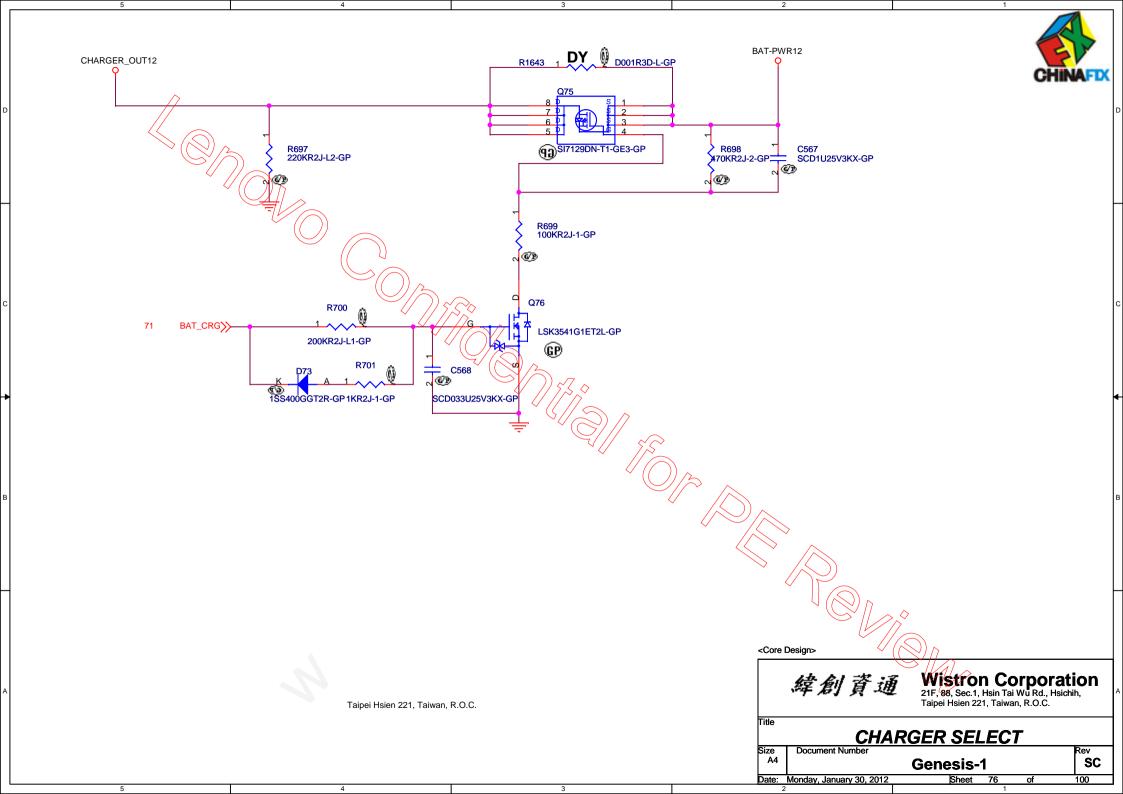


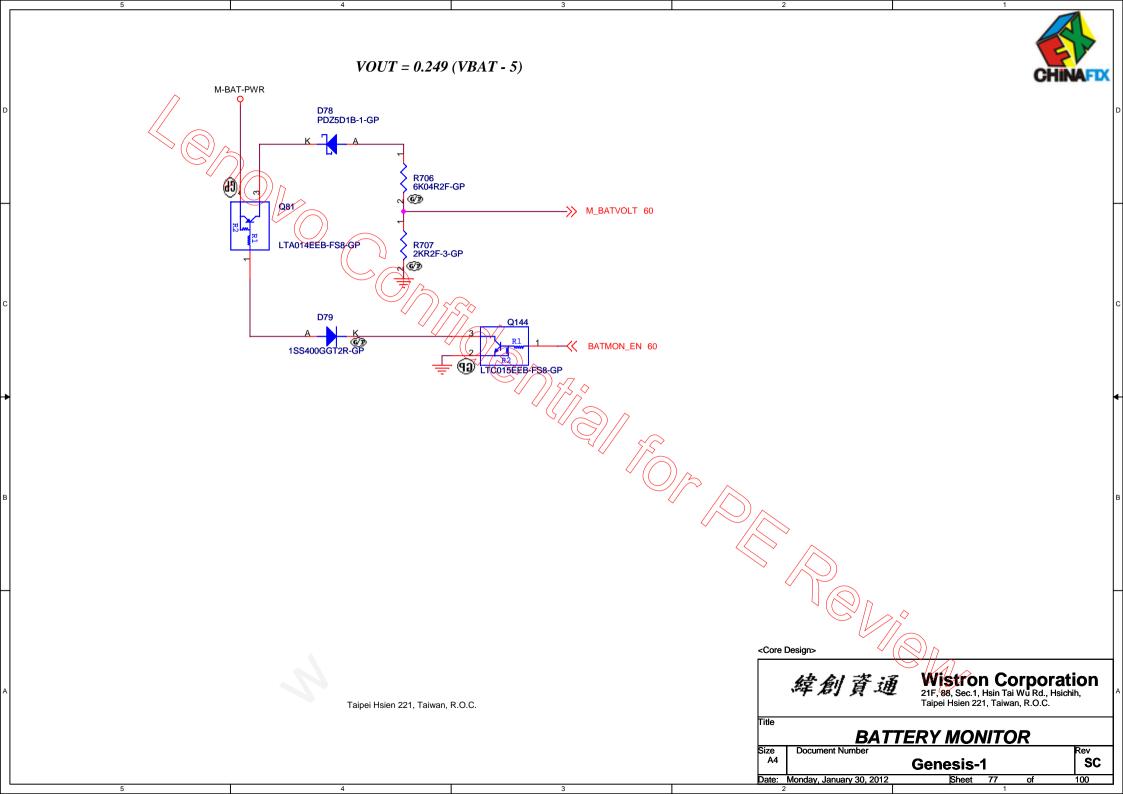


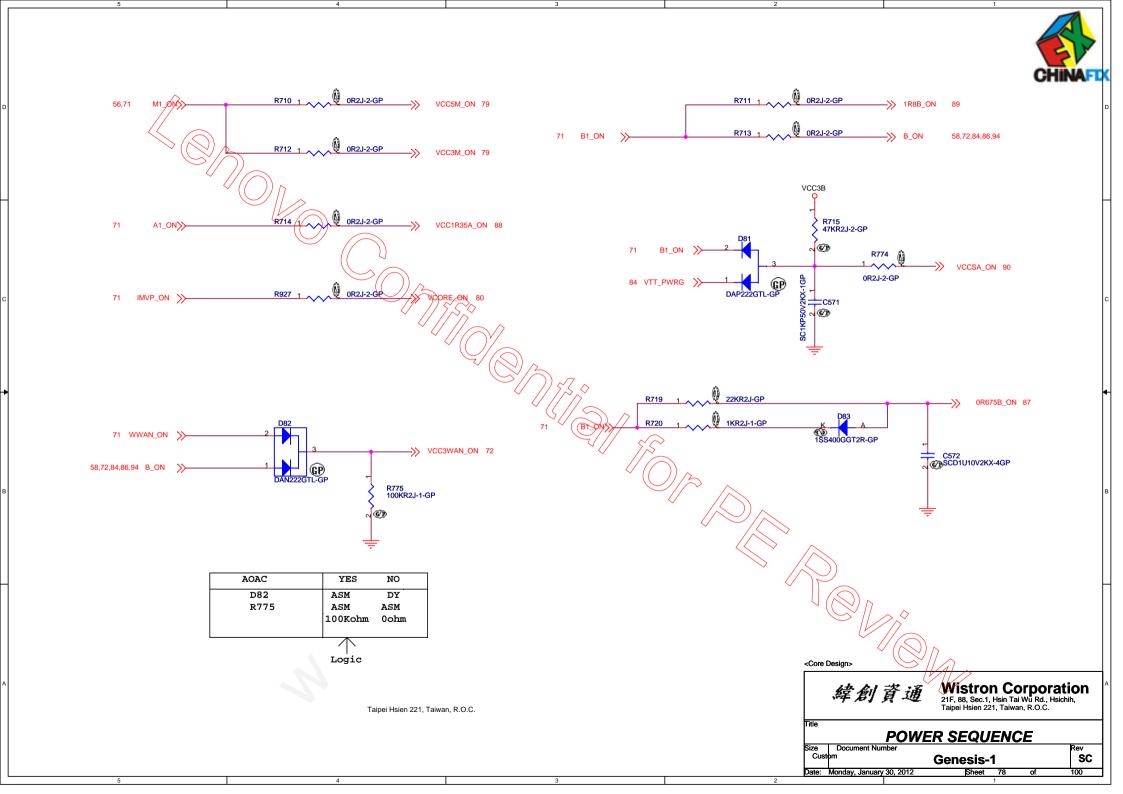


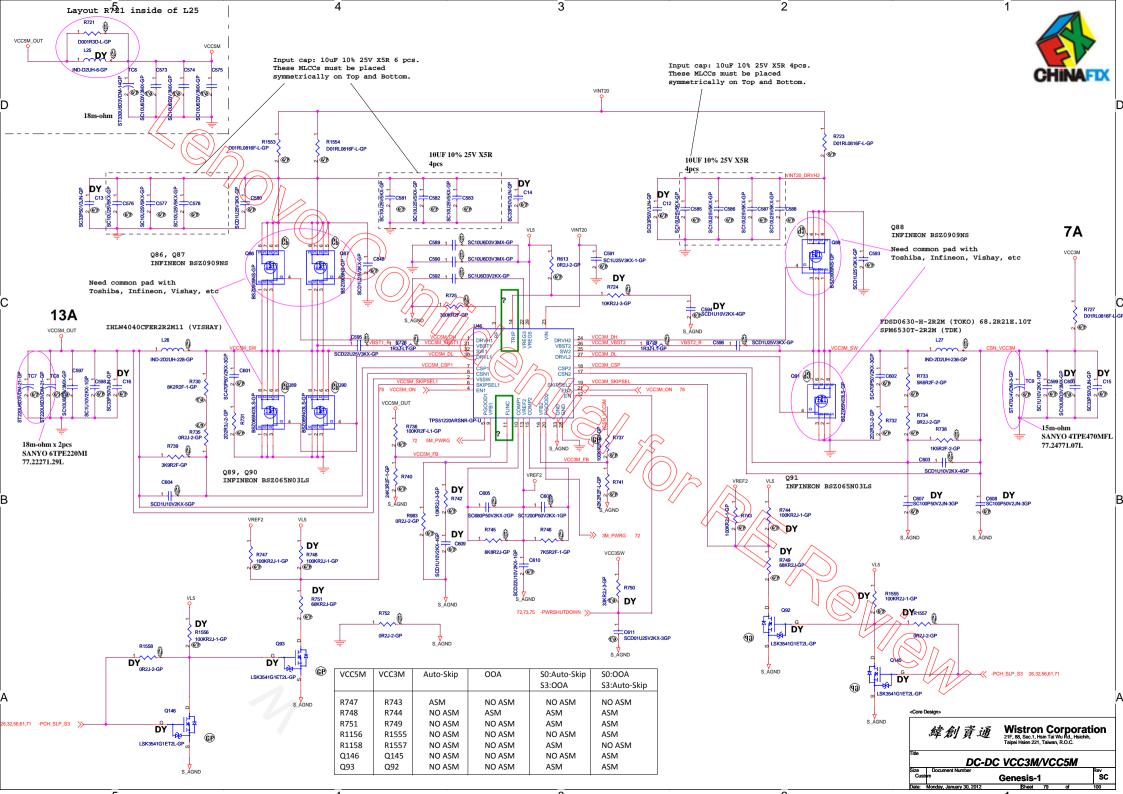


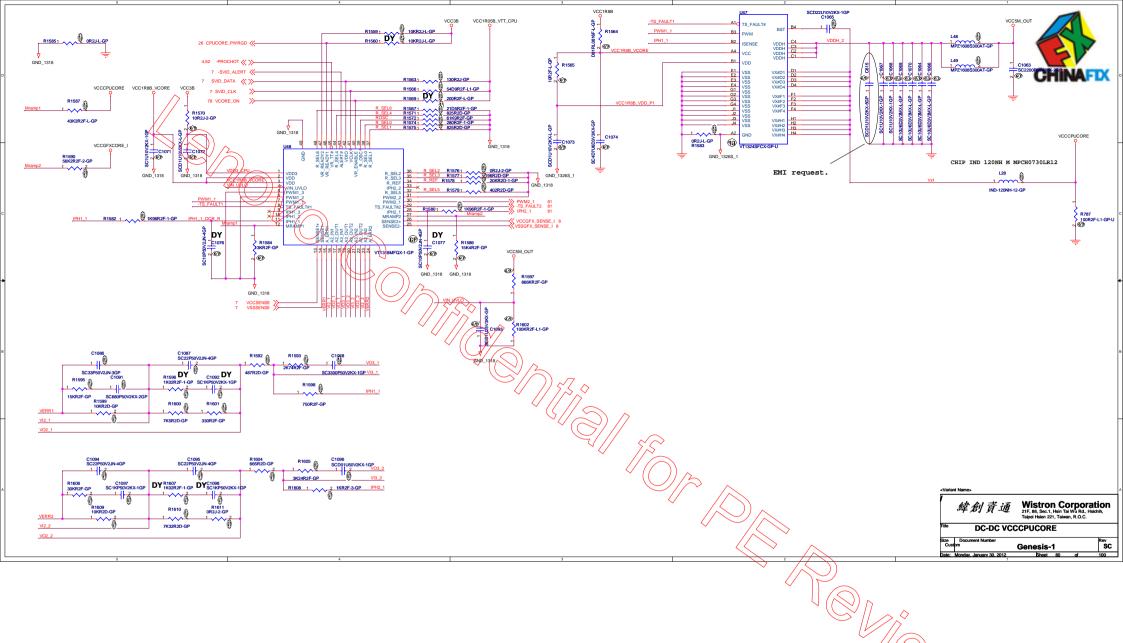


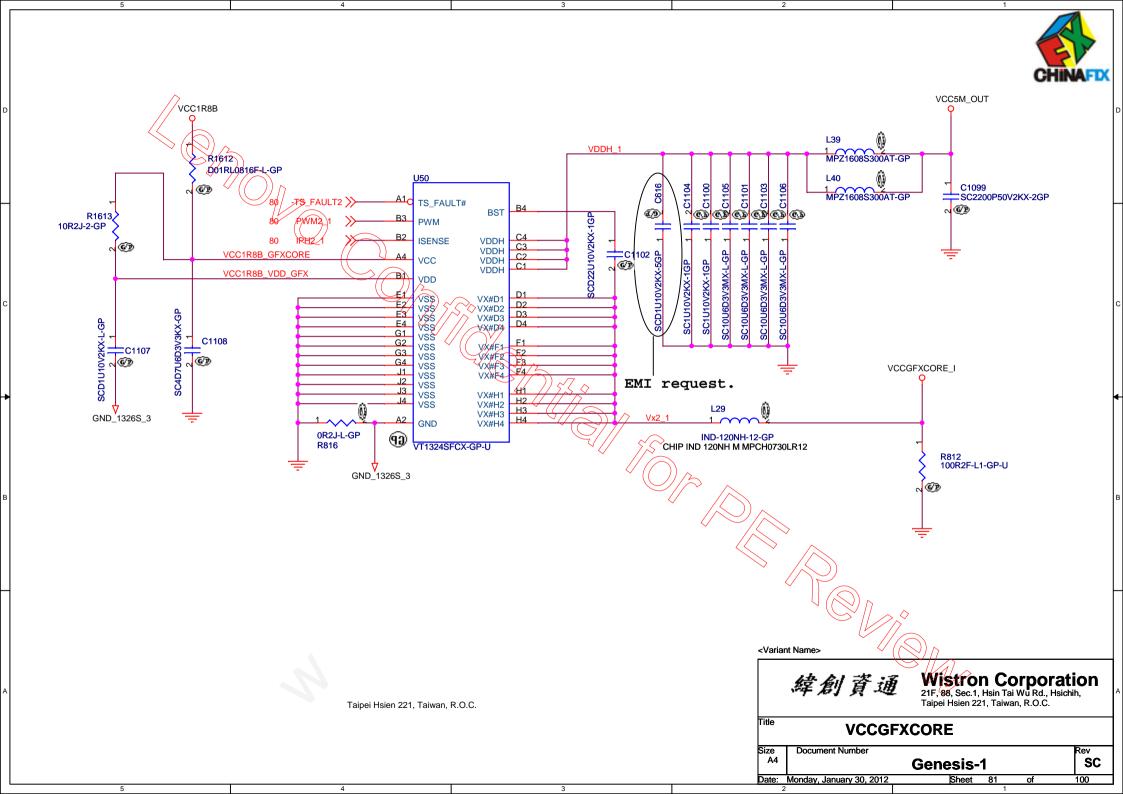


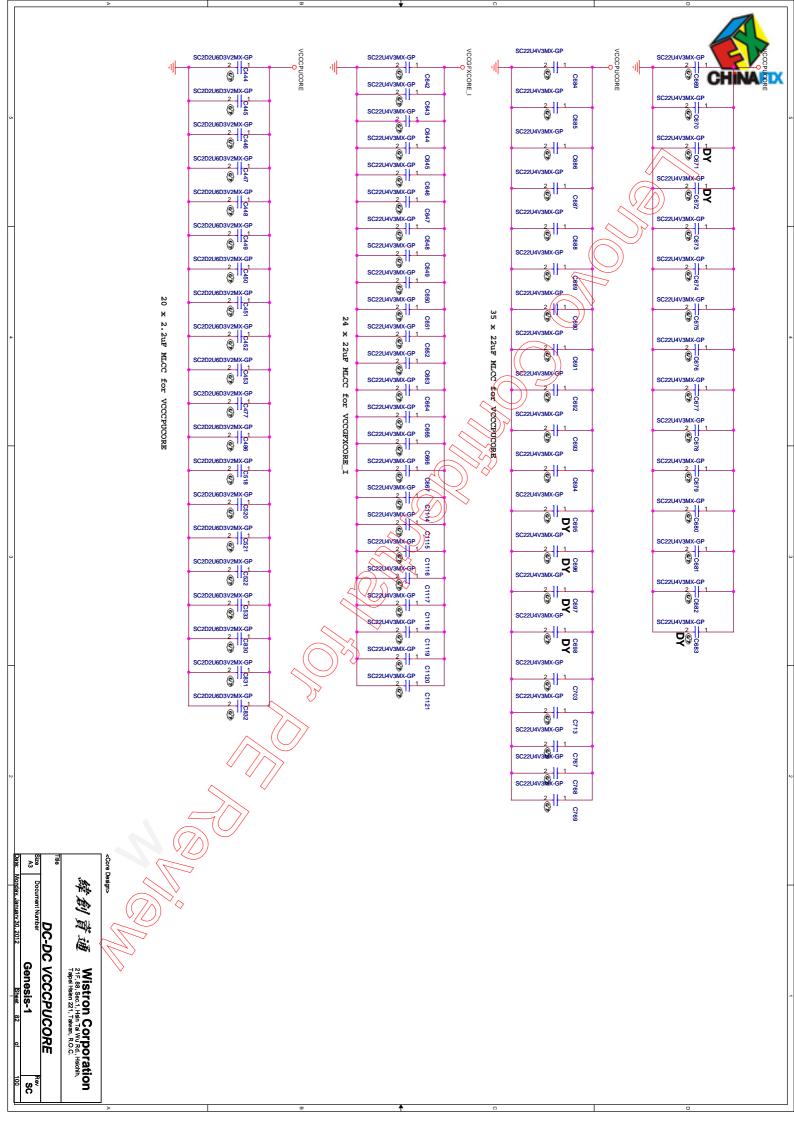














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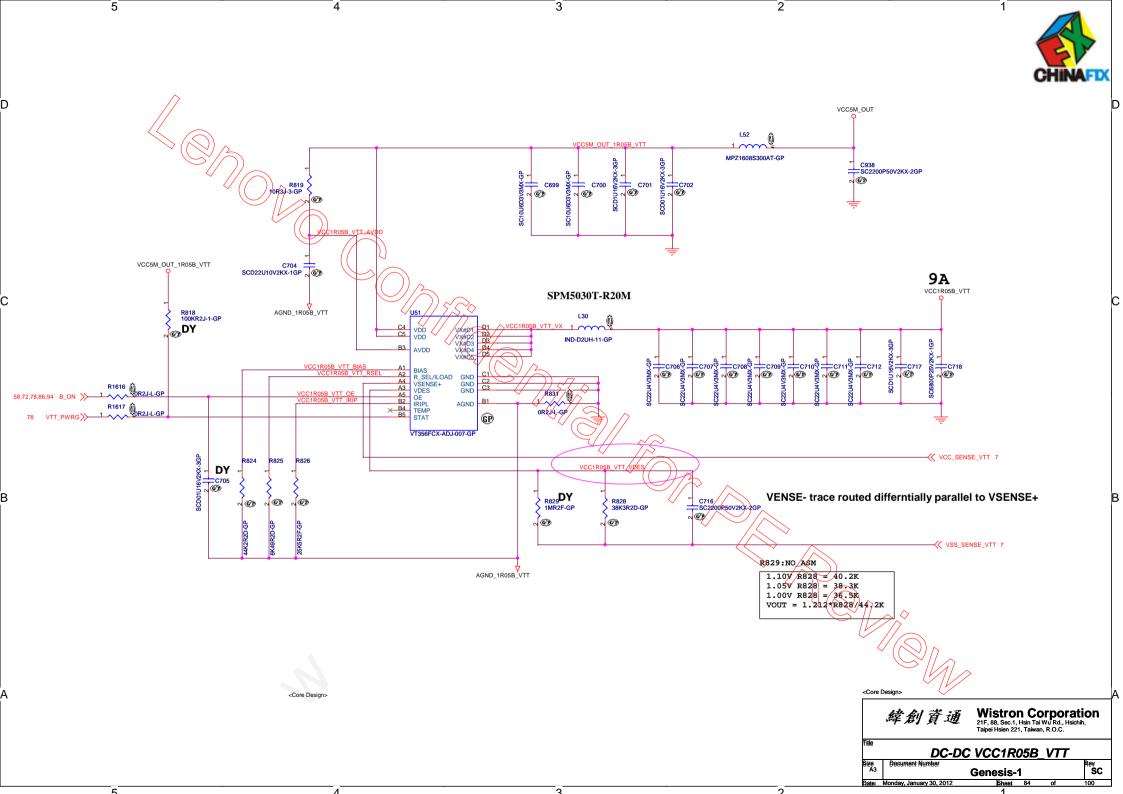
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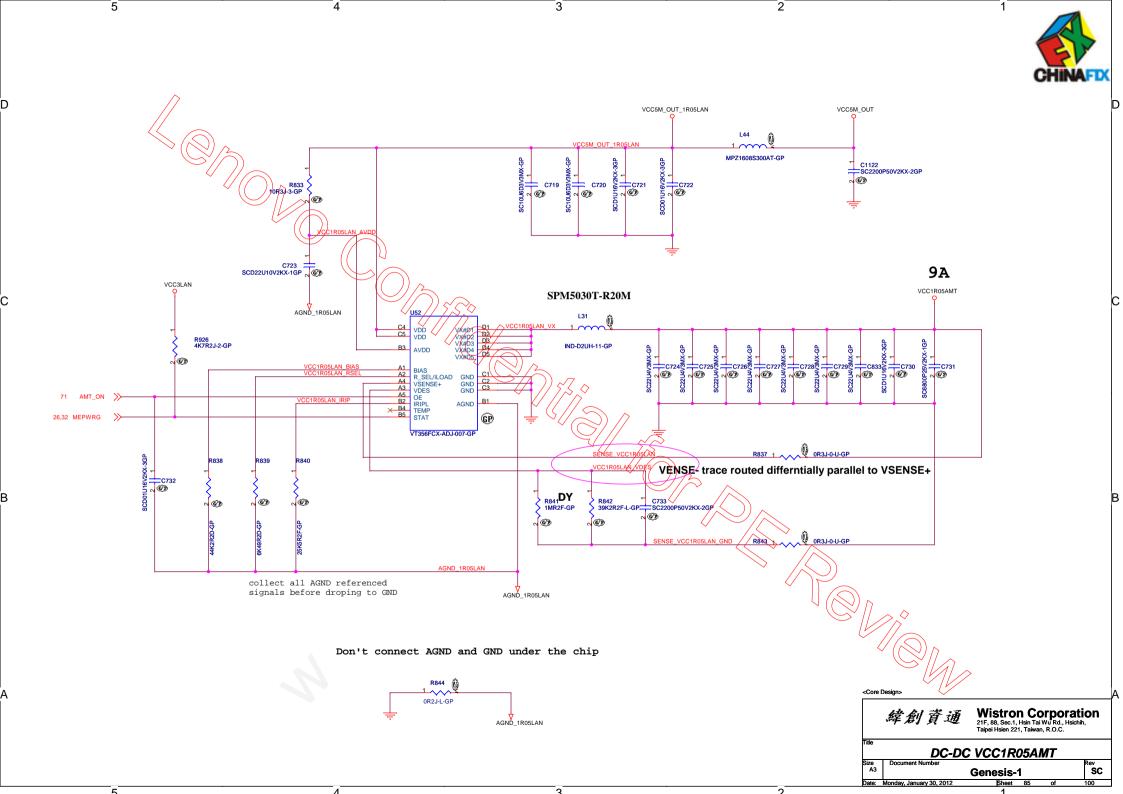
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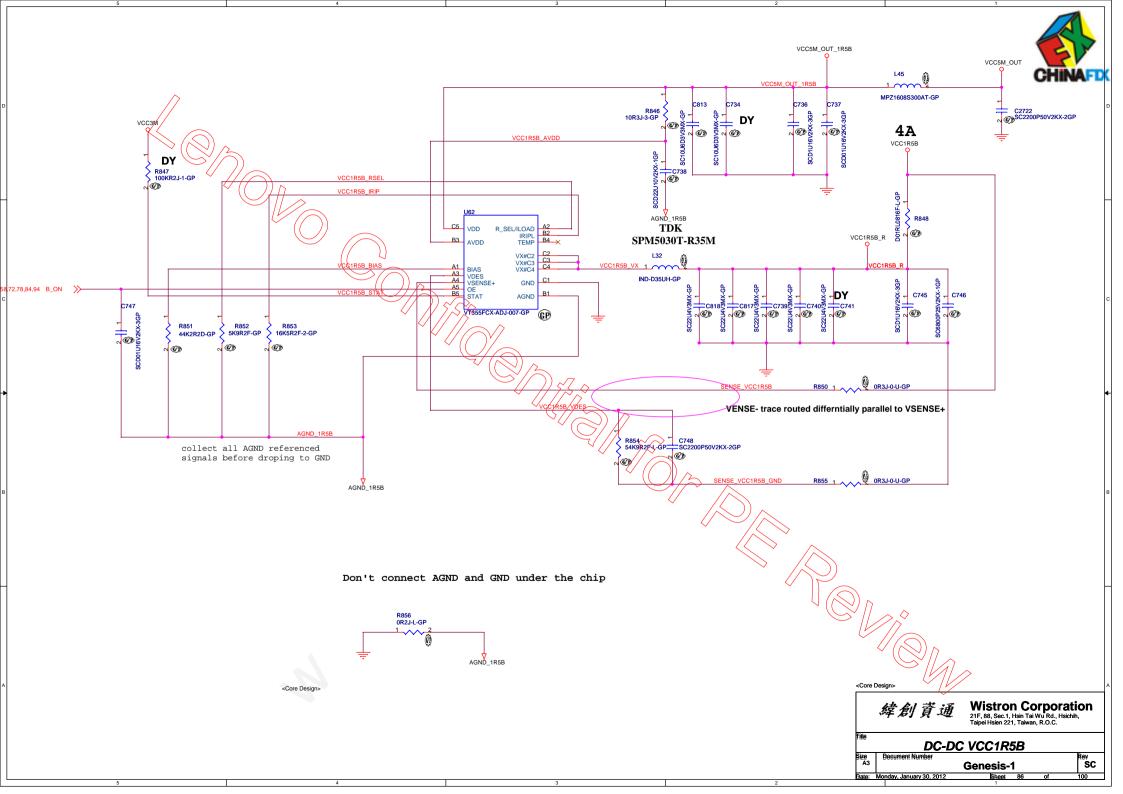
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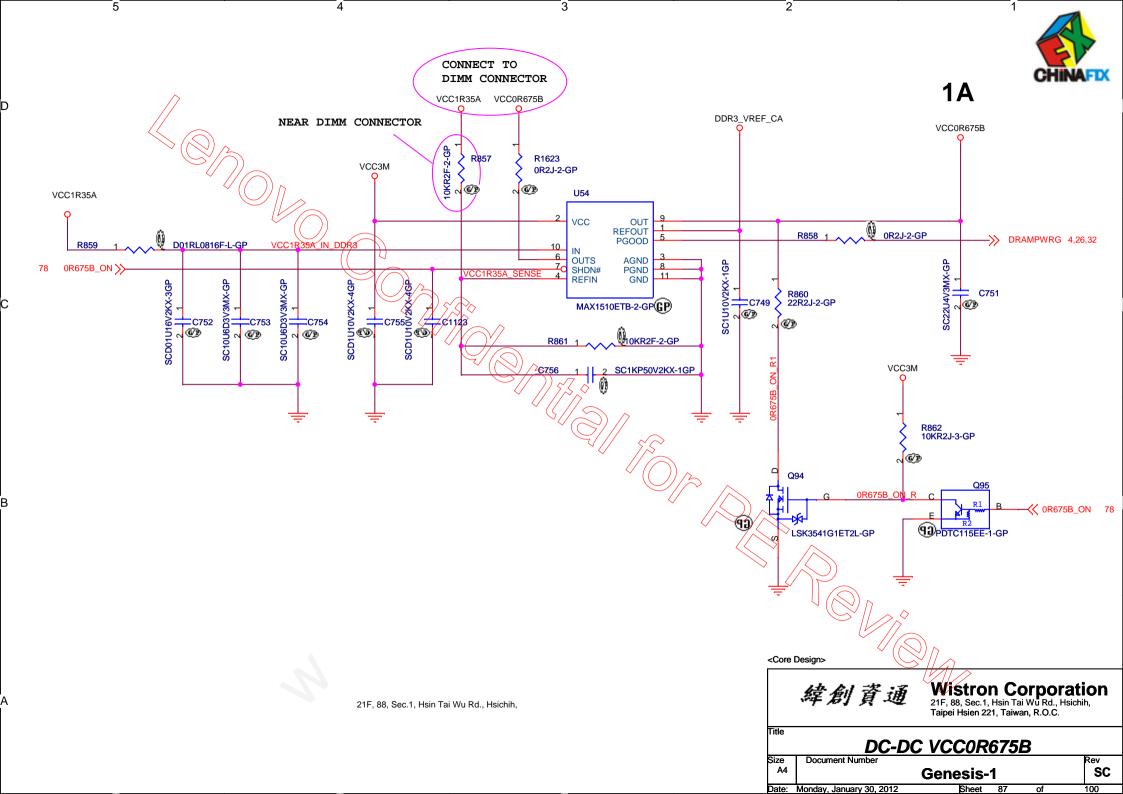
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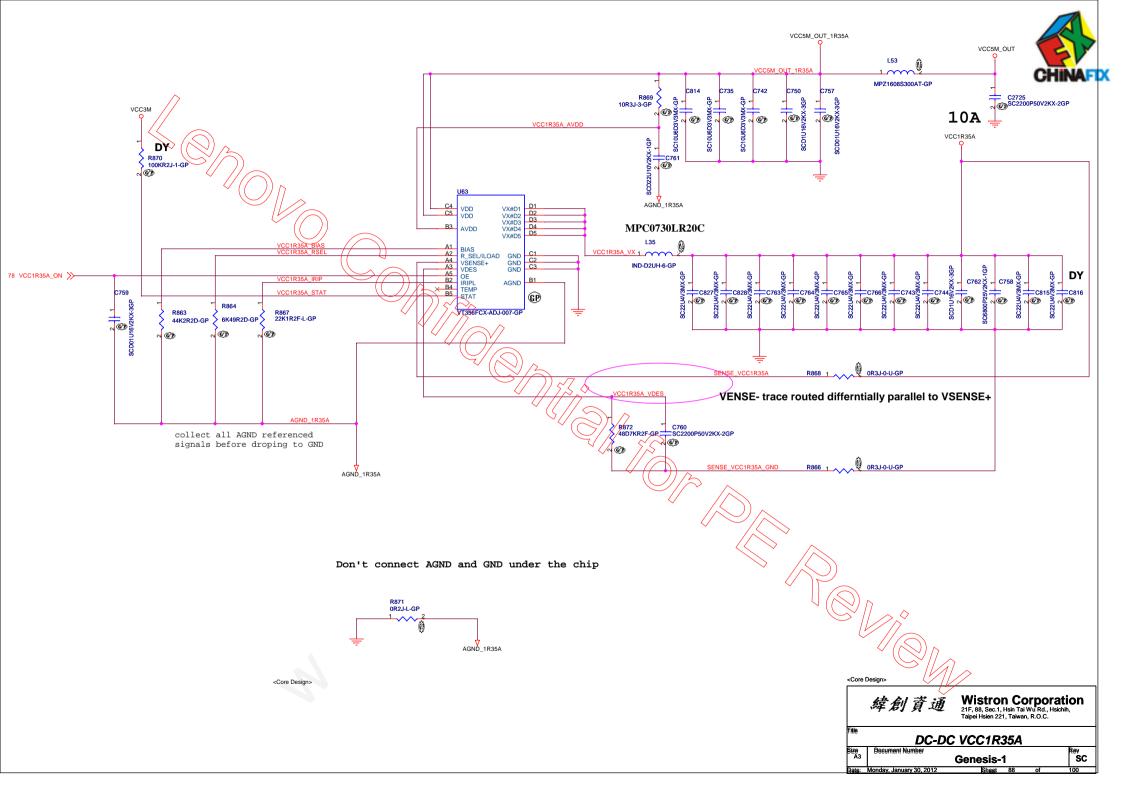
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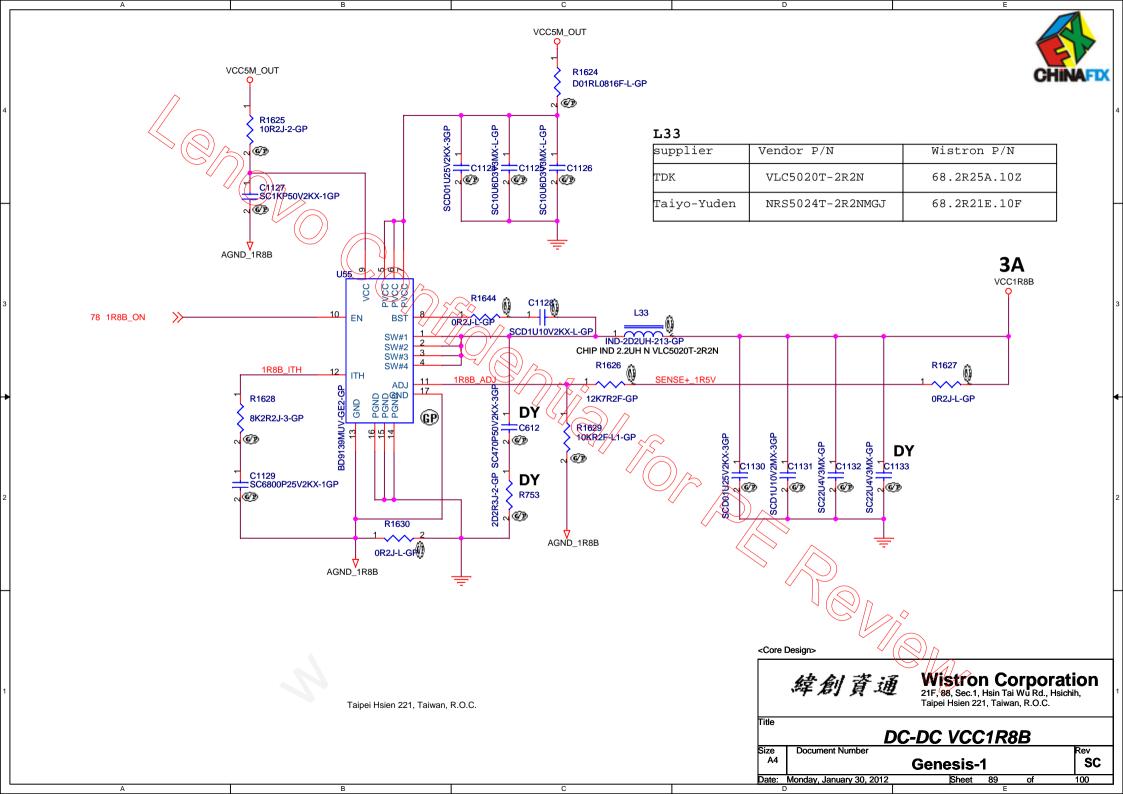


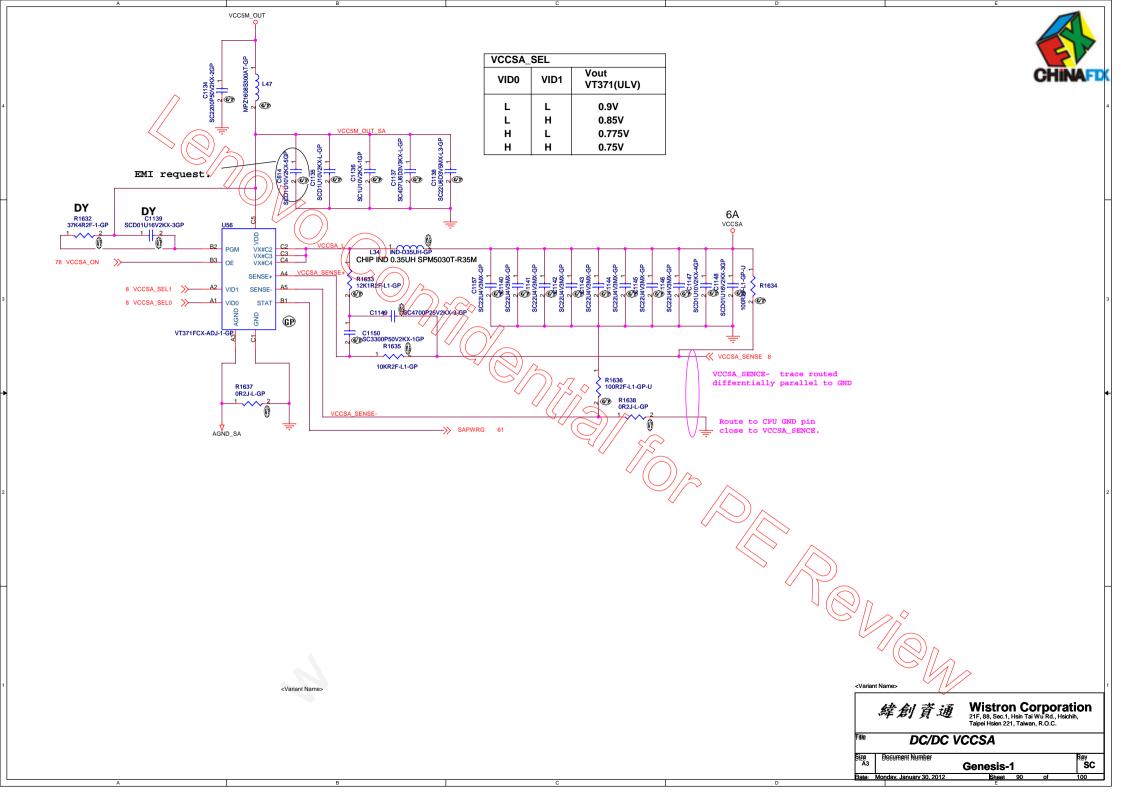


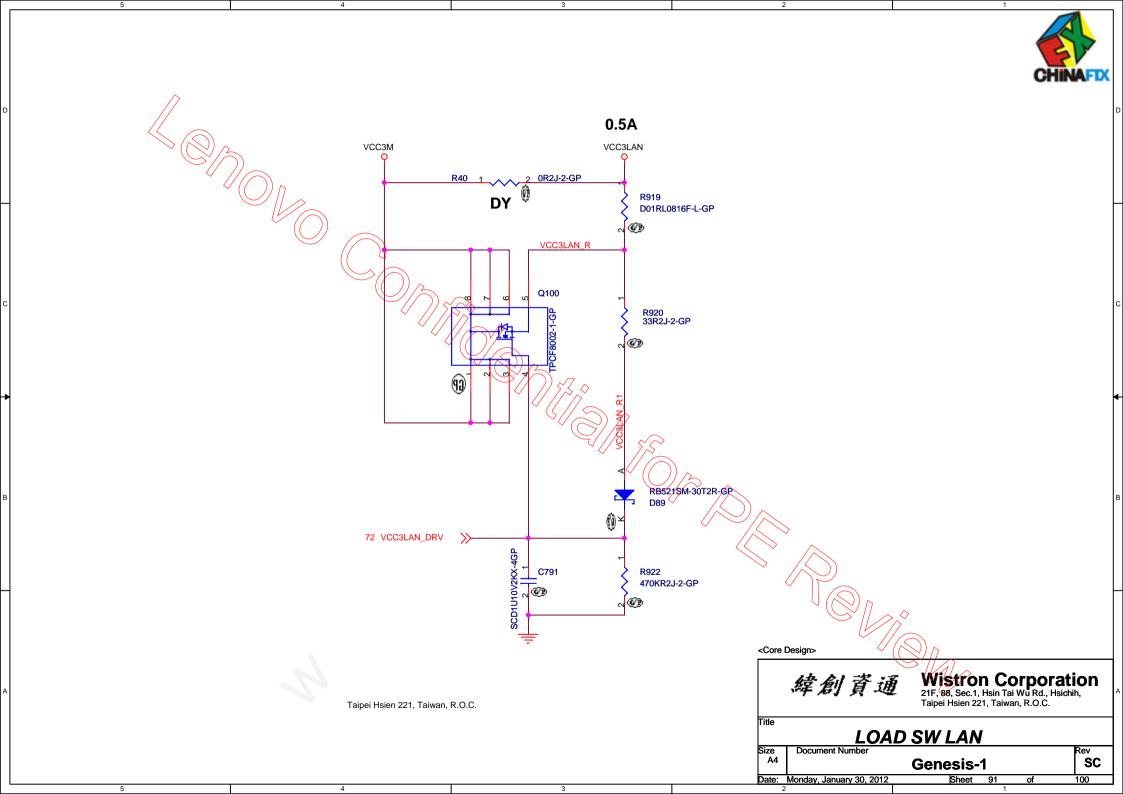


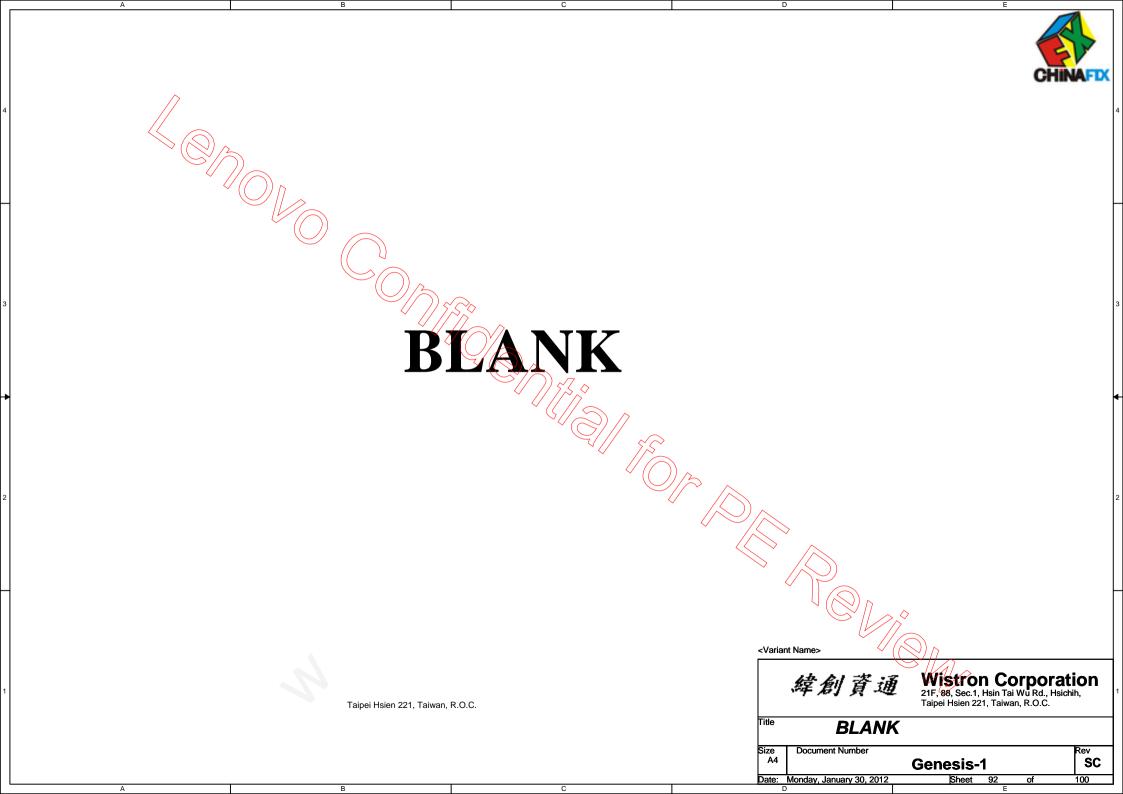


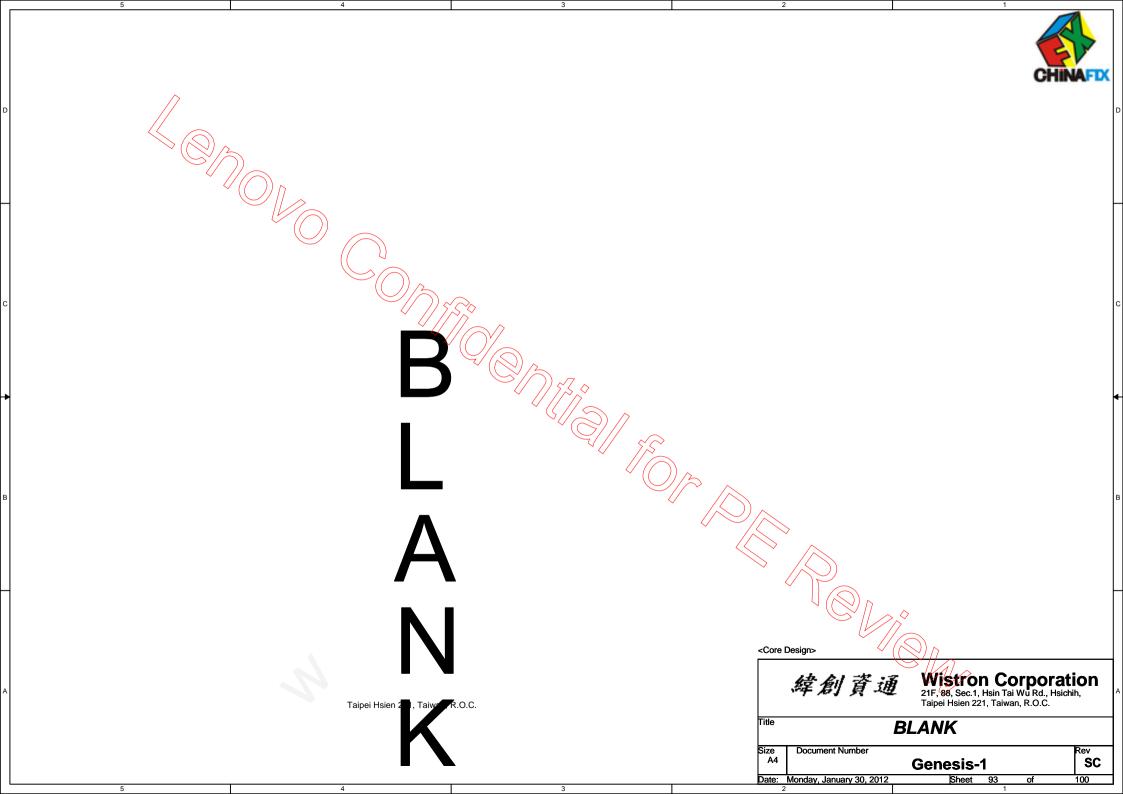


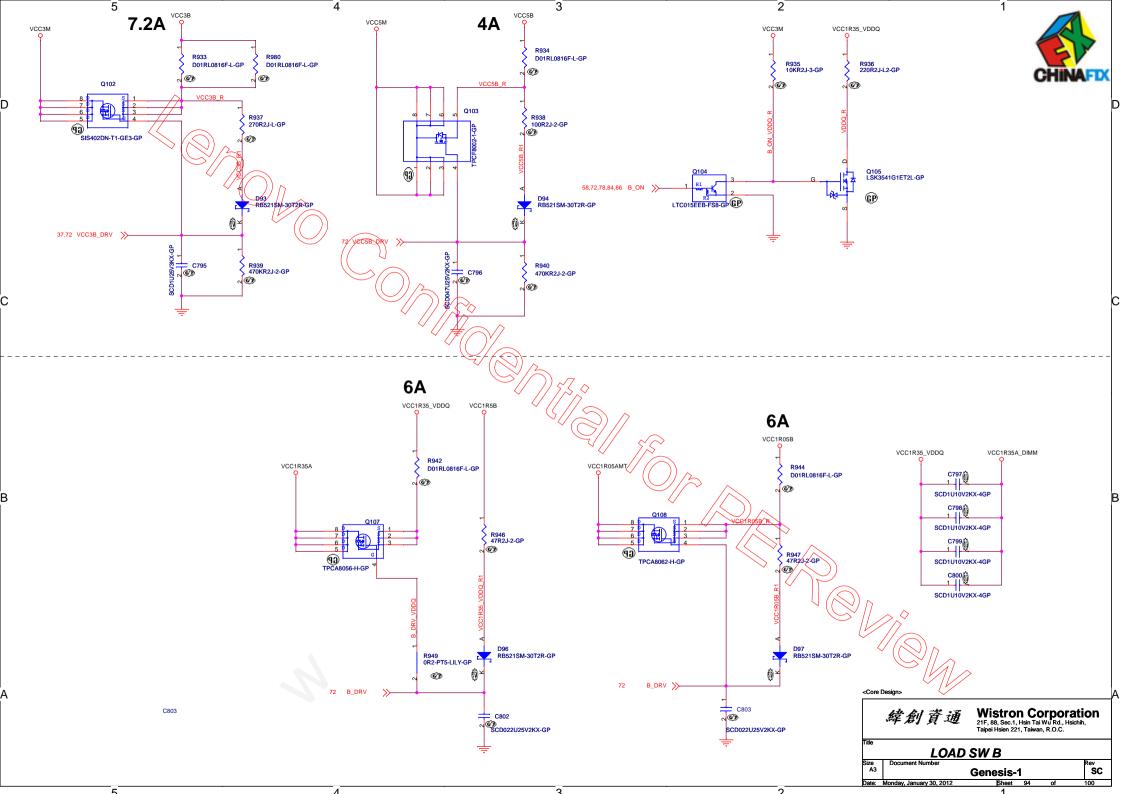


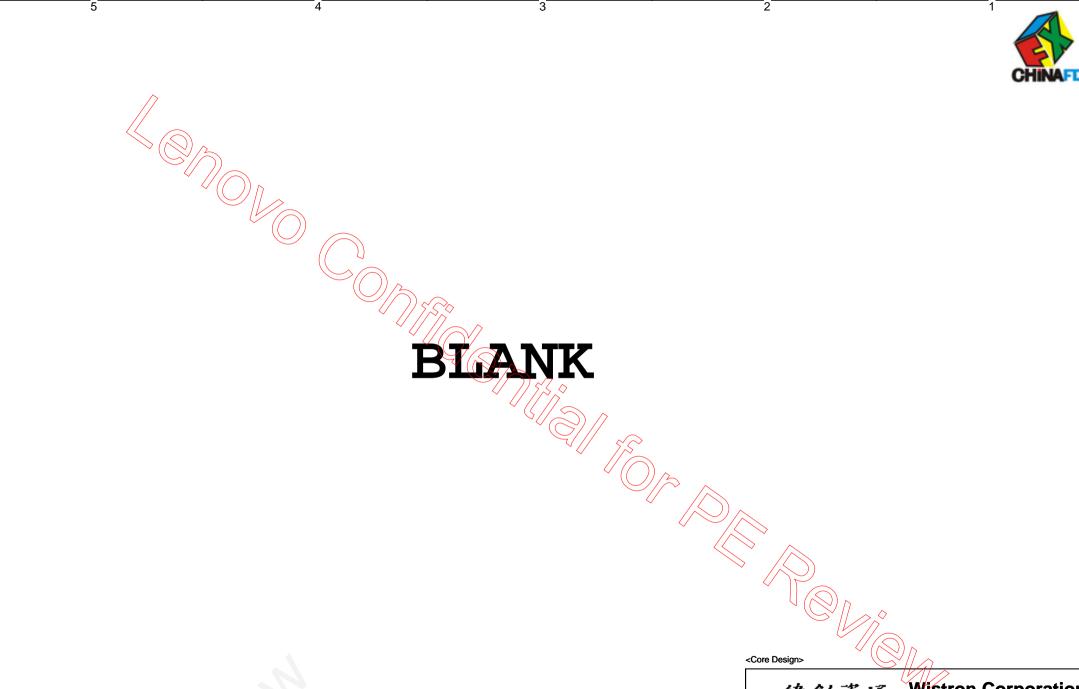




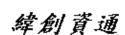








21F, 88, Sec.1, Hsin Tai Wu Rd., Hsichih,



Date: Monday, January 30, 2012

Wistron Corporation 21F, 88, Sec.1, Hsin Tai Wu Rd., Hsichih,

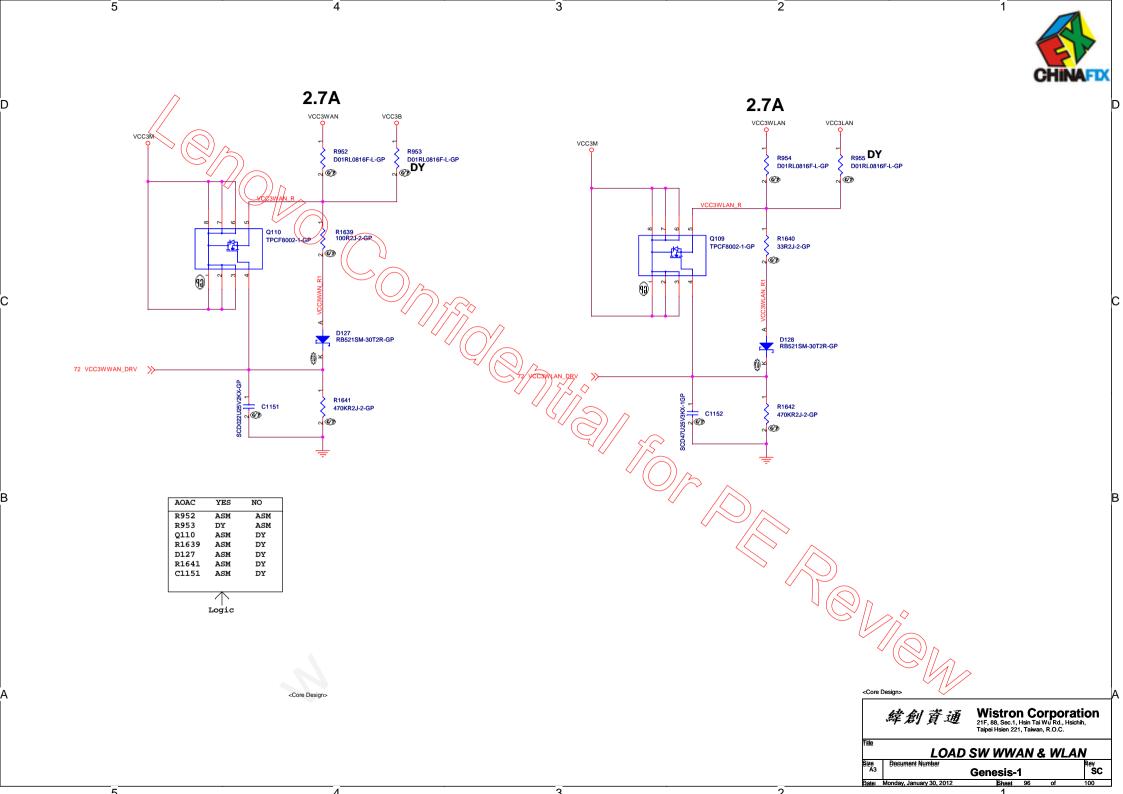
Taipei Hsien 221, Taiwan, R.O.C.

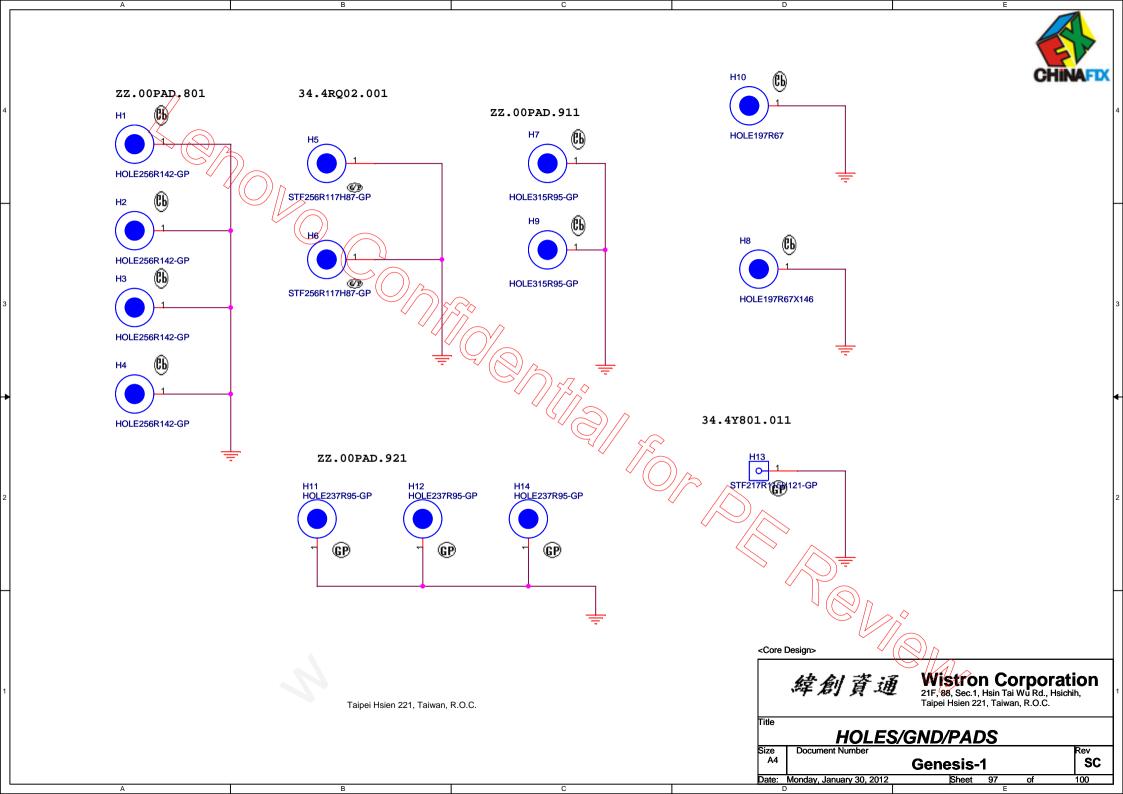
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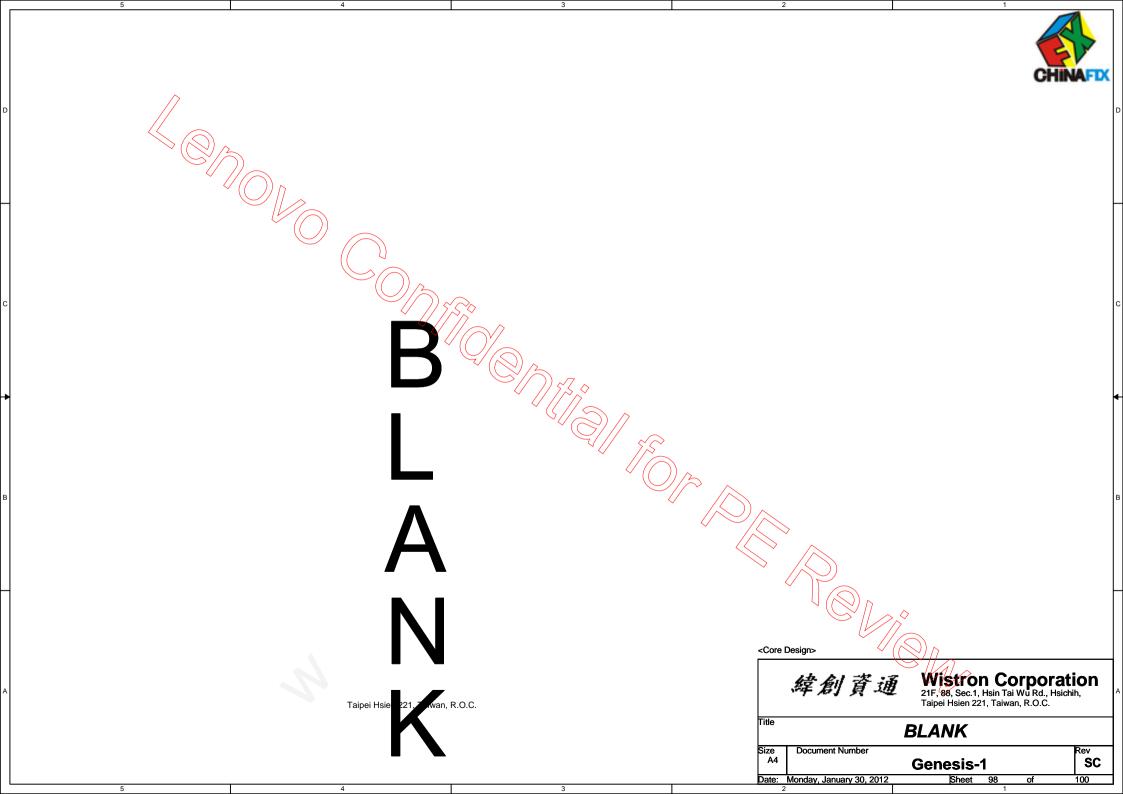
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